

True low-power platform (66  $\mu$ A/MHz, and 0.60  $\mu$ A for operation with only RTC and LVD) for the general-purpose applications, with 1.6-V to 5.5-V operation, 16- to 512-Kbyte code flash memory, and 44 DMIPS at 32 MHz

## 1. OUTLINE

### 1.1 Features

#### Ultra-Low Power Consumption Technology

- $V_{DD}$  = single power supply voltage of 1.6 to 5.5 V which can operate a 1.8 V device at a low voltage
- HALT mode
- STOP mode
- SNOOZE mode

#### RL78 CPU Core

- CISC architecture with 3-stage pipeline
- Minimum instruction execution time: Can be changed from high speed (0.03125  $\mu$ s: @ 32 MHz operation with high-speed on-chip oscillator) to ultra-low speed (30.5  $\mu$ s: @ 32.768 kHz operation with subsystem clock)
- Multiply/divide/multiply & accumulate instructions are supported.
- Address space: 1 MB
- General-purpose registers: (8-bit register  $\times$  8)  $\times$  4 banks
- On-chip RAM: 2.5 to 48 KB

#### Code Flash Memory

- Code flash memory: 16 to 512 KB
- Block size: 1 KB
- Prohibition of block erase and rewriting (security function)
- On-chip debug function
- Self-programming (with boot swap function/flash shield window function)

#### Data Flash Memory

- Data flash memory: 4 KB and 8 KB
- Back ground operation (BGO): Instructions can be executed from the program memory while rewriting the data flash memory.
- Number of rewrites: 1,000,000 times (TYP.)
- Voltage of rewrites:  $V_{DD}$  = 1.8 to 5.5 V

#### High-speed On-chip Oscillator

- Select from 64 MHz, 48 MHz, 32 MHz, 24 MHz, 16 MHz, 12 MHz, 8 MHz, 6 MHz, 4 MHz, 3 MHz, 2 MHz, and 1 MHz
- High accuracy:  $\pm 1.0\%$  ( $V_{DD}$  = 1.8 to 5.5 V,  $T_A$  = -20 to +85°C)

#### Operating Ambient Temperature

- $T_A$  = -40 to +85°C (A: Consumer applications, D: Industrial applications)
- $T_A$  = -40 to +105°C (G: Industrial applications)

#### Power Management and Reset Function

- On-chip power-on-reset (POR) circuit
- On-chip voltage detector (LVD) (Select interrupt and reset from 14 levels)

#### Data Transfer Controller (DTC)

- Transfer modes: Normal transfer mode, repeat transfer mode, block transfer mode
- Activation sources: Activated by interrupt sources.
- Chain transfer function

#### Event Link Controller (ELC)

- Event signals of 19 to 26 types can be linked to the specified peripheral function.

#### Serial Interfaces

- CSI: 3 to 8 channels
- UART/UART (LIN-bus supported): 3 or 4 channels
- I<sup>2</sup>C/simplified I<sup>2</sup>C: 3 to 8 channels

#### Timer

- 16-bit timer: 8 to 12 channels (Timer Array Unit (TAU): 4 to 8 channels, Timer RJ: 1 channel, Timer RD: 2 channels, Timer RG: 1 channel)
- 12-bit interval timer: 1 channel
- Real-time clock: 1 channel (calendar for 99 years, alarm function, and clock correction function)
- Watchdog timer: 1 channel (operable with the dedicated low-speed on-chip oscillator)

#### A/D Converter

- 8/10-bit resolution A/D converter ( $V_{DD}$  = 1.6 to 5.5 V)
- Analog input: 8 to 20 channels
- Internal reference voltage (1.45 V) and temperature sensor

#### D/A Converter

- 8-bit resolution D/A converter ( $V_{DD}$  = 1.6 to 5.5 V)
- Analog output: None or up to two channels
- Output voltage: 0 V to  $V_{DD}$
- Real-time output function

#### Comparator

- None or up to two channels
- Operating modes: Comparator high-speed mode, comparator low-speed mode, window mode
- The external reference voltage or internal reference voltage can be selected as the reference voltage.

#### I/O Port

- I/O port: 26 to 92 (N-ch open drain I/O [withstand voltage of 6 V]: 2 to 4, N-ch open drain I/O [ $V_{DD}$  withstand voltage/EV<sub>DD</sub> withstand voltage]: 10 to 28)
- Can be set to N-ch open drain, TTL input buffer, and on-chip pull-up resistor
- Different potential interface: Can connect to a 1.8/2.5/3 V device
- On-chip key interrupt function
- On-chip clock output/buzzer output controller

#### Others

- On-chip BCD (binary-coded decimal) correction circuit

**Remark** The functions mounted depend on the product. See 1.6 Outline of Functions.

## ○ ROM, RAM capacities

Flash ROM	Data flash	RAM	RL78/G14			
			30 pins	32 pins	36 pins	40 pins
192 KB	8 KB	20 KB	—	—	—	R5F104EH
128 KB	8 KB	16 KB	R5F104AG	R5F104BG	R5F104CG	R5F104EG
96 KB	8 KB	12 KB	R5F104AF	R5F104BF	R5F104CF	R5F104EF
64 KB	4 KB	5.5 KB Note	R5F104AE	R5F104BE	R5F104CE	R5F104EE
48 KB	4 KB	5.5 KB Note	R5F104AD	R5F104BD	R5F104CD	R5F104ED
32 KB	4 KB	4 KB	R5F104AC	R5F104BC	R5F104CC	R5F104EC
16 KB	4 KB	2.5 KB	R5F104AA	R5F104BA	R5F104CA	R5F104EA

Flash ROM	Data flash	RAM	RL78/G14			
			44 pins	48 pins	52 pins	64 pins
512 KB	8 KB	48 KB Note	—	R5F104GL	—	R5F104LL
384 KB	8 KB	32 KB	—	R5F104GK	—	R5F104LK
256 KB	8 KB	24 KB Note	R5F104FJ	R5F104GJ	R5F104JJ	R5F104LJ
192 KB	8 KB	20 KB	R5F104FH	R5F104GH	R5F104JH	R5F104LH
128 KB	8 KB	16 KB	R5F104FG	R5F104GG	R5F104JG	R5F104LG
96 KB	8 KB	12 KB	R5F104FF	R5F104GF	R5F104JF	R5F104LF
64 KB	4 KB	5.5 KB Note	R5F104FE	R5F104GE	R5F104JE	R5F104LE
48 KB	4 KB	5.5 KB Note	R5F104FD	R5F104GD	R5F104JD	R5F104LD
32 KB	4 KB	4 KB	R5F104FC	R5F104GC	R5F104JC	R5F104LC
16 KB	4 KB	2.5 KB	R5F104FA	R5F104GA	—	—

Flash ROM	Data flash	RAM	RL78/G14	
			80 pins	100 pins
512 KB	8 KB	48 KB Note	R5F104ML	R5F104PL
384 KB	8 KB	32 KB	R5F104MK	R5F104PK
256 KB	8 KB	24 KB Note	R5F104MJ	R5F104PJ
192 KB	8 KB	20 KB	R5F104MH	R5F104PH
128 KB	8 KB	16 KB	R5F104MG	R5F104PG
96 KB	8 KB	12 KB	R5F104MF	R5F104PF

**Note** The flash library uses RAM in self-programming and rewriting of the data flash memory.  
The target products and start address of the RAM areas used by the flash library are shown below.

R5F104xD (x = A to C, E to G, J, L): Start address FE900H

R5F104xE (x = A to C, E to G, J, L): Start address FE900H

R5F104xJ (x = F, G, J, L, M, P): Start address F9F00H

R5F104xL (x = G, L, M, P): Start address F3F00H

For the RAM areas used by the flash library, see **Self RAM list of Flash Self-Programming Library for RL78 Family (R20UT2944)**.

## 1.2 Ordering Information

<R>

Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14



<R>

**Table 1 - 1 List of Ordering Part Numbers (1/12)**

Pin count	Package	Fields of Application Note	Ordering Part Number	RENESAS Code
30 pins	30-pin plastic LSSOP (7.62 mm (300), 0.65 mm pitch)	A	R5F104AAASP#V0, R5F104ACASP#V0, R5F104ADASP#V0, R5F104AEASP#V0, R5F104AFASP#V0, R5F104AGASP#V0 R5F104AAASP#X0, R5F104ACASP#X0, R5F104ADASP#X0, R5F104AEASP#X0, R5F104AFASP#X0, R5F104AGASP#X0 R5F104AAASP#30, R5F104ACASP#30, R5F104ADASP#30, R5F104AEASP#30, R5F104AFASP#30, R5F104AGASP#30 R5F104AAASP#50, R5F104ACASP#50, R5F104ADASP#50, R5F104AEASP#50, R5F104AFASP#50, R5F104AGASP#50	PLSP0030JB-B
		D	R5F104AADSP#V0, R5F104ACDSP#V0, R5F104ADDSP#V0, R5F104AEDSP#V0, R5F104AFDSP#V0, R5F104AGDSP#V0 R5F104AADSP#X0, R5F104ACDSP#X0, R5F104ADDSP#X0, R5F104AEDSP#X0, R5F104AFDSP#X0, R5F104AGDSP#X0 R5F104AADSP#30, R5F104ACDSP#30, R5F104ADDSP#30, R5F104AEDSP#30, R5F104AFDSP#30, R5F104AGDSP#30 R5F104AADSP#50, R5F104ACDSP#50, R5F104ADDSP#50, R5F104AEDSP#50, R5F104AFDSP#50, R5F104AGDSP#50	
		G	R5F104AAGSP#V0, R5F104ACGSP#V0, R5F104ADGSP#V0, R5F104AEGSP#V0, R5F104AFGSP#V0, R5F104AGGSP#V0 R5F104AAGSP#X0, R5F104ACGSP#X0, R5F104ADGSP#X0, R5F104AEGSP#X0, R5F104AFGSP#X0, R5F104AGGSP#X0 R5F104AAGSP#30, R5F104ACGSP#30, R5F104ADGSP#30, R5F104AEGSP#30, R5F104AFGSP#30, R5F104AGGSP#30 R5F104AAGSP#50, R5F104ACGSP#50, R5F104ADGSP#50, R5F104AEGSP#50, R5F104AFGSP#50, R5F104AGGSP#50	

**Note** For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14**.

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

<R>

**Table 1 - 1 List of Ordering Part Numbers (2/12)**

Pin count	Package	Fields of Application Note	Ordering Part Number	RENESAS Code		
32 pins	32-pin plastic HWQFN (5 × 5 mm, 0.5 mm pitch)	A	R5F104BAANA#U0, R5F104BCANA#U0, R5F104BDANA#U0, R5F104BEANA#U0, R5F104BFANA#U0, R5F104BGANA#U0 R5F104BAANA#W0, R5F104BCANA#W0, R5F104BDANA#W0, R5F104BEANA#W0, R5F104BFANA#W0, R5F104BGANA#W0	PWQN0032KB-A		
			R5F104BAANA#20, R5F104BCANA#20, R5F104BDANA#20, R5F104BEANA#20, R5F104BFANA#20, R5F104BGANA#20 R5F104BAANA#40, R5F104BCANA#40, R5F104BDANA#40, R5F104BEANA#40, R5F104BFANA#40, R5F104BGANA#40	PWQN0032KE-A		
		D	R5F104BADNA#U0, R5F104BCDNA#U0, R5F104BDDNA#U0, R5F104BEDNA#U0, R5F104BFDNA#U0, R5F104BGDNA#U0 R5F104BADNA#W0, R5F104BCDNA#W0, R5F104BDDNA#W0, R5F104BEDNA#W0, R5F104BFDNA#W0, R5F104BGDNA#W0	PWQN0032KB-A		
			G	R5F104BAGNA#U0, R5F104BCGNA#U0, R5F104BDGNA#U0, R5F104BEGNA#U0, R5F104BFGNA#U0, R5F104BGGNA#U0 R5F104BAGNA#W0, R5F104BCGNA#W0, R5F104BDGNA#W0, R5F104BEGNA#W0, R5F104BFGNA#W0, R5F104BGGNA#W0	PWQN0032KE-A	
		R5F104BAGNA#20, R5F104BCGNA#20, R5F104BDGNA#20, R5F104BEGNA#20, R5F104BFGNA#20, R5F104BGGNA#20 R5F104BAGNA#40, R5F104BCGNA#40, R5F104BDGNA#40, R5F104BEGNA#40, R5F104BFGNA#40, R5F104BGGNA#40				
		32-pin plastic LQFP (7 × 7 mm, 0.8 mm pitch)		A	R5F104BAAFP#V0, R5F104BCAFP#V0, R5F104BDAFP#V0, R5F104BEAFP#V0, R5F104BFAFP#V0, R5F104BGAFP#V0 R5F104BAAFP#X0, R5F104BCAFP#X0, R5F104BDAFP#X0, R5F104BEAFP#X0, R5F104BFAFP#X0, R5F104BGAFP#X0 R5F104BAAFP#30, R5F104BCAFP#30, R5F104BDAFP#30, R5F104BEAFP#30, R5F104BFAFP#30, R5F104BGAFP#30 R5F104BAAFP#50, R5F104BCAFP#50, R5F104BDAFP#50, R5F104BEAFP#50, R5F104BFAFP#50, R5F104BGAFP#50	PLQP0032GB-A
					D	
				G		

**Note** For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14**.

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

&lt;R&gt;

Table 1 - 1 List of Ordering Part Numbers (3/12)

Pin count	Package	Fields of Application Note	Ordering Part Number	RENESAS Code
36 pins	36-pin plastic WFLGA (4 × 4 mm, 0.5 mm pitch)	A	R5F104CAALA#U0, R5F104CCALA#U0, R5F104CDALA#U0, R5F104CEALA#U0, R5F104CFALA#U0, R5F104CGALA#U0 R5F104CAALA#W0, R5F104CCALA#W0, R5F104CDALA#W0, R5F104CEALA#W0, R5F104CFALA#W0, R5F104CGALA#W0	PWLG0036KA-A
		G	R5F104CAGLA#U0, R5F104CCGLA#U0, R5F104CDGLA#U0, R5F104CEGLA#U0, R5F104CFGLA#U0, R5F104CGGLA#U0 R5F104CAGLA#W0, R5F104CCGLA#W0, R5F104CDGLA#W0, R5F104CEGLA#W0, R5F104CFGLA#W0, R5F104CGGLA#W0	
40 pins	40-pin plastic HWQFN (6 × 6 mm, 0.5 mm pitch)	A	R5F104EAANA#U0, R5F104ECANA#U0, R5F104EDANA#U0, R5F104EEANA#U0, R5F104EFANA#U0, R5F104EGANA#U0, R5F104EHANA#U0 R5F104EAANA#W0, R5F104ECANA#W0, R5F104EDANA#W0, R5F104EEANA#W0, R5F104EFANA#W0, R5F104EGANA#W0, R5F104EHANA#W0	PWQN0040KC-A
		D	R5F104EADNA#U0, R5F104ECDNA#U0, R5F104EDDNA#U0, R5F104EEDNA#U0, R5F104EFDNA#U0, R5F104EGDNA#U0, R5F104EHDNA#U0 R5F104EADNA#W0, R5F104ECDNA#W0, R5F104EDDNA#W0, R5F104EEDNA#W0, R5F104EFDNA#W0, R5F104EGDNA#W0, R5F104EHDNA#W0	
		G	R5F104EAGNA#U0, R5F104ECGNA#U0, R5F104EDGNA#U0, R5F104EEGNA#U0, R5F104EFGNA#U0, R5F104EGGNA#U0, R5F104EHGNA#U0 R5F104EAGNA#W0, R5F104ECGNA#W0, R5F104EDGNA#W0, R5F104EEGNA#W0, R5F104EFGNA#W0, R5F104EGGNA#W0, R5F104EHGNA#W0	

**Note** For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14**.

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

<R>

**Table 1 - 1 List of Ordering Part Numbers (4/12)**

Pin count	Package	Fields of Application Note	Ordering Part Number	RENESAS Code
44 pins	44-pin plastic LQFP (10 × 10 mm, 0.8 mm pitch)	A	R5F104FAAFP#V0, R5F104FCAFP#V0, R5F104FDAFP#V0, R5F104FEAFP#V0, R5F104FFAFP#V0, R5F104FGAFP#V0, R5F104FHAFP#V0, R5F104FJAFP#V0	PLQP0044GC-A
			R5F104FAAFP#X0, R5F104FCAFP#X0, R5F104FDAFP#X0, R5F104FEAFP#X0, R5F104FFAFP#X0, R5F104FGAFP#X0, R5F104FHAFP#X0, R5F104FJAFP#X0	
			R5F104FAAFP#30, R5F104FCAFP#30, R5F104FDAFP#30, R5F104FEAFP#30, R5F104FFAFP#30, R5F104FGAFP#30, R5F104FHAFP#30, R5F104FJAFP#30	PLQP0044GC-A/ PLQP0044GC-D
			R5F104FAAFP#50, R5F104FCAFP#50, R5F104FDAFP#50, R5F104FEAFP#50, R5F104FFAFP#50, R5F104FGAFP#50, R5F104FHAFP#50, R5F104FJAFP#50	
		D	R5F104FADFP#V0, R5F104FCDFP#V0, R5F104FDDFP#V0, R5F104FEDFP#V0, R5F104FFDFP#V0, R5F104FGDFP#V0, R5F104FHDFP#V0, R5F104FJDFP#V0	PLQP0044GC-A
			R5F104FADFP#X0, R5F104FCDFP#X0, R5F104FDDFP#X0, R5F104FEDFP#X0, R5F104FFDFP#X0, R5F104FGDFP#X0, R5F104FHDFP#X0, R5F104FJDFP#X0	
			R5F104FADFP#30, R5F104FCDFP#30, R5F104FDDFP#30, R5F104FEDFP#30, R5F104FFDFP#30, R5F104FGDFP#30, R5F104FHDFP#30, R5F104FJDFP#30	PLQP0044GC-A/ PLQP0044GC-D
			R5F104FADFP#50, R5F104FCDFP#50, R5F104FDDFP#50, R5F104FEDFP#50, R5F104FFDFP#50, R5F104FGDFP#50, R5F104FHDFP#50, R5F104FJDFP#50	
		G	R5F104FAGFP#V0, R5F104FCGFP#V0, R5F104FDGFP#V0, R5F104FEGFP#V0, R5F104FFGFP#V0, R5F104FGGFP#V0, R5F104FHGFP#V0, R5F104FJGFP#V0	PLQP0044GC-A
			R5F104FAGFP#X0, R5F104FCGFP#X0, R5F104FDGFP#X0, R5F104FEGFP#X0, R5F104FFGFP#X0, R5F104FGGFP#X0, R5F104FHGFP#X0, R5F104FJGFP#X0	
			R5F104FAGFP#30, R5F104FCGFP#30, R5F104FDGFP#30, R5F104FEGFP#30, R5F104FFGFP#30, R5F104FGGFP#30, R5F104FHGFP#30, R5F104FJGFP#30	PLQP0044GC-A/ PLQP0044GC-D
			R5F104FAGFP#50, R5F104FCGFP#50, R5F104FDGFP#50, R5F104FEGFP#50, R5F104FFGFP#50, R5F104FGGFP#50, R5F104FHGFP#50, R5F104FJGFP#50	

**Note** For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14.**

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

&lt;R&gt;

Table 1 - 1 List of Ordering Part Numbers (5/12)

Pin count	Package	Fields of Application Note	Ordering Part Number	RENESAS Code		
48 pins	48-pin plastic LFQFP (7 × 7 mm, 0.5 mm pitch)	A	R5F104GAAFB#V0, R5F104GCAFB#V0, R5F104GDADF#V0, R5F104GEAFB#V0, R5F104GFAFB#V0, R5F104GGAFB#V0, R5F104GHAFB#V0, R5F104GJAFB#V0	PLQP0048KF-A		
			R5F104GAAFB#X0, R5F104GCAFB#X0, R5F104GDADF#X0, R5F104GEAFB#X0, R5F104GFAFB#X0, R5F104GGAFB#X0, R5F104GHAFB#X0, R5F104GJAFB#X0			
			R5F104GAAFB#30, R5F104GCAFB#30, R5F104GDADF#30, R5F104GEAFB#30, R5F104GFAFB#30, R5F104GGAFB#30, R5F104GHAFB#30, R5F104GJAFB#30, R5F104GKAFB#30, R5F104GLAFB#30		PLQP0048KB-B	
		D	R5F104GADFB#V0, R5F104GCDFB#V0, R5F104GDDFB#V0, R5F104GEDFB#V0, R5F104GFDFB#V0, R5F104GGDFB#V0, R5F104GHDFB#V0, R5F104GJDFB#V0	PLQP0048KF-A		
			R5F104GADFB#X0, R5F104GCDFB#X0, R5F104GDDFB#X0, R5F104GEDFB#X0, R5F104GFDFB#X0, R5F104GGDFB#X0, R5F104GHDFB#X0, R5F104GJDFB#X0			
			R5F104GADFB#30, R5F104GCDFB#30, R5F104GDDFB#30, R5F104GEDFB#30, R5F104GFDFB#30, R5F104GGDFB#30, R5F104GHDFB#30, R5F104GJDFB#30		PLQP0048KB-B	
		G	R5F104GAGFB#V0, R5F104GCGFB#V0, R5F104GDGFB#V0, R5F104GEGFB#V0, R5F104GFGFB#V0, R5F104GGGFB#V0, R5F104GHGFB#V0, R5F104GJGFB#V0	PLQP0048KF-A		
			R5F104GAGFB#X0, R5F104GCGFB#X0, R5F104GDGFB#X0, R5F104GEGFB#X0, R5F104GFGFB#X0, R5F104GGGFB#X0, R5F104GHGFB#X0, R5F104GJGFB#X0			
			R5F104GAGFB#30, R5F104GCGFB#30, R5F104GDGFB#30, R5F104GEGFB#30, R5F104GFGFB#30, R5F104GGGFB#30, R5F104GHGFB#30, R5F104GJGFB#30, R5F104GKGF#30, R5F104GLGFB#30		PLQP0048KB-B	
					R5F104GAGFB#50, R5F104GCGFB#50, R5F104GDGFB#50, R5F104GEGFB#50, R5F104GFGFB#50, R5F104GGGFB#50, R5F104GHGFB#50, R5F104GJGFB#50, R5F104GKGF#50, R5F104GLGFB#50	

**Note** For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14**.

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.



&lt;R&gt;

Table 1 - 1 List of Ordering Part Numbers (6/12)

Pin count	Package	Fields of Application <small>Note</small>	Ordering Part Number	RENESAS Code
48 pins	48-pin plastic HWQFN (7 × 7 mm, 0.5 mm pitch)	A	R5F104GAANA#U0, R5F104GCANA#U0, R5F104GDANA#U0, R5F104GEANA#U0, R5F104GFANA#U0, R5F104GGANA#U0, R5F104GHANA#U0, R5F104GJANA#U0, R5F104GKANA#U0, R5F104GLANA#U0  R5F104GAANA#W0, R5F104GCANA#W0, R5F104GDANA#W0, R5F104GEANA#W0, R5F104GFANA#W0, R5F104GGANA#W0, R5F104GHANA#W0, R5F104GJANA#W0, R5F104GKANA#W0, R5F104GLANA#W0	PWQN0048KB-A
		D	R5F104GADNA#U0, R5F104GCDNA#U0, R5F104GDDNA#U0, R5F104GEDNA#U0, R5F104GFDNA#U0, R5F104GGDNA#U0, R5F104GHDNA#U0, R5F104GJDNA#U0  R5F104GADNA#W0, R5F104GCDNA#W0, R5F104GDDNA#W0, R5F104GEDNA#W0, R5F104GFDNA#W0, R5F104GGDNA#W0, R5F104GHDNA#W0, R5F104GJDNA#W0	
		G	R5F104GAGNA#U0, R5F104GCGNA#U0, R5F104GDGNA#U0, R5F104GEGNA#U0, R5F104GFGNA#U0, R5F104GGGNA#U0, R5F104GHGNA#U0, R5F104GJGNA#U0, R5F104GKGNA#U0, R5F104GLGNA#U0  R5F104GAGNA#W0, R5F104GCGNA#W0, R5F104GDGNA#W0, R5F104GEGNA#W0, R5F104GFGNA#W0, R5F104GGGNA#W0, R5F104GHGNA#W0, R5F104GJGNA#W0, R5F104GKGNA#W0, R5F104GLGNA#W0	

**Note** For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14**.

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

&lt;R&gt;

Table 1 - 1 List of Ordering Part Numbers (7/12)

Pin count	Package	Fields of Application Note	Ordering Part Number	RENESAS Code
52 pins	52-pin plastic LQFP (10 × 10 mm, 0.65 mm pitch)	A	R5F104JCAFA#V0, R5F104JDAFA#V0, R5F104JEAFA#V0, R5F104JFAFA#V0, R5F104JGFAFA#V0, R5F104JHFAFA#V0, R5F104JJFAFA#V0 R5F104JCAFA#X0, R5F104JDAFA#X0, R5F104JEAFA#X0, R5F104JFAFA#X0, R5F104JGFAFA#X0, R5F104JHFAFA#X0, R5F104JJFAFA#X0 R5F104JCAFA#30, R5F104JDAFA#30, R5F104JEAFA#30, R5F104JFAFA#30, R5F104JGFAFA#30, R5F104JHFAFA#30, R5F104JJFAFA#30 R5F104JCAFA#50, R5F104JDAFA#50, R5F104JEAFA#50, R5F104JFAFA#50, R5F104JGFAFA#50, R5F104JHFAFA#50, R5F104JJFAFA#50	PLQP0052JA-A
		D	R5F104JCDFA#V0, R5F104JDDFA#V0, R5F104JEDFA#V0, R5F104JFDFA#V0, R5F104JGDFA#V0, R5F104JHDFFA#V0, R5F104JJDFFA#V0 R5F104JCDFA#X0, R5F104JDDFA#X0, R5F104JEDFA#X0, R5F104JFDFA#X0, R5F104JGDFA#X0, R5F104JHDFFA#X0, R5F104JJDFFA#X0 R5F104JCDFA#30, R5F104JDDFA#30, R5F104JEDFA#30, R5F104JFDFA#30, R5F104JGDFA#30, R5F104JHDFFA#30, R5F104JJDFFA#30 R5F104JCDFA#50, R5F104JDDFA#50, R5F104JEDFA#50, R5F104JFDFA#50, R5F104JGDFA#50, R5F104JHDFFA#50, R5F104JJDFFA#50	
		G	R5F104JCGFA#V0, R5F104JDGFA#V0, R5F104JEGFA#V0, R5F104JFGFA#V0, R5F104JGGFA#V0, R5F104JHGFA#V0, R5F104JJGFA#V0 R5F104JCGFA#X0, R5F104JDGFA#X0, R5F104JEGFA#X0, R5F104JFGFA#X0, R5F104JGGFA#X0, R5F104JHGFA#X0, R5F104JJGFA#X0 R5F104JCGFA#30, R5F104JDGFA#30, R5F104JEGFA#30, R5F104JFGFA#30, R5F104JGGFA#30, R5F104JHGFA#30, R5F104JJGFA#30 R5F104JCGFA#50, R5F104JDGFA#50, R5F104JEGFA#50, R5F104JFGFA#50, R5F104JGGFA#50, R5F104JHGFA#50, R5F104JJGFA#50	

**Note** For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14**.

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

<R>

**Table 1 - 1 List of Ordering Part Numbers (8/12)**

Pin count	Package	Fields of Application Note	Ordering Part Number	RENESAS Code
64 pins	64-pin plastic LQFP (12 × 12 mm, 0.65 mm pitch)	A	R5F104LCAFA#V0, R5F104LDAFA#V0, R5F104LEAFA#V0, R5F104LFafa#V0, R5F104LGafa#V0, R5F104LHafa#V0, R5F104LJafa#V0 R5F104LCAFA#X0, R5F104LDAFA#X0, R5F104LEAFA#X0, R5F104LFafa#X0, R5F104LGafa#X0, R5F104LHafa#X0, R5F104LJafa#X0 R5F104LCAFA#30, R5F104LDAFA#30, R5F104LEAFA#30, R5F104LFafa#30, R5F104LGafa#30, R5F104LHafa#30, R5F104LJafa#30, R5F104LKafa#30, R5F104LLafa#30 R5F104LCAFA#50, R5F104LDAFA#50, R5F104LEAFA#50, R5F104LFafa#50, R5F104LGafa#50, R5F104LHafa#50, R5F104LJafa#50, R5F104LKafa#50, R5F104LLafa#50	PLQP0064JA-A
		D	R5F104LCDFA#V0, R5F104LDDFA#V0, R5F104LEDFA#V0, R5F104LFDFA#V0, R5F104LGDFA#V0, R5F104LHDFA#V0, R5F104LJDFA#V0 R5F104LCDFA#X0, R5F104LDDFA#X0, R5F104LEDFA#X0, R5F104LFDFA#X0, R5F104LGDFA#X0, R5F104LHDFA#X0, R5F104LJDFA#X0 R5F104LCDFA#30, R5F104LDDFA#30, R5F104LEDFA#30, R5F104LFDFA#30, R5F104LGDFA#30, R5F104LHDFA#30, R5F104LJDFA#30 R5F104LCDFA#50, R5F104LDDFA#50, R5F104LEDFA#50, R5F104LFDFA#50, R5F104LGDFA#50, R5F104LHDFA#50, R5F104LJDFA#50	
		G	R5F104LCGFA#V0, R5F104LDGFA#V0, R5F104LEGFA#V0, R5F104LFGFA#V0, R5F104LGGFA#V0, R5F104LHGFA#V0, R5F104LJGFA#V0 R5F104LCGFA#X0, R5F104LDGFA#X0, R5F104LEGFA#X0, R5F104LFGFA#X0, R5F104LGGFA#X0, R5F104LHGFA#X0, R5F104LJGFA#X0 R5F104LCGFA#30, R5F104LDGFA#30, R5F104LEGFA#30, R5F104LFGFA#30, R5F104LGGFA#30, R5F104LHGFA#30, R5F104LJGFA#30, R5F104LKGFA#30, R5F104LLGFA#30 R5F104LCGFA#50, R5F104LDGFA#50, R5F104LEGFA#50, R5F104LFGFA#50, R5F104LGGFA#50, R5F104LHGFA#50, R5F104LJGFA#50, R5F104LKGFA#50, R5F104LLGFA#50	

**Note** For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14.**

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

&lt;R&gt;

Table 1 - 1 List of Ordering Part Numbers (9/12)

Pin count	Package	Fields of Application Note	Ordering Part Number	RENESAS Code		
64 pins	64-pin plastic LFQFP (10 × 10 mm, 0.5 mm pitch)	A	R5F104LCAFB#V0, R5F104LDAFB#V0, R5F104LEAFB#V0, R5F104LFAFB#V0, R5F104LGAFB#V0, R5F104LHAFB#V0, R5F104LJAFB#V0	PLQP0064KF-A		
			R5F104LCAFB#X0, R5F104LDAFB#X0, R5F104LEAFB#X0, R5F104LFAFB#X0, R5F104LGAFB#X0, R5F104LHAFB#X0, R5F104LJAFB#X0			
			R5F104LCAFB#30, R5F104LDAFB#30, R5F104LEAFB#30, R5F104LFAFB#30, R5F104LGAFB#30, R5F104LHAFB#30, R5F104LJAFB#30, R5F104LKAFB#30, R5F104LLAFB#30	PLQP0064KB-C		
		D	R5F104LCDFB#V0, R5F104LDDFB#V0, R5F104LEDFB#V0, R5F104LDFB#V0, R5F104LGDFB#V0, R5F104LHDFB#V0, R5F104LJDFB#V0	PLQP0064KF-A		
			R5F104LCDFB#X0, R5F104LDDFB#X0, R5F104LEDFB#X0, R5F104LDFB#X0, R5F104LGDFB#X0, R5F104LHDFB#X0, R5F104LJDFB#X0			
			R5F104LCDFB#30, R5F104LDDFB#30, R5F104LEDFB#30, R5F104LDFB#30, R5F104LGDFB#30, R5F104LHDFB#30, R5F104LJDFB#30	PLQP0064KB-C		
		G	R5F104LCGFB#V0, R5F104LDGFB#V0, R5F104LEGFB#V0, R5F104LFGFB#V0, R5F104LGGFB#V0, R5F104LHGFB#V0, R5F104LJGFB#V0	PLQP0064KF-A		
			R5F104LCGFB#X0, R5F104LDGFB#X0, R5F104LEGFB#X0, R5F104LFGFB#X0, R5F104LGGFB#X0, R5F104LHGFB#X0, R5F104LJGFB#X0			
			R5F104LCGFB#30, R5F104LDGFB#30, R5F104LEGFB#30, R5F104LFGFB#30, R5F104LGGFB#30, R5F104LHGFB#30, R5F104LJGFB#30, R5F104LKGFB#30, R5F104LLGFB#30	PLQP0064KB-C		
					R5F104LCGFB#50, R5F104LDGFB#50, R5F104LEGFB#50, R5F104LFGFB#50, R5F104LGGFB#50, R5F104LHGFB#50, R5F104LJGFB#50, R5F104LKGFB#50, R5F104LLGFB#50	

**Note** For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14**.

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

&lt;R&gt;

Table 1 - 1 List of Ordering Part Numbers (10/12)

Pin count	Package	Fields of Application Note	Ordering Part Number	RENESAS Code
64 pins	64-pin plastic FLGA (5 × 5 mm, 0.5 mm pitch)	A	R5F104LCALA#U0, R5F104LDALA#U0, R5F104LEALA#U0, R5F104LFALA#U0, R5F104LGALA#U0, R5F104LHALA#U0, R5F104LJALA#U0, R5F104LKALA#U0, R5F104LLALA#U0  R5F104LCALA#W0, R5F104LDALA#W0, R5F104LEALA#W0, R5F104LFALA#W0, R5F104LGALA#W0, R5F104LHALA#W0, R5F104LJALA#W0, R5F104LKALA#W0, R5F104LLALA#W0	PWLG0064KA-A
		G	R5F104LCGLA#U0, R5F104LDGLA#U0, R5F104LEGLA#U0, R5F104LFGLA#U0, R5F104LGGLA#U0, R5F104LHGLA#U0, R5F104LJGLA#U0, R5F104LKGLA#U0, R5F104LLGLA#U0  R5F104LCGLA#W0, R5F104LDGLA#W0, R5F104LEGLA#W0, R5F104LFGLA#W0, R5F104LGGLA#W0, R5F104LHGLA#W0, R5F104LJGLA#W0, R5F104LKGLA#W0, R5F104LLGLA#W0	
64-pin plastic LQFP (14 × 14 mm, 0.8 mm pitch)		A	R5F104LCAFP#V0, R5F104LDAFP#V0, R5F104LEAFP#V0, R5F104LFAFP#V0, R5F104LGAFP#V0, R5F104LHAFP#V0, R5F104LJAFP#V0  R5F104LCAFP#X0, R5F104LDAFP#X0, R5F104LEAFP#X0, R5F104LFAFP#X0, R5F104LGAFP#X0, R5F104LHAFP#X0, R5F104LJAFP#X0  R5F104LCAFP#30, R5F104LDAFP#30, R5F104LEAFP#30, R5F104LFAFP#30, R5F104LGAFP#30, R5F104LHAFP#30, R5F104LJAFP#30  R5F104LCAFP#50, R5F104LDAFP#50, R5F104LEAFP#50, R5F104LFAFP#50, R5F104LGAFP#50, R5F104LHAFP#50, R5F104LJAFP#50	PLQP0064GA-A
		D	R5F104LCDFP#V0, R5F104LDDFP#V0, R5F104LEDFP#V0, R5F104LDFDP#V0, R5F104LGDFP#V0, R5F104LHDFP#V0, R5F104LJDFP#V0  R5F104LCDFP#X0, R5F104LDDFP#X0, R5F104LEDFP#X0, R5F104LDFDP#X0, R5F104LGDFP#X0, R5F104LHDFP#X0, R5F104LJDFP#X0  R5F104LCDFP#30, R5F104LDDFP#30, R5F104LEDFP#30, R5F104LDFDP#30, R5F104LGDFP#30, R5F104LHDFP#30, R5F104LJDFP#30  R5F104LCDFP#50, R5F104LDDFP#50, R5F104LEDFP#50, R5F104LDFDP#50, R5F104LGDFP#50, R5F104LHDFP#50, R5F104LJDFP#50	
		G	R5F104LCGFP#V0, R5F104LDGFP#V0, R5F104LEGFP#V0, R5F104LFGFP#V0, R5F104LGGFP#V0, R5F104LHGFP#V0, R5F104LJGFP#V0  R5F104LCGFP#X0, R5F104LDGFP#X0, R5F104LEGFP#X0, R5F104LFGFP#X0, R5F104LGGFP#X0, R5F104LHGFP#X0, R5F104LJGFP#X0  R5F104LCGFP#30, R5F104LDGFP#30, R5F104LEGFP#30, R5F104LFGFP#30, R5F104LGGFP#30, R5F104LHGFP#30, R5F104LJGFP#30  R5F104LCGFP#50, R5F104LDGFP#50, R5F104LEGFP#50, R5F104LFGFP#50, R5F104LGGFP#50, R5F104LHGFP#50, R5F104LJGFP#50	

**Note** For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14**.

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

<R>

**Table 1 - 1 List of Ordering Part Numbers (11/12)**

Pin count	Package	Fields of Application Note	Ordering Part Number	RENESAS Code
80 pins	80-pin plastic LFQFP (12 × 12 mm, 0.5 mm pitch)	A	R5F104MFAFB#V0, R5F104MGAFB#V0, R5F104MHAFB#V0, R5F104MJAFB#V0	PLQP0080KE-A
			R5F104MFAFB#X0, R5F104MGAFB#X0, R5F104MHAFB#X0, R5F104MJAFB#X0	
			R5F104MFAFB#30, R5F104MGAFB#30, R5F104MHAFB#30, R5F104MJAFB#30, R5F104MKAFB#30, R5F104MLAFB#30	PLQP0080KB-B
			R5F104MFAFB#50, R5F104MGAFB#50, R5F104MHAFB#50, R5F104MJAFB#50, R5F104MKAFB#50, R5F104MLAFB#50	
		D	R5F104MFDFB#V0, R5F104MGDFB#V0, R5F104MHDFB#V0, R5F104MJDFB#V0	PLQP0080KE-A
			R5F104MFDFB#X0, R5F104MGDFB#X0, R5F104MHDFB#X0, R5F104MJDFB#X0	
			R5F104MFDFB#30, R5F104MGDFB#30, R5F104MHDFB#30, R5F104MJDFB#30	PLQP0080KB-B
			R5F104MFDFB#50, R5F104MGDFB#50, R5F104MHDFB#50, R5F104MJDFB#50	
		G	R5F104MFGFB#V0, R5F104MGGFB#V0, R5F104MHGFB#V0, R5F104MJGFB#V0	PLQP0080KE-A
			R5F104MFGFB#X0, R5F104MGGFB#X0, R5F104MHGFB#X0, R5F104MJGFB#X0	
			R5F104MFGFB#30, R5F104MGGFB#30, R5F104MHGFB#30, R5F104MJGFB#30, R5F104MKGFB#30, R5F104MLGFB#30	PLQP0080KB-B
			R5F104MFGFB#50, R5F104MGGFB#50, R5F104MHGFB#50, R5F104MJGFB#50, R5F104MKGFB#50, R5F104MLGFB#50	
	80-pin plastic LQFP (14 × 14 mm, 0.65 mm pitch)	A	R5F104MFafa#V0, R5F104MGafa#V0, R5F104MHafa#V0, R5F104MJafa#V0	PLQP0080JB-E
			R5F104MFafa#X0, R5F104MGafa#X0, R5F104MHafa#X0, R5F104MJafa#X0	
			R5F104MFafa#30, R5F104MGafa#30, R5F104MHafa#30, R5F104MJafa#30, R5F104MKafa#30, R5F104MLafa#30	
			R5F104MFafa#50, R5F104MGafa#50, R5F104MHafa#50, R5F104MJafa#50, R5F104MKafa#50, R5F104MLafa#50	
		D	R5F104MFDfa#V0, R5F104MGdfa#V0, R5F104MHDfa#V0, R5F104MJdfa#V0	
			R5F104MFDfa#X0, R5F104MGdfa#X0, R5F104MHDfa#X0, R5F104MJdfa#X0	
			R5F104MFDfa#30, R5F104MGdfa#30, R5F104MHDfa#30, R5F104MJdfa#30	
			R5F104MFDfa#50, R5F104MGdfa#50, R5F104MHDfa#50, R5F104MJdfa#50	
		G	R5F104MFGfa#V0, R5F104MGGfa#V0, R5F104MHGfa#V0, R5F104MJGfa#V0	
			R5F104MFGfa#X0, R5F104MGGfa#X0, R5F104MHGfa#X0, R5F104MJGfa#X0	
			R5F104MFGfa#30, R5F104MGGfa#30, R5F104MHGfa#30, R5F104MJGfa#30, R5F104MKGfa#30, R5F104MLGfa#30	
			R5F104MFGfa#50, R5F104MGGfa#50, R5F104MHGfa#50, R5F104MJGfa#50, R5F104MKGfa#50, R5F104MLGfa#50	

**Note** For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14**.

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

&lt;R&gt;

Table 1 - 1 List of Ordering Part Numbers (12/12)

Pin count	Package	Fields of Application Note	Ordering Part Number	RENESAS Code	
100 pins	100-pin plastic LFQFP (14 × 14 mm, 0.5 mm pitch)	A	R5F104PFAFB#V0, R5F104PGAFA#V0, R5F104PHAFB#V0, R5F104PJAFB#V0	PLQP0100KE-A	
			R5F104PFAFB#X0, R5F104PGAFA#X0, R5F104PHAFB#X0, R5F104PJAFB#X0		
			R5F104PFAFB#30, R5F104PGAFA#30, R5F104PHAFB#30, R5F104PJAFB#30, R5F104PKAFB#30, R5F104PLAFB#30	PLQP0100KB-B	
			R5F104PFAFB#50, R5F104PGAFA#50, R5F104PHAFB#50, R5F104PJAFB#50, R5F104PKAFB#50, R5F104PLAFB#50		
			D	R5F104PFDFB#V0, R5F104PGDFB#V0, R5F104PHDFB#V0, R5F104PJDFB#V0	PLQP0100KE-A
				R5F104PFDFB#X0, R5F104PGDFB#X0, R5F104PHDFB#X0, R5F104PJDFB#X0	
		R5F104PFDFB#30, R5F104PGDFB#30, R5F104PHDFB#30, R5F104PJDFB#30		PLQP0100KB-B	
		R5F104PFDFB#50, R5F104PGDFB#50, R5F104PHDFB#50, R5F104PJDFB#50			
		G		R5F104PFGFB#V0, R5F104PGGFB#V0, R5F104PHGFB#V0, R5F104PJGFB#V0	PLQP0100KE-A
				R5F104PFGFB#X0, R5F104PGGFB#X0, R5F104PHGFB#X0, R5F104PJGFB#X0	
			R5F104PFGFB#30, R5F104PGGFB#30, R5F104PHGFB#30, R5F104PJGFB#30, R5F104PKGFB#30, R5F104PLGFB#30	PLQP0100KB-B	
			R5F104PFGFB#50, R5F104PGGFB#50, R5F104PHGFB#50, R5F104PJGFB#50, R5F104PKGFB#50, R5F104PLGFB#50		
100-pin plastic LQFP (14 × 20 mm, 0.65 mm pitch)	A		R5F104PFafa#V0, R5F104PGAfa#V0, R5F104PHafa#V0, R5F104PJafa#V0	PLQP0100JC-A	
			R5F104PFafa#X0, R5F104PGAfa#X0, R5F104PHafa#X0, R5F104PJafa#X0		
		R5F104PFafa#30, R5F104PGAfa#30, R5F104PHafa#30, R5F104PJafa#30, R5F104PKafa#30, R5F104PLafa#30			
		R5F104PFafa#50, R5F104PGAfa#50, R5F104PHafa#50, R5F104PJafa#50, R5F104PKafa#50, R5F104PLafa#50			
		D	R5F104PFdFa#V0, R5F104PGdFa#V0, R5F104PHdFa#V0, R5F104PJdFa#V0		
			R5F104PFdFa#X0, R5F104PGdFa#X0, R5F104PHdFa#X0, R5F104PJdFa#X0		
	R5F104PFdFa#30, R5F104PGdFa#30, R5F104PHdFa#30, R5F104PJdFa#30				
	G	R5F104PFGfa#V0, R5F104PGGfa#V0, R5F104PHGfa#V0, R5F104PJGfa#V0			
		R5F104PFGfa#X0, R5F104PGGfa#X0, R5F104PHGfa#X0, R5F104PJGfa#X0			
R5F104PFGfa#30, R5F104PGGfa#30, R5F104PHGfa#30, R5F104PJGfa#30, R5F104PKGfa#30, R5F104PLGfa#30					

**Note** For the fields of application, refer to **Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14**.

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

## 1.3 Pin Configuration (Top View)

### 1.3.1 30-pin products

- 30-pin plastic LSSOP (7.62 mm (300), 0.65 mm pitch)



**Note** Mounted on the 96 KB or more code flash memory products.

**Caution** Connect the REGC pin to V<sub>SS</sub> pin via a capacitor (0.47 to 1  $\mu$ F).

**Remark 1.** For pin identification, see 1.4 Pin Identification.

**Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).



### 1.3.2 32-pin products

- 32-pin plastic HWQFN (5 × 5 mm, 0.5 mm pitch)



**Note** Mounted on the 96 KB or more code flash memory products.

**Caution** Connect the REGC pin to V<sub>SS</sub> pin via a capacitor (0.47 to 1 μF).

**Remark 1.** For pin identification, see 1.4 Pin Identification.

**Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

**Remark 3.** It is recommended to connect an exposed die pad to V<sub>SS</sub>.

- 32-pin plastic LQFP (7 × 7 mm, 0.8 mm pitch)



**Note** Mounted on the 96 KB or more code flash memory products.

**Caution** Connect the REGC pin to V<sub>SS</sub> pin via a capacitor (0.47 to 1 μF).

**Remark 1.** For pin identification, see 1.4 Pin Identification.

**Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

### 1.3.3 36-pin products

- 36-pin plastic WFLGA (4 × 4 mm, 0.5 mm pitch)



	A	B	C	D	E	F	
6	P60/SCLA0	V <sub>DD</sub>	P121/X1	P122/X2/EXCLK	P137/INTP0	P40/TOOL0	6
5	P62/ $\overline{\text{SSI00}}$	P61/SDAA0	V <sub>SS</sub>	REGC	$\overline{\text{RESET}}$	P120/ANI19/ VCOUT0 Note	5
4	P72/SO21	P71/SI21/ SDA21	P14/RxD2/SI20/ SDA20/TRDIOD0/ (SCLA0)	P31/TI03/TO03/ INTP4/PCLBUZ0/ (TRJIO0)	P00/TI00/TxD1/ TRGCLKA/ (TRJO0)	P01/TO00/ RxD1/TRGCLKB/ TRJIO0	4
3	P50/INTP1/ SI00/RxD0/ TOOLRxD/ SDA00/TRGIOA/ (TRJO0)	P70/SCK21/ SCL21	P15/PCLBUZ1/ SCK20/SCL20/ TRDIOB0/ (SDAA0)	P22/ANI2/ ANO0 Note	P20/ANI0/ AVREFP	P21/ANI1/ AVREFM	3
2	P30/INTP3/ SCK00/SCL00/ TRJO0	P16/TI01/TO01/ INTP5/TRDIOC0/ IVREF0 Note/ (RXD0)	P12/SO11/ TRDIOB1/ IVREF1 Note	P11/SI11/ SDA11/ TRDIOC1	P24/ANI4	P23/ANI3/ ANO1 Note	2
1	P51/INTP2/ SO00/TxD0/ TOOLTxD/ TRGIOB	P17/TI02/TO02/ TRDIOA0/ TRDCLK/ IVCMP0 Note/ (TXD0)	P13/TxD2/ SO20/TRDIOA1/ IVCMP1 Note	P10/SCK11/ SCL11/ TRDIOD1	P147/ANI18/ VCOUT1 Note	P25/ANI5	1
	A	B	C	D	E	F	

**Note** Mounted on the 96 KB or more code flash memory products.

**Caution** Connect the REGC pin to V<sub>SS</sub> pin via a capacitor (0.47 to 1 μF).

**Remark 1.** For pin identification, see 1.4 Pin Identification.

**Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

### 1.3.4 40-pin products

- 40-pin plastic HWQFN (6 × 6 mm, 0.5 mm pitch)



**Note** Mounted on the 96 KB or more code flash memory products.

**Caution** Connect the REGC pin to Vss pin via a capacitor (0.47 to 1 μF).

**Remark 1.** For pin identification, see 1.4 Pin Identification.

**Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

**Remark 3.** It is recommended to connect an exposed die pad to Vss.

### 1.3.5 44-pin products

- 44-pin plastic LQFP (10 × 10 mm, 0.8 mm pitch)



**Note** Mounted on the 96 KB or more code flash memory products.

**Caution** Connect the REGC pin to V<sub>SS</sub> pin via a capacitor (0.47 to 1 μF).

**Remark 1.** For pin identification, see 1.4 Pin Identification.

**Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

### 1.3.6 48-pin products

- 48-pin plastic LQFP (7 × 7 mm, 0.5 mm pitch)



**Note 1.** Mounted on the 96 KB or more code flash memory products.

**Note 2.** Mounted on the 384 KB or more code flash memory products.

**Caution** Connect the REGC pin to Vss pin via a capacitor (0.47 to 1 μF).

**Remark 1.** For pin identification, see 1.4 Pin Identification.

**Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

- 48-pin plastic HWQFN (7 × 7 mm, 0.5 mm pitch)



**Note 1.** Mounted on the 96 KB or more code flash memory products.

**Note 2.** Mounted on the 384 KB or more code flash memory products.

**Caution** Connect the REGC pin to V<sub>SS</sub> pin via a capacitor (0.47 to 1 μF).

**Remark 1.** For pin identification, see 1.4 Pin Identification.

**Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

**Remark 3.** It is recommended to connect an exposed die pad to V<sub>SS</sub>.

### 1.3.7 52-pin products

- 52-pin plastic LQFP (10 × 10 mm, 0.65 mm pitch)



**Note** Mounted on the 96 KB or more code flash memory products.

**Caution** Connect the REGC pin to Vss pin via a capacitor (0.47 to 1 μF).

**Remark 1.** For pin identification, see 1.4 Pin Identification.

**Remark 2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).



### 1.3.8 64-pin products

- 64-pin plastic LQFP (14 × 14 mm, 0.8 mm pitch)
- 64-pin plastic LQFP (12 × 12 mm, 0.65 mm pitch)
- 64-pin plastic LFQFP (10 × 10 mm, 0.5 mm pitch)



**Note 1.** Mounted on the 96 KB or more code flash memory products.  
**Note 2.** Mounted on the 384 KB or more code flash memory products.

- Caution 1.** Make EVSS0 pin the same potential as Vss pin.  
**Caution 2.** Make VDD pin the potential that is higher than EVDD0 pin.  
**Caution 3.** Connect the REGC pin to Vss pin via a capacitor (0.47 to 1 μF).

- Remark 1.** For pin identification, see 1.4 Pin Identification.  
**Remark 2.** When using the microcontroller for an application where the noise generated inside the microcontroller must be reduced, it is recommended to supply separate powers to the VDD and EVDD0 pins and connect the Vss and EVSS0 pins to separate ground lines.  
**Remark 3.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

- 64-pin plastic FLGA (5 × 5 mm, 0.5 mm pitch)



	A	B	C	D	E	F	G	H	
8	EVDD0	EVSS0	P121/X1	P122/X2/ EXCLK	P137/INTP0	P123/XT1	P124/XT2/ EXCLKS	P120/ANI19/ VCOUT0 Note 1	8
7	P60/SCLA0	VDD	VSS	REGC	RESET	P01/TO00/ TRGCLKB/ TRJIO0	P00/TI00/ TRGCLKA/ (TRJIO0)	P140/ PCLBUZ0/ INTP6	7
6	P61/SDAA0	P62/SSIO0	P63	P40/TOOL0	P41/(TRJIO0)	P43/(INTP9)	P02/ANI17/ SO10/TxD1	P141/ PCLBUZ1/ INTP7	6
5	P77/KR7/ INTP11/(TXD2)	P31/TI03/ TO03/INTP4/ (PCLBUZ0)/ (TRJIO0)	P53/(INTP2)	P42/(INTP8)	P03/ANI16/ SI10/RxD1/ SDA10	P04/SCK10/ SCL10	P130	P20/ANI0/ AVREFF	5
4	P75/KR5/ INTP9/ SCK01/ SCL01	P76/KR6/ INTP10/ (RxD2)	P52/(INTP1)	P54/(INTP3)	P16/TI01/ TO01/INTP5/ TRDI0C0/ IVREF0 Note 1/ (SI00)/(RxD0)	P21/ANI1/ AVREFM	P22/ANI2/ ANO0 Note 1	P23/ANI3/ ANO1 Note 1	4
3	P70/KR0/ SCK21/ SCL21	P73/KR3/ SO01	P74/KR4/ INTP8/SI01/ SDA01	P17/TI02/TO02/ TRDIOA0/ TRDCLK/ IVCMP0 Note 1/ (SO00)/(TXD0)	P15/SCK20/ SCL20/ TRDIOB0/ (SDAA0)	P12/SO11/ TRDIOB1/ IVREF1 Note 1/ (INTP5)/ (TxD0_1) Note 2	P24/ANI4	P26/ANI6	3
2	P30/INTP3/ RTC1HZ/ SCK00/ SCL00/TRJIO0	P72/KR2/ SO21	P71/KR1/ SI21/SDA21	P06/(INTP11)/ (TRJIO0)	P14/RxD2/ SI20/SDA20/ TRDIOD0/ (SCLA0)	P11/SI11/ SDA11/ TRDI0C1/ (RxD0_1) Note 2	P25/ANI5	P27/ANI7	2
1	P05/(INTP10)	P50/INTP1/ SI00/RxD0/ TOOLRxD/ SDA00/ TRGIOA/ (TRJIO0)	P51/INTP2/ SO00/TxD0/ TOOLTxD/ TRGIOB	P55/ (PCLBUZ1)/ (SCK00)/ (INTP4)	P13/TxD2/ SO20/ TRDIOA1/ IVCMP1 Note 1	P10/SCK11/ SCL11/ TRDIOD1	P146	P147/ANI18/ VCOUT1 Note 1	1
	A	B	C	D	E	F	G	H	

- Note 1.** Mounted on the 96 KB or more code flash memory products.  
**Note 2.** Mounted on the 384 KB or more code flash memory products.

- Caution 1.** Make EVSS0 pin the same potential as VSS pin.  
**Caution 2.** Make VDD pin the potential that is higher than EVDD0 pin.  
**Caution 3.** Connect the REGC pin to VSS pin via a capacitor (0.47 to 1 μF).

- Remark 1.** For pin identification, see 1.4 Pin Identification.  
**Remark 2.** When using the microcontroller for an application where the noise generated inside the microcontroller must be reduced, it is recommended to supply separate powers to the VDD and EVDD0 pins and connect the VSS and EVSS0 pins to separate ground lines.  
**Remark 3.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

### 1.3.9 80-pin products

- 80-pin plastic LQFP (14 × 14 mm, 0.65 mm pitch)
- 80-pin plastic LFQFP (12 × 12 mm, 0.5 mm pitch)



**Note** Mounted on the 384 KB or more code flash memory products.

**Caution 1.** Make EV<sub>SS0</sub> pin the same potential as V<sub>SS</sub> pin.

**Caution 2.** Make V<sub>DD</sub> pin the potential that is higher than EV<sub>DD0</sub> pin.

**Caution 3.** Connect the REGC pin to V<sub>SS</sub> pin via a capacitor (0.47 to 1 μF).

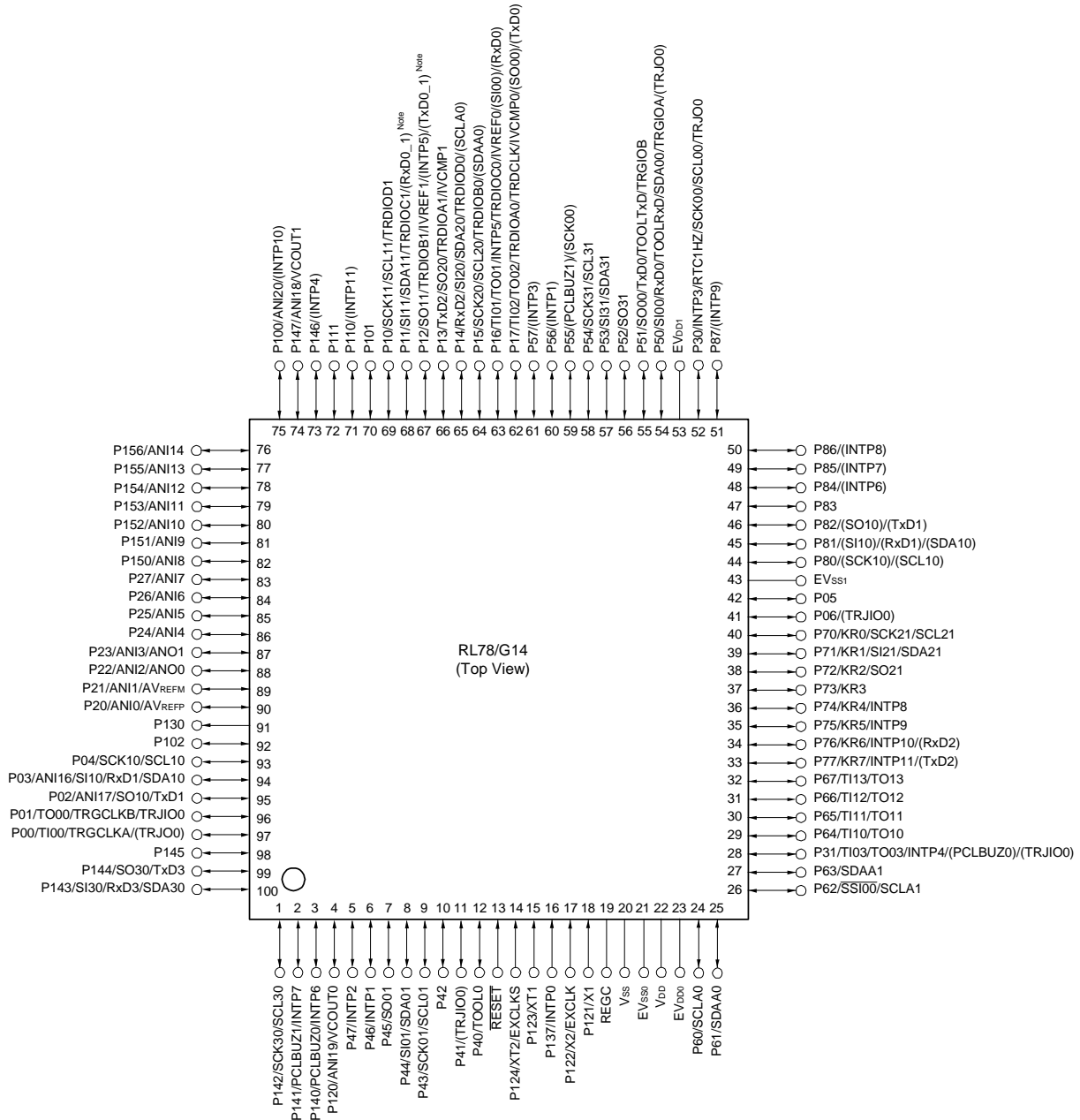
**Remark 1.** For pin identification, see 1.4 Pin Identification.

**Remark 2.** When using the microcontroller for an application where the noise generated inside the microcontroller must be reduced, it is recommended to supply separate powers to the V<sub>DD</sub> and EV<sub>DD0</sub> pins and connect the V<sub>SS</sub> and EV<sub>SS0</sub> pins to separate ground lines.

**Remark 3.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

### 1.3.10 100-pin products

- 100-pin plastic LFQFP (14 × 14 mm, 0.5 mm pitch)



**Note** Mounted on the 384 KB or more code flash memory products.

**Caution 1.** Make EVss0, EVss1 pins the same potential as Vss pin.

**Caution 2.** Make VDD pin the potential that is higher than EVDD0, EVDD1 pins (EVDD0 = EVDD1).

**Caution 3.** Connect the REGC pin to Vss pin via a capacitor (0.47 to 1 μF).

**Remark 1.** For pin identification, see 1.4 Pin Identification.

**Remark 2.** When using the microcontroller for an application where the noise generated inside the microcontroller must be reduced, it is recommended to supply separate powers to the VDD, EVDD0 and EVDD1 pins and connect the Vss, EVss0 and EVss1 pins to separate ground lines.

**Remark 3.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

- 100-pin plastic LQFP (14 × 20 mm, 0.65 mm pitch)



**Note** Mounted on the 384 KB or more code flash memory products.

**Caution 1.** Make EV<sub>SS0</sub>, EV<sub>SS1</sub> pins the same potential as V<sub>SS</sub> pin.

**Caution 2.** Make V<sub>DD</sub> pin the potential that is higher than EV<sub>DD0</sub>, EV<sub>DD1</sub> pins (EV<sub>DD0</sub> = EV<sub>DD1</sub>).

**Caution 3.** Connect the REGC pin to V<sub>SS</sub> pin via a capacitor (0.47 to 1 μF).

**Remark 1.** For pin identification, see 1.4 Pin Identification.

**Remark 2.** When using the microcontroller for an application where the noise generated inside the microcontroller must be reduced, it is recommended to supply separate powers to the V<sub>DD</sub>, EV<sub>DD0</sub> and EV<sub>DD1</sub> pins and connect the V<sub>SS</sub>, EV<sub>SS0</sub> and EV<sub>SS1</sub> pins to separate ground lines.

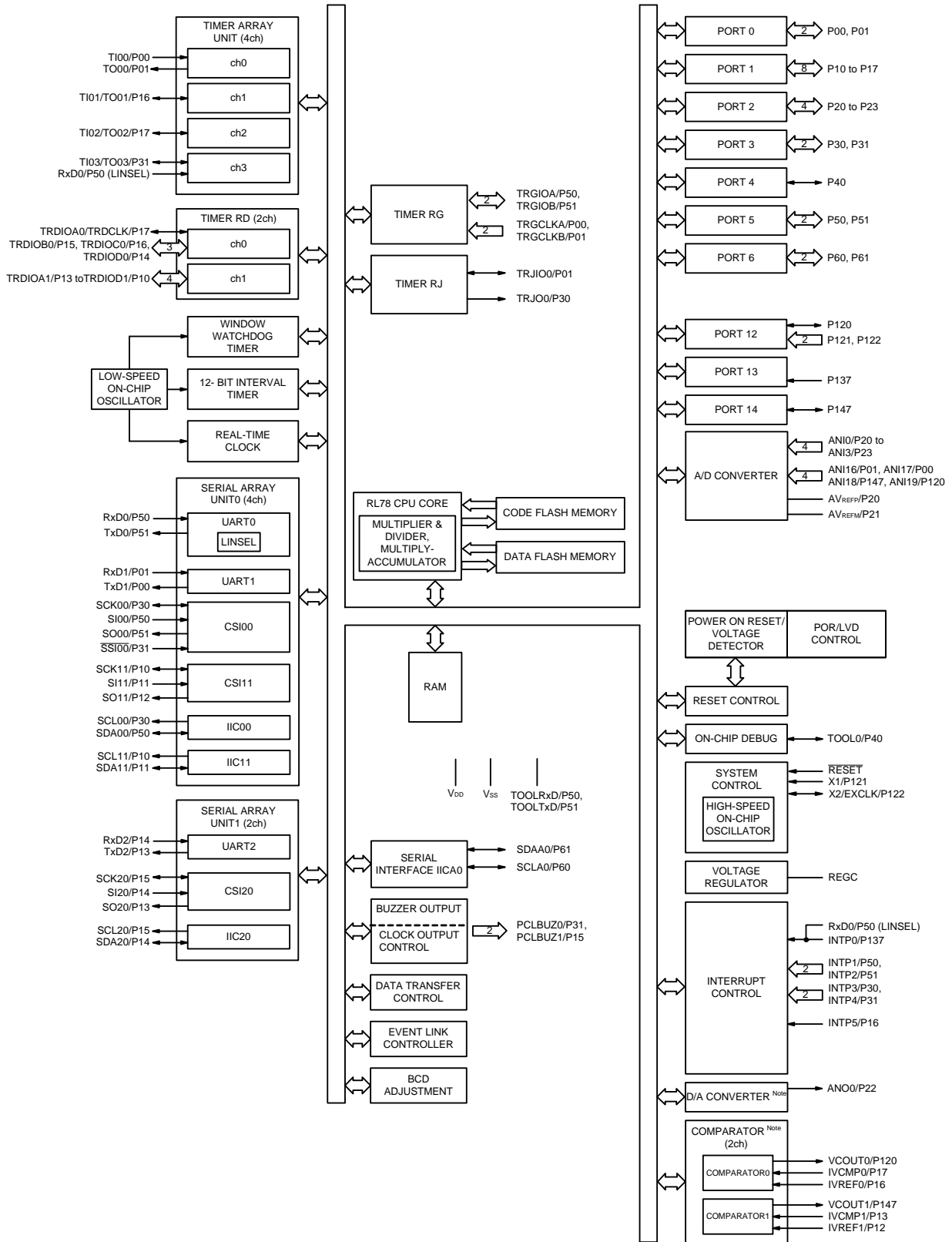
**Remark 3.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register 0, 1 (PIOR0, 1).

## 1.4 Pin Identification

ANI0 to ANI14,		RxD0 to RxD3:	Receive data
ANI16 to ANI20:	Analog output	SCK00, SCK01, SCK10,	
ANO0, ANO1:	Analog output	SCK11, SCK20, SCK21,	
AVREFM:	A/D converter reference potential (– side) input	SCK30, SCK31,	
AVREFF:	A/D converter reference potential (+ side) input	SCLA0, SCLA1:	Serial clock input/output
EVDD0, EVDD1:	Power supply for port	SCL00, SCL01, SCL10, SCL11,	
EVSS0, EVSS1:	Ground for port	SCL20, SCL21, SCL30,	
EXCLK:	External clock input (main system clock)	SCL31:	Serial clock output
EXCLKS:	External clock input (subsystem clock)	SDAA0, SDAA1, SDA00,	
INTP0 to INTP11:	External interrupt input	SDA01, SDA10, SDA11,	
IVCMP0, IVCMP1:	Comparator input	SDA20, SDA21, SDA30,	
IVREF0, IVREF1:	Comparator reference input	SDA31:	Serial data input/output
KR0 to KR7:	Key return	SI00, SI01, SI10, SI11,	
P00 to P06:	Port 0	SI20, SI21, SI30, SI31:	Serial data input
P10 to P17:	Port 1	SO00, SO01, SO10,	
P20 to P27:	Port 2	SO11, SO20, SO21,	
P30, P31:	Port 3	SO30, SO31:	Serial data output
P40 to P47:	Port 4	$\overline{\text{SSI00}}$ :	Serial interface chip select input
P50 to P57:	Port 5	TI00 to TI03,	
P60 to P67:	Port 6	TI10 to TI13:	Timer input
P70 to P77:	Port 7	TO00 to TO03,	
P80 to P87:	Port 8	TO10 to TO13, TRJ00:	Timer output
P100 to P102:	Port 10	TOOL0:	Data input/output for tool
P110, P111:	Port 11	TOOLRxD, TOOLTxD:	Data input/output for external device
P120 to P124:	Port 12	TRDCLK, TRGCLKA,	
P130, P137:	Port 13	TRGCLKB:	Timer external input clock
P140 to P147:	Port 14	TRDIOA0, TRDIOB0,	
P150 to P156:	Port 15	TRDIOC0, TRDIOD0,	
PCLBUZ0, PCLBUZ1:	Programmable clock output/buzzer output	TRDIOA1, TRDIOB1,	
REGC:	Regulator capacitance	TRDIOC1, TRDIOD1,	
$\overline{\text{RESET}}$ :	Reset	TRGIOA, TRGIOB, TRJIO0:	Timer input/output
RTC1HZ:	Real-time clock correction clock (1 Hz) output	TxD0 to TxD3:	Transmit data
		VCOUT0, VCOUT1:	Comparator output
		VDD:	Power supply
		VSS:	Ground
		X1, X2:	Crystal oscillator (main system clock)
		XT1, XT2:	Crystal oscillator (subsystem clock)

1.5 Block Diagram

1.5.1 30-pin products



Note Mounted on the 96 KB or more code flash memory products.

### 1.5.2 32-pin products



**Note** Mounted on the 96 KB or more code flash memory products.



### 1.5.3 36-pin products



**Note** Mounted on the 96 KB or more code flash memory products.

1.5.4 40-pin products



**Note** Mounted on the 96 KB or more code flash memory products.

### 1.5.5 44-pin products



**Note** Mounted on the 96 KB or more code flash memory products.

1.5.6 48-pin products



**Note** Mounted on the 96 KB or more code flash memory products.

1.5.7 52-pin products



**Note** Mounted on the 96 KB or more code flash memory products.

1.5.8 64-pin products



**Note** Mounted on the 96 KB or more code flash memory products.

1.5.9 80-pin products



1.5.10 100-pin products





## 1.6 Outline of Functions

[30-pin, 32-pin, 36-pin, 40-pin products (code flash memory 16 KB to 64 KB)]

**Caution** This outline describes the functions at the time when Peripheral I/O redirection register 0, 1 (PIOR0, 1) are set to 00H.

(1/2)

Item		30-pin	32-pin	36-pin	40-pin
		R5F104Ax (x = A, C to E)	R5F104Bx (x = A, C to E)	R5F104Cx (x = A, C to E)	R5F104Ex (x = A, C to E)
Code flash memory (KB)		16 to 64	16 to 64	16 to 64	16 to 64
Data flash memory (KB)		4	4	4	4
RAM (KB)		2.5 to 5.5 Note	2.5 to 5.5 Note	2.5 to 5.5 Note	2.5 to 5.5 Note
Address space		1 MB			
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (high-speed main) mode: 1 to 20 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)			
	High-speed on-chip oscillator clock (f <sub>IH</sub> )	HS (high-speed main) mode: 1 to 32 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)			
Subsystem clock		—			XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz
Low-speed on-chip oscillator clock		15 kHz (TYP.): V <sub>DD</sub> = 1.6 to 5.5 V			
General-purpose register		8 bits × 32 registers (8 bits × 8 registers × 4 banks)			
Minimum instruction execution time		0.03125 μs (High-speed on-chip oscillator clock: f <sub>IH</sub> = 32 MHz operation)			
		0.05 μs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)			
		—			30.5 μs (Subsystem clock: f <sub>SUB</sub> = 32.768 kHz operation)
Instruction set		<ul style="list-style-type: none"> <li>Data transfer (8/16 bits)</li> <li>Adder and subtractor/logical operation (8/16 bits)</li> <li>Multiplication (8 bits × 8 bits, 16 bits × 16 bits), Division (16 bits ÷ 16 bits, 32 bits ÷ 32 bits)</li> <li>Multiplication and Accumulation (16 bits × 16 bits + 32 bits)</li> <li>Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li> </ul>			
I/O port	Total	26	28	32	36
	CMOS I/O	21	22	26	28
	CMOS input	3	3	3	5
	CMOS output	—	—	—	—
	N-ch open-drain I/O (6 V tolerance)	2	3	3	3
Timer	16-bit timer	8 channels (TAU: 4 channels, Timer RJ: 1 channel, Timer RD: 2 channels, Timer RG: 1 channel)			
	Watchdog timer	1 channel			
	Real-time clock (RTC)	1 channel			
	12-bit interval timer	1 channel			
	Timer output	Timer outputs: 13 channels PWM outputs: 9 channels			
	RTC output	—			1 • 1 Hz (subsystem clock: f <sub>SUB</sub> = 32.768 kHz)

(Note is listed on the next page.)

**Note** The flash library uses RAM in self-programming and rewriting of the data flash memory.  
The target products and start address of the RAM areas used by the flash library are shown below.  
R5F104xD (x = A to C, E to G, J, L): Start address FE900H  
R5F104xE (x = A to C, E to G, J, L): Start address FE900H  
For the RAM areas used by the flash library, see **Self RAM list of Flash Self-Programming Library for RL78 Family (R20UT2944)**.

(2/2)

Item	30-pin	32-pin	36-pin	40-pin
	R5F104Ax (x = A, C to E)	R5F104Bx (x = A, C to E)	R5F104Cx (x = A, C to E)	R5F104Ex (x = A, C to E)
Clock output/buzzer output	2	2	2	2
	[30-pin, 32-pin, 36-pin products] • 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: $f_{MAIN} = 20$ MHz operation) [40-pin products] • 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: $f_{MAIN} = 20$ MHz operation) • 256 Hz, 512 Hz, 1.024 kHz, 2.048 kHz, 4.096 kHz, 8.192 kHz, 16.384 kHz, 32.768 kHz (Subsystem clock: $f_{SUB} = 32.768$ kHz operation)			
8/10-bit resolution A/D converter	8 channels	8 channels	8 channels	9 channels
Serial interface	[30-pin, 32-pin products] • CSI: 1 channel/UART (UART supporting LIN-bus): 1 channel/simplified I <sup>2</sup> C: 1 channel • CSI: 1 channel/UART: 1 channel/simplified I <sup>2</sup> C: 1 channel • CSI: 1 channel/UART: 1 channel/simplified I <sup>2</sup> C: 1 channel [36-pin, 40-pin products] • CSI: 1 channel/UART (UART supporting LIN-bus): 1 channel/simplified I <sup>2</sup> C: 1 channel • CSI: 1 channel/UART: 1 channel/simplified I <sup>2</sup> C: 1 channel • CSI: 2 channels/UART: 1 channel/simplified I <sup>2</sup> C: 2 channels			
I <sup>2</sup> C bus	1 channel	1 channel	1 channel	1 channel
Data transfer controller (DTC)	28 sources			29 sources
Event link controller (ELC)	Event input: 19 Event trigger output: 7			Event input: 20 Event trigger output: 7
Vectored interrupt sources	Internal	24	24	24
	External	6	6	7
Key interrupt	—	—	—	4
Reset	<ul style="list-style-type: none"> <li>Reset by <math>\overline{RESET}</math> pin</li> <li>Internal reset by watchdog timer</li> <li>Internal reset by power-on-reset</li> <li>Internal reset by voltage detector</li> <li>Internal reset by illegal instruction execution <sup>Note</sup></li> <li>Internal reset by RAM parity error</li> <li>Internal reset by illegal-memory access</li> </ul>			
Power-on-reset circuit	<ul style="list-style-type: none"> <li>Power-on-reset: 1.51 ±0.04 V (<math>T_A = -40</math> to +85°C) 1.51 ±0.06 V (<math>T_A = -40</math> to +105°C)</li> <li>Power-down-reset: 1.50 ±0.04 V (<math>T_A = -40</math> to +85°C) 1.50 ±0.06 V (<math>T_A = -40</math> to +105°C)</li> </ul>			
Voltage detector	1.63 V to 4.06 V (14 stages)			
On-chip debug function	Provided			
Power supply voltage	$V_{DD} = 1.6$ to 5.5 V ( $T_A = -40$ to +85°C) $V_{DD} = 2.4$ to 5.5 V ( $T_A = -40$ to +105°C)			
Operating ambient temperature	$T_A = -40$ to +85°C (A: Consumer applications, D: Industrial applications), $T_A = -40$ to +105°C (G: Industrial applications)			

**Note** The illegal instruction is generated when instruction code FFH is executed.

Reset by the illegal instruction execution not is issued by emulation with the in-circuit emulator or on-chip debug emulator.

[30-pin, 32-pin, 36-pin, 40-pin products (code flash memory 96 KB to 256 KB)]

**Caution** This outline describes the functions at the time when Peripheral I/O redirection register 0, 1 (PIOR0, 1) are set to 00H.

(1/2)

Item		30-pin	32-pin	36-pin	40-pin
		R5F104Ax (x = F, G)	R5F104Bx (x = F, G)	R5F104Cx (x = F, G)	R5F104Ex (x = F to H)
Code flash memory (KB)		96 to 128	96 to 128	96 to 128	96 to 192
Data flash memory (KB)		8	8	8	8
RAM (KB)		12 to 16 <i>Note</i>	12 to 16 <i>Note</i>	12 to 16 <i>Note</i>	12 to 20 <i>Note</i>
Address space		1 MB			
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (high-speed main) mode: 1 to 20 MHz ( $V_{DD} = 2.7$ to $5.5$ V), HS (high-speed main) mode: 1 to 16 MHz ( $V_{DD} = 2.4$ to $5.5$ V), LS (low-speed main) mode: 1 to 8 MHz ( $V_{DD} = 1.8$ to $5.5$ V), LV (low-voltage main) mode: 1 to 4 MHz ( $V_{DD} = 1.6$ to $5.5$ V)			
	High-speed on-chip oscillator clock ( $f_{IH}$ )	HS (high-speed main) mode: 1 to 32 MHz ( $V_{DD} = 2.7$ to $5.5$ V), HS (high-speed main) mode: 1 to 16 MHz ( $V_{DD} = 2.4$ to $5.5$ V), LS (low-speed main) mode: 1 to 8 MHz ( $V_{DD} = 1.8$ to $5.5$ V), LV (low-voltage main) mode: 1 to 4 MHz ( $V_{DD} = 1.6$ to $5.5$ V)			
Subsystem clock		—			XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz
Low-speed on-chip oscillator clock		15 kHz (TYP.): $V_{DD} = 1.6$ to $5.5$ V			
General-purpose register		8 bits $\times$ 32 registers (8 bits $\times$ 8 registers $\times$ 4 banks)			
Minimum instruction execution time		0.03125 $\mu$ s (High-speed on-chip oscillator clock: $f_{IH} = 32$ MHz operation)			
		0.05 $\mu$ s (High-speed system clock: $f_{MX} = 20$ MHz operation)			
		—			30.5 $\mu$ s (Subsystem clock: $f_{SUB} = 32.768$ kHz operation)
Instruction set		<ul style="list-style-type: none"> <li>• Data transfer (8/16 bits)</li> <li>• Adder and subtractor/logical operation (8/16 bits)</li> <li>• Multiplication (8 bits <math>\times</math> 8 bits, 16 bits <math>\times</math> 16 bits), Division (16 bits <math>\div</math> 16 bits, 32 bits <math>\div</math> 32 bits)</li> <li>• Multiplication and Accumulation (16 bits <math>\times</math> 16 bits + 32 bits)</li> <li>• Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li> </ul>			
I/O port	Total	26	28	32	36
	CMOS I/O	21	22	26	28
	CMOS input	3	3	3	5
	CMOS output	—	—	—	—
	N-ch open-drain I/O (6 V tolerance)	2	3	3	3
Timer	16-bit timer	8 channels (TAU: 4 channels, Timer RJ: 1 channel, Timer RD: 2 channels, Timer RG: 1 channel)			
	Watchdog timer	1 channel			
	Real-time clock (RTC)	1 channel			
	12-bit interval timer	1 channel			
	Timer output	Timer outputs: 13 channels PWM outputs: 9 channels			
	RTC output	—			1 • 1 Hz (subsystem clock: $f_{SUB} = 32.768$ kHz)

(Note is listed on the next page.)

**Note** The flash library uses RAM in self-programming and rewriting of the data flash memory.  
The target products and start address of the RAM areas used by the flash library are shown below.  
R5F104xJ (x = F, G, J, L, M, P): Start address F9F00H  
For the RAM areas used by the flash library, see **Self RAM list of Flash Self-Programming Library for RL78 Family (R20UT2944)**.

(2/2)

Item	30-pin	32-pin	36-pin	40-pin
	R5F104Ax (x = F, G)	R5F104Bx (x = F, G)	R5F104Cx (x = F, G)	R5F104Ex (x = F to H)
Clock output/buzzer output	2	2	2	2
	[30-pin, 32-pin, 36-pin products] • 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: $f_{MAIN} = 20$ MHz operation) [40-pin products] • 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: $f_{MAIN} = 20$ MHz operation) • 256 Hz, 512 Hz, 1.024 kHz, 2.048 kHz, 4.096 kHz, 8.192 kHz, 16.384 kHz, 32.768 kHz (Subsystem clock: $f_{SUB} = 32.768$ kHz operation)			
8/10-bit resolution A/D converter	8 channels	8 channels	8 channels	9 channels
D/A converter	1 channel	2 channels		
Comparator	2 channels			
Serial interface	[30-pin, 32-pin products] • CSI: 1 channel/UART (UART supporting LIN-bus): 1 channel/simplified I <sup>2</sup> C: 1 channel • CSI: 1 channel/UART: 1 channel/simplified I <sup>2</sup> C: 1 channel • CSI: 1 channel/UART: 1 channel/simplified I <sup>2</sup> C: 1 channel [36-pin, 40-pin products] • CSI: 1 channel/UART (UART supporting LIN-bus): 1 channel/simplified I <sup>2</sup> C: 1 channel • CSI: 1 channel/UART: 1 channel/simplified I <sup>2</sup> C: 1 channel • CSI: 2 channels/UART: 1 channel/simplified I <sup>2</sup> C: 2 channels			
	I <sup>2</sup> C bus	1 channel	1 channel	1 channel
Data transfer controller (DTC)	30 sources			31 sources
Event link controller (ELC)	Event input: 21 Event trigger output: 8	Event input: 21, Event trigger output: 9		Event input: 22 Event trigger output: 9
Vectored interrupt sources	Internal	24	24	24
	External	6	6	7
Key interrupt	—	—	—	4
Reset	<ul style="list-style-type: none"> <li>Reset by <math>\overline{RESET}</math> pin</li> <li>Internal reset by watchdog timer</li> <li>Internal reset by power-on-reset</li> <li>Internal reset by voltage detector</li> <li>Internal reset by illegal instruction execution <sup>Note</sup></li> <li>Internal reset by RAM parity error</li> <li>Internal reset by illegal-memory access</li> </ul>			
Power-on-reset circuit	<ul style="list-style-type: none"> <li>Power-on-reset: 1.51 ±0.04 V (<math>T_A = -40</math> to +85°C) 1.51 ±0.06 V (<math>T_A = -40</math> to +105°C)</li> <li>Power-down-reset: 1.50 ±0.04 V (<math>T_A = -40</math> to +85°C) 1.50 ±0.06 V (<math>T_A = -40</math> to +105°C)</li> </ul>			
Voltage detector	1.63 V to 4.06 V (14 stages)			
On-chip debug function	Provided			
Power supply voltage	$V_{DD} = 1.6$ to 5.5 V ( $T_A = -40$ to +85°C) $V_{DD} = 2.4$ to 5.5 V ( $T_A = -40$ to +105°C)			
Operating ambient temperature	$T_A = -40$ to +85°C (A: Consumer applications, D: Industrial applications), $T_A = -40$ to +105°C (G: Industrial applications)			

**Note** The illegal instruction is generated when instruction code FFH is executed.  
Reset by the illegal instruction execution not is issued by emulation with the in-circuit emulator or on-chip debug emulator.

[44-pin, 48-pin, 52-pin, 64-pin products (code flash memory 16 KB to 64 KB)]

**Caution** This outline describes the functions at the time when Peripheral I/O redirection register 0, 1 (PIOR0, 1) are set to 00H.

(1/2)

Item		44-pin	48-pin	52-pin	64-pin
		R5F104Fx (x = A, C to E)	R5F104Gx (x = A, C to E)	R5F104Jx (x = C to E)	R5F104Lx (x = C to E)
Code flash memory (KB)		16 to 64	16 to 64	32 to 64	32 to 64
Data flash memory (KB)		4	4	4	4
RAM (KB)		2.5 to 5.5 Note	2.5 to 5.5 Note	4 to 5.5 Note	4 to 5.5 Note
Address space		1 MB			
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (high-speed main) mode: 1 to 20 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)			
	High-speed on-chip oscillator clock (f <sub>IH</sub> )	HS (high-speed main) mode: 1 to 32 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)			
Subsystem clock		XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz			
Low-speed on-chip oscillator clock		15 kHz (TYP.): V <sub>DD</sub> = 1.6 to 5.5 V			
General-purpose register		8 bits × 32 registers (8 bits × 8 registers × 4 banks)			
Minimum instruction execution time		0.03125 μs (High-speed on-chip oscillator clock: f <sub>IH</sub> = 32 MHz operation)			
		0.05 μs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)			
		30.5 μs (Subsystem clock: f <sub>SUB</sub> = 32.768 kHz operation)			
Instruction set		<ul style="list-style-type: none"> <li>• Data transfer (8/16 bits)</li> <li>• Adder and subtractor/logical operation (8/16 bits)</li> <li>• Multiplication (8 bits × 8 bits, 16 bits × 16 bits), Division (16 bits ÷ 16 bits, 32 bits ÷ 32 bits)</li> <li>• Multiplication and Accumulation (16 bits × 16 bits + 32 bits)</li> <li>• Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li> </ul>			
I/O port	Total	40	44	48	58
	CMOS I/O	31	34	38	48
	CMOS input	5	5	5	5
	CMOS output	—	1	1	1
	N-ch open-drain I/O (6 V tolerance)	4	4	4	4
Timer	16-bit timer	8 channels (TAU: 4 channels, Timer RJ: 1 channel, Timer RD: 2 channels, Timer RG: 1 channel)			
	Watchdog timer	1 channel			
	Real-time clock (RTC)	1 channel			
	12-bit interval timer	1 channel			
	Timer output	Timer outputs: 13 channels PWM outputs: 9 channels			
	RTC output	1 • 1 Hz (subsystem clock: f <sub>SUB</sub> = 32.768 kHz)			

(Note is listed on the next page.)

**Note** The flash library uses RAM in self-programming and rewriting of the data flash memory.  
The target products and start address of the RAM areas used by the flash library are shown below.  
R5F104xD (x = A to C, E to G, J, L): Start address FE900H  
R5F104xE (x = A to C, E to G, J, L): Start address FE900H  
For the RAM areas used by the flash library, see **Self RAM list of Flash Self-Programming Library for RL78 Family (R20UT2944)**.



(2/2)

Item	44-pin	48-pin	52-pin	64-pin
	R5F104Fx (x = A, C to E)	R5F104Gx (x = A, C to E)	R5F104Jx (x = C to E)	R5F104Lx (x = C to E)
Clock output/buzzer output	2	2	2	2
	<ul style="list-style-type: none"> <li>2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: f<sub>MAIN</sub> = 20 MHz operation)</li> <li>256 Hz, 512 Hz, 1.024 kHz, 2.048 kHz, 4.096 kHz, 8.192 kHz, 16.384 kHz, 32.768 kHz (Subsystem clock: f<sub>SUB</sub> = 32.768 kHz operation)</li> </ul>			
8/10-bit resolution A/D converter	10 channels	10 channels	12 channels	12 channels
Serial interface	[44-pin products] <ul style="list-style-type: none"> <li>CSI: 1 channel/UART (UART supporting LIN-bus): 1 channel/simplified I<sup>2</sup>C: 1 channel</li> <li>CSI: 1 channel/UART: 1 channel/simplified I<sup>2</sup>C: 1 channel</li> <li>CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> </ul> [48-pin, 52-pin products] <ul style="list-style-type: none"> <li>CSI: 2 channels/UART (UART supporting LIN-bus): 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>CSI: 1 channel/UART: 1 channel/simplified I<sup>2</sup>C: 1 channel</li> <li>CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> </ul> [64-pin products] <ul style="list-style-type: none"> <li>CSI: 2 channels/UART (UART supporting LIN-bus): 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> </ul>			
	I <sup>2</sup> C bus	1 channel	1 channel	1 channel
Data transfer controller (DTC)	29 sources	30 sources		31 sources
Event link controller (ELC)	Event input: 20 Event trigger output: 7			
Vectored interrupt sources	Internal	24	24	24
	External	7	10	13
Key interrupt	4	6	8	8
Reset	<ul style="list-style-type: none"> <li>Reset by RESET pin</li> <li>Internal reset by watchdog timer</li> <li>Internal reset by power-on-reset</li> <li>Internal reset by voltage detector</li> <li>Internal reset by illegal instruction execution <sup>Note</sup></li> <li>Internal reset by RAM parity error</li> <li>Internal reset by illegal-memory access</li> </ul>			
Power-on-reset circuit	<ul style="list-style-type: none"> <li>Power-on-reset: 1.51 ±0.04 V (T<sub>A</sub> = -40 to +85°C) 1.51 ±0.06 V (T<sub>A</sub> = -40 to +105°C)</li> <li>Power-down-reset: 1.50 ±0.04 V (T<sub>A</sub> = -40 to +85°C) 1.50 ±0.06 V (T<sub>A</sub> = -40 to +105°C)</li> </ul>			
Voltage detector	1.63 V to 4.06 V (14 stages)			
On-chip debug function	Provided			
Power supply voltage	V <sub>DD</sub> = 1.6 to 5.5 V (T <sub>A</sub> = -40 to +85°C) V <sub>DD</sub> = 2.4 to 5.5 V (T <sub>A</sub> = -40 to +105°C)			
Operating ambient temperature	T <sub>A</sub> = -40 to +85°C (A: Consumer applications, D: Industrial applications), T <sub>A</sub> = -40 to +105°C (G: Industrial applications)			

**Note** The illegal instruction is generated when instruction code FFH is executed.  
 Reset by the illegal instruction execution is not issued by emulation with the in-circuit emulator or on-chip debug emulator.

[44-pin, 48-pin, 52-pin, 64-pin products (code flash memory 96 KB to 256 KB)]

**Caution** This outline describes the functions at the time when Peripheral I/O redirection register 0, 1 (PIOR0, 1) are set to 00H.

(1/2)

Item		44-pin	48-pin	52-pin	64-pin
		R5F104Fx (x = F to H, J)	R5F104Gx (x = F to H, J)	R5F104Jx (x = F to H, J)	R5F104Lx (x = F to H, J)
Code flash memory (KB)		96 to 256	96 to 256	96 to 256	96 to 256
Data flash memory (KB)		8	8	8	8
RAM (KB)		12 to 24 Note	12 to 24 Note	12 to 24 Note	12 to 24 Note
Address space		1 MB			
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (high-speed main) mode: 1 to 20 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)			
	High-speed on-chip oscillator clock (f <sub>IH</sub> )	HS (high-speed main) mode: 1 to 32 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)			
Subsystem clock		XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz			
Low-speed on-chip oscillator clock		15 kHz (TYP.): V <sub>DD</sub> = 1.6 to 5.5 V			
General-purpose register		8 bits × 32 registers (8 bits × 8 registers × 4 banks)			
Minimum instruction execution time		0.03125 μs (High-speed on-chip oscillator clock: f <sub>IH</sub> = 32 MHz operation)			
		0.05 μs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)			
		30.5 μs (Subsystem clock: f <sub>SUB</sub> = 32.768 kHz operation)			
Instruction set		<ul style="list-style-type: none"> <li>• Data transfer (8/16 bits)</li> <li>• Adder and subtractor/logical operation (8/16 bits)</li> <li>• Multiplication (8 bits × 8 bits, 16 bits × 16 bits), Division (16 bits ÷ 16 bits, 32 bits ÷ 32 bits)</li> <li>• Multiplication and Accumulation (16 bits × 16 bits + 32 bits)</li> <li>• Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li> </ul>			
I/O port	Total	40	44	48	58
	CMOS I/O	31	34	38	48
	CMOS input	5	5	5	5
	CMOS output	—	1	1	1
	N-ch open-drain I/O (6 V tolerance)	4	4	4	4
Timer	16-bit timer	8 channels (TAU: 4 channels, Timer RJ: 1 channel, Timer RD: 2 channels, Timer RG: 1 channel)			
	Watchdog timer	1 channel			
	Real-time clock (RTC)	1 channel			
	12-bit interval timer	1 channel			
	Timer output	Timer outputs: 14 channels PWM outputs: 9 channels			
	RTC output	1 • 1 Hz (subsystem clock: f <sub>SUB</sub> = 32.768 kHz)			

(Note is listed on the next page.)

**Note** The flash library uses RAM in self-programming and rewriting of the data flash memory.  
The target products and start address of the RAM areas used by the flash library are shown below.  
R5F104xJ (x = F, G, J, L, M, P): Start address F9F00H  
For the RAM areas used by the flash library, see **Self RAM list of Flash Self-Programming Library for RL78 Family (R20UT2944)**.

(2/2)

Item	44-pin	48-pin	52-pin	64-pin	
	R5F104Fx (x = F to H, J)	R5F104Gx (x = F to H, J)	R5F104Jx (x = F to H, J)	R5F104Lx (x = F to H, J)	
Clock output/buzzer output	2	2	2	2	
	<ul style="list-style-type: none"> <li>• 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: f<sub>MAIN</sub> = 20 MHz operation)</li> <li>• 256 Hz, 512 Hz, 1.024 kHz, 2.048 kHz, 4.096 kHz, 8.192 kHz, 16.384 kHz, 32.768 kHz (Subsystem clock: f<sub>SUB</sub> = 32.768 kHz operation)</li> </ul>				
8/10-bit resolution A/D converter	10 channels	10 channels	12 channels	12 channels	
D/A converter	2 channels				
Comparator	2 channels				
Serial interface	[44-pin products] <ul style="list-style-type: none"> <li>• CSI: 1 channel/UART (UART supporting LIN-bus): 1 channel/simplified I<sup>2</sup>C: 1 channel</li> <li>• CSI: 1 channel/UART: 1 channel/simplified I<sup>2</sup>C: 1 channel</li> <li>• CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> </ul> [48-pin, 52-pin products] <ul style="list-style-type: none"> <li>• CSI: 2 channels/UART (UART supporting LIN-bus): 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>• CSI: 1 channel/UART: 1 channel/simplified I<sup>2</sup>C: 1 channel</li> <li>• CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> </ul> [64-pin products] <ul style="list-style-type: none"> <li>• CSI: 2 channels/UART (UART supporting LIN-bus): 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>• CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>• CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> </ul>				
	I <sup>2</sup> C bus	1 channel	1 channel	1 channel	1 channel
Data transfer controller (DTC)	31 sources	32 sources		33 sources	
Event link controller (ELC)	Event input: 22 Event trigger output: 9				
Vectored interrupt sources	Internal	24	24	24	24
	External	7	10	12	13
Key interrupt	4	6	8	8	
Reset	<ul style="list-style-type: none"> <li>• Reset by <math>\overline{\text{RESET}}</math> pin</li> <li>• Internal reset by watchdog timer</li> <li>• Internal reset by power-on-reset</li> <li>• Internal reset by voltage detector</li> <li>• Internal reset by illegal instruction execution <sup>Note</sup></li> <li>• Internal reset by RAM parity error</li> <li>• Internal reset by illegal-memory access</li> </ul>				
Power-on-reset circuit	<ul style="list-style-type: none"> <li>• Power-on-reset: 1.51 ±0.04 V (T<sub>A</sub> = -40 to +85°C) 1.51 ±0.06 V (T<sub>A</sub> = -40 to +105°C)</li> <li>• Power-down-reset: 1.50 ±0.04 V (T<sub>A</sub> = -40 to +85°C) 1.50 ±0.06 V (T<sub>A</sub> = -40 to +105°C)</li> </ul>				
Voltage detector	1.63 V to 4.06 V (14 stages)				
On-chip debug function	Provided				
Power supply voltage	V <sub>DD</sub> = 1.6 to 5.5 V (T <sub>A</sub> = -40 to +85°C) V <sub>DD</sub> = 2.4 to 5.5 V (T <sub>A</sub> = -40 to +105°C)				
Operating ambient temperature	T <sub>A</sub> = -40 to +85°C (A: Consumer applications, D: Industrial applications), T <sub>A</sub> = -40 to +105°C (G: Industrial applications)				

**Note** The illegal instruction is generated when instruction code FFH is executed.  
Reset by the illegal instruction execution is not issued by emulation with the in-circuit emulator or on-chip debug emulator.

[48-pin, 64-pin products (code flash memory 384 KB to 512 KB)]

**Caution** This outline describes the functions at the time when Peripheral I/O redirection register 0, 1 (PIOR0, 1) are set to 00H.

(1/2)

Item		48-pin	64-pin
		R5F104Gx (x = K, L)	R5F104Lx (x = K, L)
Code flash memory (KB)		384 to 512	384 to 512
Data flash memory (KB)		8	8
RAM (KB)		32 to 48 Note	32 to 48 Note
Address space		1 MB	
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (high-speed main) mode: 1 to 20 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)	
	High-speed on-chip oscillator clock (f <sub>IH</sub> )	HS (high-speed main) mode: 1 to 32 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)	
Subsystem clock		XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz	
Low-speed on-chip oscillator clock		15 kHz (TYP.): V <sub>DD</sub> = 1.6 to 5.5 V	
General-purpose register		8 bits × 32 registers (8 bits × 8 registers × 4 banks)	
Minimum instruction execution time		0.03125 μs (High-speed on-chip oscillator clock: f <sub>IH</sub> = 32 MHz operation)	
		0.05 μs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)	
		30.5 μs (Subsystem clock: f <sub>SUB</sub> = 32.768 kHz operation)	
Instruction set		<ul style="list-style-type: none"> <li>• Data transfer (8/16 bits)</li> <li>• Adder and subtractor/logical operation (8/16 bits)</li> <li>• Multiplication (8 bits × 8 bits, 16 bits × 16 bits), Division (16 bits ÷ 16 bits, 32 bits ÷ 32 bits)</li> <li>• Multiplication and Accumulation (16 bits × 16 bits + 32 bits)</li> <li>• Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li> </ul>	
I/O port	Total	44	58
	CMOS I/O	34	48
	CMOS input	5	5
	CMOS output	1	1
	N-ch open-drain I/O (6 V tolerance)	4	4
Timer	16-bit timer	8 channels (TAU: 4 channels, Timer RJ: 1 channel, Timer RD: 2 channels, Timer RG: 1 channel)	
	Watchdog timer	1 channel	
	Real-time clock (RTC)	1 channel	
	12-bit interval timer	1 channel	
	Timer output	Timer outputs: 14 channels PWM outputs: 9 channels	
	RTC output	1 • 1 Hz (subsystem clock: f <sub>SUB</sub> = 32.768 kHz)	

(Note is listed on the next page.)

**Note** The flash library uses RAM in self-programming and rewriting of the data flash memory.  
The target products and start address of the RAM areas used by the flash library are shown below.  
R5F104xL (x = G, L, M, P): Start address F3F00H  
For the RAM areas used by the flash library, see **Self RAM list of Flash Self-Programming Library for RL78 Family (R20UT2944)**.

(2/2)

Item	48-pin		64-pin	
	R5F104Gx (x = K, L)		R5F104Lx (x = K, L)	
Clock output/buzzer output	2		2	
	<ul style="list-style-type: none"> <li>• 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: <math>f_{MAIN} = 20</math> MHz operation)</li> <li>• 256 Hz, 512 Hz, 1.024 kHz, 2.048 kHz, 4.096 kHz, 8.192 kHz, 16.384 kHz, 32.768 kHz (Subsystem clock: <math>f_{SUB} = 32.768</math> kHz operation)</li> </ul>			
8/10-bit resolution A/D converter	10 channels		12 channels	
D/A converter	2 channels			
Comparator	2 channels			
Serial interface	[48-pin products]			
	<ul style="list-style-type: none"> <li>• CSI: 2 channels/UART (UART supporting LIN-bus): 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>• CSI: 1 channel/UART: 1 channel/simplified I<sup>2</sup>C: 1 channel</li> <li>• CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> </ul>			
Serial interface	[64-pin products]			
	<ul style="list-style-type: none"> <li>• CSI: 2 channels/UART (UART supporting LIN-bus): 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>• CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>• CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> </ul>			
	I <sup>2</sup> C bus	1 channel	1 channel	
Data transfer controller (DTC)	32 sources		33 sources	
Event link controller (ELC)	Event input: 22 Event trigger output: 9			
Vectored interrupt sources	Internal	24	24	
	External	10	13	
Key interrupt	6		8	
Reset	<ul style="list-style-type: none"> <li>• Reset by <math>\overline{RESET}</math> pin</li> <li>• Internal reset by watchdog timer</li> <li>• Internal reset by power-on-reset</li> <li>• Internal reset by voltage detector</li> <li>• Internal reset by illegal instruction execution <sup>Note</sup></li> <li>• Internal reset by RAM parity error</li> <li>• Internal reset by illegal-memory access</li> </ul>			
Power-on-reset circuit	<ul style="list-style-type: none"> <li>• Power-on-reset: 1.51 ±0.04 V (<math>T_A = -40</math> to +85°C) 1.51 ±0.06 V (<math>T_A = -40</math> to +105°C)</li> <li>• Power-down-reset: 1.50 ±0.04 V (<math>T_A = -40</math> to +85°C) 1.50 ±0.06 V (<math>T_A = -40</math> to +105°C)</li> </ul>			
Voltage detector	1.63 V to 4.06 V (14 stages)			
On-chip debug function	Provided			
Power supply voltage	V <sub>DD</sub> = 1.6 to 5.5 V ( $T_A = -40$ to +85°C) V <sub>DD</sub> = 2.4 to 5.5 V ( $T_A = -40$ to +105°C)			
Operating ambient temperature	T <sub>A</sub> = -40 to +85°C (A: Consumer applications, D: Industrial applications), T <sub>A</sub> = -40 to +105°C (G: Industrial applications)			

**Note** The illegal instruction is generated when instruction code FFH is executed.  
Reset by the illegal instruction execution is not issued by emulation with the in-circuit emulator or on-chip debug emulator.

[80-pin, 100-pin products (code flash memory 96 KB to 256 KB)]

**Caution** This outline describes the functions at the time when Peripheral I/O redirection register 0, 1 (PIOR0, 1) are set to 00H.

(1/2)

Item		80-pin	100-pin
		R5F104Mx (x = F to H, J)	R5F104Px (x = F to H, J)
Code flash memory (KB)		96 to 256	96 to 256
Data flash memory (KB)		8	8
RAM (KB)		12 to 24 Note	12 to 24 Note
Address space		1 MB	
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (high-speed main) mode: 1 to 20 MHz ( $V_{DD} = 2.7$ to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz ( $V_{DD} = 2.4$ to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz ( $V_{DD} = 1.8$ to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz ( $V_{DD} = 1.6$ to 5.5 V)	
	High-speed on-chip oscillator clock ( $f_{IH}$ )	HS (high-speed main) mode: 1 to 32 MHz ( $V_{DD} = 2.7$ to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz ( $V_{DD} = 2.4$ to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz ( $V_{DD} = 1.8$ to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz ( $V_{DD} = 1.6$ to 5.5 V)	
Subsystem clock		XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz	
Low-speed on-chip oscillator clock		15 kHz (TYP.): $V_{DD} = 1.6$ to 5.5 V	
General-purpose register		8 bits $\times$ 32 registers (8 bits $\times$ 8 registers $\times$ 4 banks)	
Minimum instruction execution time		0.03125 $\mu$ s (High-speed on-chip oscillator clock: $f_{IH} = 32$ MHz operation)	
		0.05 $\mu$ s (High-speed system clock: $f_{MX} = 20$ MHz operation)	
		30.5 $\mu$ s (Subsystem clock: $f_{SUB} = 32.768$ kHz operation)	
Instruction set		<ul style="list-style-type: none"> <li>• Data transfer (8/16 bits)</li> <li>• Adder and subtractor/logical operation (8/16 bits)</li> <li>• Multiplication (8 bits <math>\times</math> 8 bits, 16 bits <math>\times</math> 16 bits), Division (16 bits <math>\div</math> 16 bits, 32 bits <math>\div</math> 32 bits)</li> <li>• Multiplication and Accumulation (16 bits <math>\times</math> 16 bits + 32 bits)</li> <li>• Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li> </ul>	
I/O port	Total	74	92
	CMOS I/O	64	82
	CMOS input	5	5
	CMOS output	1	1
	N-ch open-drain I/O (6 V tolerance)	4	4
Timer	16-bit timer	12 channels (TAU: 8 channels, Timer RJ: 1 channel, Timer RD: 2 channels, Timer RG: 1 channel)	
	Watchdog timer	1 channel	
	Real-time clock (RTC)	1 channel	
	12-bit interval timer	1 channel	
	Timer output	Timer outputs: 18 channels PWM outputs: 12 channels	
	RTC output	1 • 1 Hz (subsystem clock: $f_{SUB} = 32.768$ kHz)	

**Note** In the case of the 24 KB, this is about 23 KB when the self-programming function and data flash function are used (For details, see CHAPTER 3 in the RL78/G14 User's Manual).



(2/2)

Item	80-pin		100-pin	
	R5F104Mx (x = F to H, J)		R5F104Px (x = F to H, J)	
Clock output/buzzer output	2		2	
	<ul style="list-style-type: none"> <li>• 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: f<sub>MAIN</sub> = 20 MHz operation)</li> <li>• 256 Hz, 512 Hz, 1.024 kHz, 2.048 kHz, 4.096 kHz, 8.192 kHz, 16.384 kHz, 32.768 kHz (Subsystem clock: f<sub>SUB</sub> = 32.768 kHz operation)</li> </ul>			
8/10-bit resolution A/D converter	17 channels		20 channels	
D/A converter	2 channels		2 channels	
Comparator	2 channels		2 channels	
Serial interface	[80-pin, 100-pin products]			
	<ul style="list-style-type: none"> <li>• CSI: 2 channels/UART (UART supporting LIN-bus): 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>• CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>• CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>• CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> </ul>			
I <sup>2</sup> C bus	2 channels		2 channels	
Data transfer controller (DTC)	39 sources		39 sources	
Event link controller (ELC)	Event input: 26 Event trigger output: 9			
Vectored interrupt sources	Internal	32		32
	External	13		13
Key interrupt	8		8	
Reset	<ul style="list-style-type: none"> <li>• Reset by <math>\overline{\text{RESET}}</math> pin</li> <li>• Internal reset by watchdog timer</li> <li>• Internal reset by power-on-reset</li> <li>• Internal reset by voltage detector</li> <li>• Internal reset by illegal instruction execution <sup>Note</sup></li> <li>• Internal reset by RAM parity error</li> <li>• Internal reset by illegal-memory access</li> </ul>			
Power-on-reset circuit	<ul style="list-style-type: none"> <li>• Power-on-reset: 1.51 ±0.04 V (T<sub>A</sub> = -40 to +85°C) 1.51 ±0.06 V (T<sub>A</sub> = -40 to +105°C)</li> <li>• Power-down-reset: 1.50 ±0.04 V (T<sub>A</sub> = -40 to +85°C) 1.50 ±0.06 V (T<sub>A</sub> = -40 to +105°C)</li> </ul>			
Voltage detector	1.63 V to 4.06 V (14 stages)			
On-chip debug function	Provided			
Power supply voltage	V <sub>DD</sub> = 1.6 to 5.5 V (T <sub>A</sub> = -40 to +85°C) V <sub>DD</sub> = 2.4 to 5.5 V (T <sub>A</sub> = -40 to +105°C)			
Operating ambient temperature	T <sub>A</sub> = -40 to +85°C (A: Consumer applications, D: Industrial applications), T <sub>A</sub> = -40 to +105°C (G: Industrial applications)			

**Note** The illegal instruction is generated when instruction code FFH is executed.  
Reset by the illegal instruction execution is not issued by emulation with the in-circuit emulator or on-chip debug emulator.

[80-pin, 100-pin products (code flash memory 384 KB to 512 KB)]

**Caution** This outline describes the functions at the time when Peripheral I/O redirection register 0, 1 (PIOR0, 1) are set to 00H.

(1/2)

Item		80-pin	100-pin
		R5F104Mx (x = K, L)	R5F104Px (x = K, L)
Code flash memory (KB)		384 to 512	384 to 512
Data flash memory (KB)		8	8
RAM (KB)		32 to 48 Note	32 to 48 Note
Address space		1 MB	
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (high-speed main) mode: 1 to 20 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)	
	High-speed on-chip oscillator clock (f <sub>IH</sub> )	HS (high-speed main) mode: 1 to 32 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (high-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)	
Subsystem clock		XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz	
Low-speed on-chip oscillator clock		15 kHz (TYP.): V <sub>DD</sub> = 1.6 to 5.5 V	
General-purpose register		8 bits × 32 registers (8 bits × 8 registers × 4 banks)	
Minimum instruction execution time		0.03125 μs (High-speed on-chip oscillator clock: f <sub>IH</sub> = 32 MHz operation)	
		0.05 μs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)	
		30.5 μs (Subsystem clock: f <sub>SUB</sub> = 32.768 kHz operation)	
Instruction set		<ul style="list-style-type: none"> <li>• Data transfer (8/16 bits)</li> <li>• Adder and subtractor/logical operation (8/16 bits)</li> <li>• Multiplication (8 bits × 8 bits, 16 bits × 16 bits), Division (16 bits ÷ 16 bits, 32 bits ÷ 32 bits)</li> <li>• Multiplication and Accumulation (16 bits × 16 bits + 32 bits)</li> <li>• Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li> </ul>	
I/O port	Total	74	92
	CMOS I/O	64	82
	CMOS input	5	5
	CMOS output	1	1
	N-ch open-drain I/O (6 V tolerance)	4	4
Timer	16-bit timer	12 channels (TAU: 8 channels, Timer RJ: 1 channel, Timer RD: 2 channels, Timer RG: 1 channel)	
	Watchdog timer	1 channel	
	Real-time clock (RTC)	1 channel	
	12-bit interval timer	1 channel	
	Timer output	Timer outputs: 18 channels PWM outputs: 12 channels	
	RTC output	1 • 1 Hz (subsystem clock: f <sub>SUB</sub> = 32.768 kHz)	

**Note** In the case of the 48 KB, this is about 47 KB when the self-programming function and data flash function are used (For details, see **CHAPTER 3** in the RL78/G14 User's Manual).

(2/2)

Item	80-pin		100-pin	
	R5F104Mx (x = K, L)		R5F104Px (x = K, L)	
Clock output/buzzer output	2		2	
	<ul style="list-style-type: none"> <li>• 2.44 kHz, 4.88 kHz, 9.76 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: f<sub>MAIN</sub> = 20 MHz operation)</li> <li>• 256 Hz, 512 Hz, 1.024 kHz, 2.048 kHz, 4.096 kHz, 8.192 kHz, 16.384 kHz, 32.768 kHz (Subsystem clock: f<sub>SUB</sub> = 32.768 kHz operation)</li> </ul>			
8/10-bit resolution A/D converter	17 channels		20 channels	
D/A converter	2 channels		2 channels	
Comparator	2 channels		2 channels	
Serial interface	[80-pin, 100-pin products]			
	<ul style="list-style-type: none"> <li>• CSI: 2 channels/UART (UART supporting LIN-bus): 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>• CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>• CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> <li>• CSI: 2 channels/UART: 1 channel/simplified I<sup>2</sup>C: 2 channels</li> </ul>			
I <sup>2</sup> C bus	2 channels		2 channels	
Data transfer controller (DTC)	39 sources		39 sources	
Event link controller (ELC)	Event input: 26 Event trigger output: 9			
Vectored interrupt sources	Internal	32		32
	External	13		13
Key interrupt	8		8	
Reset	<ul style="list-style-type: none"> <li>• Reset by <math>\overline{\text{RESET}}</math> pin</li> <li>• Internal reset by watchdog timer</li> <li>• Internal reset by power-on-reset</li> <li>• Internal reset by voltage detector</li> <li>• Internal reset by illegal instruction execution <sup>Note</sup></li> <li>• Internal reset by RAM parity error</li> <li>• Internal reset by illegal-memory access</li> </ul>			
Power-on-reset circuit	<ul style="list-style-type: none"> <li>• Power-on-reset: 1.51 ±0.04 V (T<sub>A</sub> = -40 to +85°C) 1.51 ±0.06 V (T<sub>A</sub> = -40 to +105°C)</li> <li>• Power-down-reset: 1.50 ±0.04 V (T<sub>A</sub> = -40 to +85°C) 1.50 ±0.06 V (T<sub>A</sub> = -40 to +105°C)</li> </ul>			
Voltage detector	1.63 V to 4.06 V (14 stages)			
On-chip debug function	Provided			
Power supply voltage	V <sub>DD</sub> = 1.6 to 5.5 V (T <sub>A</sub> = -40 to +85°C) V <sub>DD</sub> = 2.4 to 5.5 V (T <sub>A</sub> = -40 to +105°C)			
Operating ambient temperature	T <sub>A</sub> = -40 to +85°C (A: Consumer applications, D: Industrial applications), T <sub>A</sub> = -40 to +105°C (G: Industrial applications)			

**Note** The illegal instruction is generated when instruction code FFH is executed.  
Reset by the illegal instruction execution is not issued by emulation with the in-circuit emulator or on-chip debug emulator.

## 2. ELECTRICAL SPECIFICATIONS (TA = -40 to +85°C)

This chapter describes the following electrical specifications.

Target products A: Consumer applications TA = -40 to +85°C

R5F104xxAxx

D: Industrial applications TA = -40 to +85°C

R5F104xxDxx

G: Industrial applications when TA = -40 to +105°C products is used in the range of TA = -40 to +85°C

R5F104xxGxx

**Caution 1.** The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.

**Caution 2.** With products not provided with an EVDD0, EVDD1, EVSS0, or EVSS1 pin, replace EVDD0 and EVDD1 with VDD, or replace EVSS0 and EVSS1 with Vss.

**Caution 3.** The pins mounted depend on the product. Refer to 2.1 Port Functions to 2.2.1 Functions for each product in the RL78/G14 User's Manual.

## 2.1 Absolute Maximum Ratings

### Absolute Maximum Ratings

(1/2)

Parameter	Symbols	Conditions	Ratings	Unit
Supply voltage	V <sub>DD</sub>		-0.5 to +6.5	V
	EV <sub>DD0</sub> , EV <sub>DD1</sub>	EV <sub>DD0</sub> = EV <sub>DD1</sub>	-0.5 to +6.5	V
	EV <sub>SS0</sub> , EV <sub>SS1</sub>	EV <sub>SS0</sub> = EV <sub>SS1</sub>	-0.5 to +0.3	V
REGC pin input voltage	V <sub>IREGC</sub>	REGC	-0.3 to +2.8 and -0.3 to V <sub>DD</sub> +0.3 Note 1	V
Input voltage	V <sub>I1</sub>	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147	-0.3 to EV <sub>DD0</sub> +0.3 and -0.3 to V <sub>DD</sub> +0.3 Note 2	V
	V <sub>I2</sub>	P60 to P63 (N-ch open-drain)	-0.3 to +6.5	V
	V <sub>I3</sub>	P20 to P27, P121 to P124, P137, P150 to P156, EXCLK, EXCLKS, $\overline{\text{RESET}}$	-0.3 to V <sub>DD</sub> +0.3 Note 2	V
Output voltage	V <sub>O1</sub>	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147	-0.3 to EV <sub>DD0</sub> +0.3 and -0.3 to V <sub>DD</sub> +0.3 Note 2	V
	V <sub>O2</sub>	P20 to P27, P150 to P156	-0.3 to V <sub>DD</sub> +0.3 Note 2	V
Analog input voltage	V <sub>AI1</sub>	ANI16 to ANI20	-0.3 to EV <sub>DD0</sub> +0.3 and -0.3 to AV <sub>REF</sub> (+) +0.3 Notes 2, 3	V
	V <sub>AI2</sub>	ANI0 to ANI14	-0.3 to V <sub>DD</sub> +0.3 and -0.3 to AV <sub>REF</sub> (+) +0.3 Notes 2, 3	V

**Note 1.** Connect the REGC pin to V<sub>SS</sub> via a capacitor (0.47 to 1 μF). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.

**Note 2.** Must be 6.5 V or lower.

**Note 3.** Do not exceed AV<sub>REF</sub> (+) + 0.3 V in case of A/D conversion target pin.

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remark 1.** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

**Remark 2.** AV<sub>REF</sub> (+): + side reference voltage of the A/D converter.

**Remark 3.** V<sub>SS</sub>: Reference voltage

**Absolute Maximum Ratings****(2/2)**

Parameter	Symbols	Conditions		Ratings	Unit
Output current, high	IOH1	Per pin	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147	-40	mA
		Total of all pins -170 mA	P00 to P04, P40 to P47, P102, P120, P130, P140 to P145	-70	mA
			P05, P06, P10 to P17, P30, P31, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100, P101, P110, P111, P146, P147	-100	mA
	IOH2	Per pin	P20 to P27, P150 to P156	-0.5	mA
		Total of all pins		-2	mA
	Output current, low	IOL1	Per pin	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147	40
Total of all pins 170 mA			P00 to P04, P40 to P47, P102, P120, P130, P140 to P145	70	mA
			P05, P06, P10 to P17, P30, P31, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P100, P101, P110, P111, P146, P147	100	mA
IOL2		Per pin	P20 to P27, P150 to P156	1	mA
		Total of all pins		5	mA
Operating ambient temperature		TA	In normal operation mode		-40 to +85
	In flash memory programming mode				
Storage temperature	Tstg			-65 to +150	°C

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## 2.2 Oscillator Characteristics

### 2.2.1 X1, XT1 characteristics

(TA = -40 to +85°C, 1.6 V ≤ VDD ≤ 5.5 V, VSS = 0 V)

Resonator	Resonator	Conditions	MIN.	TYP.	MAX.	Unit
X1 clock oscillation frequency (fx) <sup>Note</sup>	Ceramic resonator/ crystal resonator	2.7 V ≤ VDD ≤ 5.5 V	1.0		20.0	MHz
		2.4 V ≤ VDD < 2.7 V	1.0		16.0	
		1.8 V ≤ VDD < 2.4 V	1.0		8.0	
		1.6 V ≤ VDD < 1.8 V	1.0		4.0	
XT1 clock oscillation frequency (fxT) <sup>Note</sup>	Crystal resonator		32	32.768	35	kHz

**Note** Indicates only permissible oscillator frequency ranges. Refer to **AC Characteristics** for instruction execution time. Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

**Caution** Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.

**Remark** When using the X1 oscillator and XT1 oscillator, refer to **5.4 System Clock Oscillator** in the RL78/G14 User's Manual.

### 2.2.2 On-chip oscillator characteristics

(TA = -40 to +85°C, 1.6 V ≤ VDD ≤ 5.5 V, VSS = 0 V)

Oscillators	Parameters	Conditions		MIN.	TYP.	MAX.	Unit
High-speed on-chip oscillator clock frequency Notes 1, 2	f <sub>IH</sub>			1		32	MHz
High-speed on-chip oscillator clock frequency accuracy		-20 to +85°C	1.8 V ≤ VDD ≤ 5.5 V	-1.0		+1.0	%
			1.6 V ≤ VDD < 1.8 V	-5.0		+5.0	%
		-40 to -20°C	1.8 V ≤ VDD < 5.5 V	-1.5		+1.5	%
			1.6 V ≤ VDD < 1.8 V	-5.5		+5.5	%
Low-speed on-chip oscillator clock frequency	f <sub>IL</sub>				15		kHz
Low-speed on-chip oscillator clock frequency accuracy				-15		+15	%

**Note 1.** High-speed on-chip oscillator frequency is selected with bits 0 to 4 of the option byte (000C2H) and bits 0 to 2 of the HOCODIV register.

**Note 2.** This only indicates the oscillator characteristics. Refer to **AC Characteristics** for instruction execution time.

## 2.3 DC Characteristics

### 2.3.1 Pin characteristics

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(1/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit		
Output current, high <sup>Note 1</sup>	IOH1	Per pin for P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147	1.6 V ≤ EVDD0 ≤ 5.5 V			-10.0 Note 2	mA	
		Total of P00 to P04, P40 to P47, P102, P120, P130, P140 to P145 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EVDD0 ≤ 5.5 V			-55.0	mA	
			2.7 V ≤ EVDD0 < 4.0 V			-10.0	mA	
			1.8 V ≤ EVDD0 < 2.7 V			-5.0	mA	
			1.6 V ≤ EVDD0 < 1.8 V			-2.5	mA	
		Total of P05, P06, P10 to P17, P30, P31, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100, P101, P110, P111, P146, P147 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EVDD0 ≤ 5.5 V			-80.0	mA	
			2.7 V ≤ EVDD0 < 4.0 V			-19.0	mA	
			1.8 V ≤ EVDD0 < 2.7 V			-10.0	mA	
			1.6 V ≤ EVDD0 < 1.8 V			-5.0	mA	
		Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )	1.6 V ≤ EVDD0 ≤ 5.5 V			-135.0 Note 4	mA	
		IOH2	Per pin for P20 to P27, P150 to P156	1.6 V ≤ VDD ≤ 5.5 V			-0.1 Note 2	mA
			Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )	1.6 V ≤ VDD ≤ 5.5 V			-1.5	mA

**Note 1.** Value of current at which the device operation is guaranteed even if the current flows from the EVDD0, EVDD1, VDD pins to an output pin.

**Note 2.** Do not exceed the total current value.

**Note 3.** Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (IOH × 0.7)/(n × 0.01)

<Example> Where n = 80% and IOH = -10.0 mA

$$\text{Total output current of pins} = (-10.0 \times 0.7)/(80 \times 0.01) \approx -8.7 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor.

A current higher than the absolute maximum rating must not flow into one pin.

**Note 4.** -100 mA for industrial applications (R5F104xxDxx, R5F104xxGxx).

**Caution** P00, P02 to P04, P10, P11, P13 to P15, P17, P30, P43 to P45, P50 to P55, P71, P74, P80 to P82, and P142 to P144 do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.



(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(2/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Output current, low <sup>Note 1</sup>	IOL1	Per pin for P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147			20.0 Note 2	mA	
					15.0 Note 2	mA	
			Total of P00 to P04, P40 to P47, P102, P120, P130, P140 to P145 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EVDD0 ≤ 5.5 V		70.0	mA
				2.7 V ≤ EVDD0 < 4.0 V		15.0	mA
		1.8 V ≤ EVDD0 < 2.7 V			9.0	mA	
		1.6 V ≤ EVDD0 < 1.8 V			4.5	mA	
		Total of P05, P06, P10 to P17, P30, P31, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P100, P101, P110, P111, P146, P147 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EVDD0 ≤ 5.5 V		80.0	mA	
			2.7 V ≤ EVDD0 < 4.0 V		35.0	mA	
			1.8 V ≤ EVDD0 < 2.7 V		20.0	mA	
			1.6 V ≤ EVDD0 < 1.8 V		10.0	mA	
	Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )			150.0	mA		
	IOL2	Per pin for P20 to P27, P150 to P156			0.4 Note 2	mA	
			1.6 V ≤ VDD ≤ 5.5 V		5.0	mA	
Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )							

**Note 1.** Value of current at which the device operation is guaranteed even if the current flows from an output pin to the EVSS0, EVSS1, and VSS pins.

**Note 2.** Do not exceed the total current value.

**Note 3.** Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (IOL × 0.7)/(n × 0.01)

<Example> Where n = 80% and IOL = 10.0 mA

$$\text{Total output current of pins} = (10.0 \times 0.7)/(80 \times 0.01) \approx 8.7 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor.

A current higher than the absolute maximum rating must not flow into one pin.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(3/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input voltage, high	V <sub>IH1</sub>	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147	Normal input buffer	0.8 EVDD0		EVDD0	V
	V <sub>IH2</sub>	P01, P03, P04, P10, P14 to P17, P30, P43, P44, P50, P53 to P55, P80, P81, P142, P143	TTL input buffer 4.0 V ≤ EVDD0 ≤ 5.5 V	2.2		EVDD0	V
			TTL input buffer 3.3 V ≤ EVDD0 < 4.0 V	2.0		EVDD0	V
			TTL input buffer 1.6 V ≤ EVDD0 < 3.3 V	1.5		EVDD0	V
	V <sub>IH3</sub>	P20 to P27, P150 to P156		0.7 VDD		VDD	V
	V <sub>IH4</sub>	P60 to P63		0.7 EVDD0		6.0	V
V <sub>IH5</sub>	P121 to P124, P137, EXCLK, EXCLKS, RESET		0.8 VDD		VDD	V	
Input voltage, low	V <sub>IL1</sub>	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147	Normal input buffer	0		0.2 EVDD0	V
	V <sub>IL2</sub>	P01, P03, P04, P10, P14 to P17, P30, P43, P44, P50, P53 to P55, P80, P81, P142, P143	TTL input buffer 4.0 V ≤ EVDD0 ≤ 5.5 V	0		0.8	V
			TTL input buffer 3.3 V ≤ EVDD0 < 4.0 V	0		0.5	V
			TTL input buffer 1.6 V ≤ EVDD0 < 3.3 V	0		0.32	V
	V <sub>IL3</sub>	P20 to P27, P150 to P156		0		0.3 VDD	V
	V <sub>IL4</sub>	P60 to P63		0		0.3 EVDD0	V
V <sub>IL5</sub>	P121 to P124, P137, EXCLK, EXCLKS, RESET		0		0.2 VDD	V	

**Caution** The maximum value of V<sub>IH</sub> of pins P00, P02 to P04, P10, P11, P13 to P15, P17, P30, P43 to P45, P50 to P55, P71, P74, P80 to P82, and P142 to P144 is EVDD0, even in the N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(4/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output voltage, high	VOH1	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147	4.0 V ≤ EVDD0 ≤ 5.5 V, IOH1 = -10.0 mA	EVDD0 - 1.5		V
			4.0 V ≤ EVDD0 ≤ 5.5 V, IOH1 = -3.0 mA	EVDD0 - 0.7		V
			1.8 V ≤ EVDD0 ≤ 5.5 V, IOH1 = -1.5 mA	EVDD0 - 0.5		V
			1.6 V ≤ EVDD0 < 1.8 V, IOH1 = -1.0 mA	EVDD0 - 0.5		V
	VOH2	P20 to P27, P150 to P156	1.6 V ≤ VDD ≤ 5.5 V, IOH2 = -100 μA	VDD - 0.5		V
Output voltage, low	VOL1	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147	4.0 V ≤ EVDD0 ≤ 5.5 V, IOL1 = 20.0 mA		1.3	V
			4.0 V ≤ EVDD0 ≤ 5.5 V, IOL1 = 8.5 mA		0.7	V
			2.7 V ≤ EVDD0 ≤ 5.5 V, IOL1 = 3.0 mA		0.6	V
			2.7 V ≤ EVDD0 ≤ 5.5 V, IOL1 = 1.5 mA		0.4	V
			1.8 V ≤ EVDD0 ≤ 5.5 V, IOL1 = 0.6 mA		0.4	V
			1.6 V ≤ EVDD0 ≤ 5.5 V, IOL1 = 0.3 mA		0.4	V
	VOL2	P20 to P27, P150 to P156	1.6 V ≤ VDD ≤ 5.5 V, IOL2 = 400 μA		0.4	V
	VOL3	P60 to P63	4.0 V ≤ EVDD0 ≤ 5.5 V, IOL3 = 15.0 mA		2.0	V
			4.0 V ≤ EVDD0 ≤ 5.5 V, IOL3 = 5.0 mA		0.4	V
			2.7 V ≤ EVDD0 ≤ 5.5 V, IOL3 = 3.0 mA		0.4	V
			1.8 V ≤ EVDD0 ≤ 5.5 V, IOL3 = 2.0 mA		0.4	V
			1.6 V ≤ EVDD0 ≤ 5.5 V, IOL3 = 1.0 mA		0.4	V

**Caution** P00, P02 to P04, P10, P11, P13 to P15, P17, P30, P43 to P45, P50 to P55, P71, P74, P80 to P82, P142 to P144 do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(5/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit		
Input leakage current, high	ILIH1	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147	Vi = EVDD0			1	μA	
	ILIH2	P20 to P27, P137, P150 to P156, RESET	Vi = VDD			1	μA	
	ILIH3	P121 to P124 (X1, X2, EXCLK, XT1, XT2, EXCLKS)	Vi = VDD		In input port or external clock input		1	μA
					In resonator connection		10	μA
Input leakage current, low	ILIL1	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147	Vi = EVSS0			-1	μA	
	ILIL2	P20 to P27, P137, P150 to P156, RESET	Vi = VSS			-1	μA	
	ILIL3	P121 to P124 (X1, X2, EXCLK, XT1, XT2, EXCLKS)	Vi = VSS		In input port or external clock input		-1	μA
					In resonator connection		-10	μA
On-chip pull-up resistance	Ru	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147	Vi = EVSS0, In input port		10	20	100	kΩ

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## 2.3.2 Supply current characteristics

### (1) Flash ROM: 16 to 64 KB of 30- to 64-pin products

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = 0 V)

(1/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit		
Supply current Note 1	IDD1	Operating mode	HS (high-speed main) mode Note 5	fHOCO = 64 MHz, fIH = 32 MHz Note 3	Basic operation	VDD = 5.0 V		2.4		mA	
						VDD = 3.0 V		2.4			
					fHOCO = 32 MHz, fIH = 32 MHz Note 3	Basic operation	VDD = 5.0 V		2.1		
					VDD = 3.0 V			2.1			
				HS (high-speed main) mode Note 5	fHOCO = 64 MHz, fIH = 32 MHz Note 3	Normal operation	VDD = 5.0 V		5.1		8.7
							VDD = 3.0 V		5.1		8.7
					fHOCO = 32 MHz, fIH = 32 MHz Note 3	Normal operation	VDD = 5.0 V		4.8	8.1	
					VDD = 3.0 V			4.8	8.1		
					fHOCO = 48 MHz, fIH = 24 MHz Note 3	Normal operation	VDD = 5.0 V		4.0	6.9	
					VDD = 3.0 V			4.0	6.9		
				fHOCO = 24 MHz, fIH = 24 MHz Note 3	Normal operation	VDD = 5.0 V		3.8	6.3		
				VDD = 3.0 V			3.8	6.3			
			fHOCO = 16 MHz, fIH = 16 MHz Note 3	Normal operation	VDD = 5.0 V		2.8	4.6			
			VDD = 3.0 V			2.8	4.6				
		LS (low-speed main) mode Note 5	fHOCO = 8 MHz, fIH = 8 MHz Note 3	Normal operation	VDD = 3.0 V		1.3	2.0			
					VDD = 2.0 V		1.3	2.0			
		LV (low-voltage main) mode Note 5	fHOCO = 4 MHz, fIH = 4 MHz Note 3	Normal operation	VDD = 3.0 V		1.3	1.8			
					VDD = 2.0 V		1.3	1.8			
		HS (high-speed main) mode Note 5	fMX = 20 MHz Note 2, VDD = 5.0 V	Normal operation	Square wave input		3.3	5.3			
					Resonator connection		3.4	5.5			
				Normal operation	Square wave input		3.3	5.3			
					Resonator connection		3.4	5.5			
			fMX = 10 MHz Note 2, VDD = 5.0 V	Normal operation	Square wave input		2.0	3.1			
					Resonator connection		2.1	3.2			
Normal operation	Square wave input				2.0	3.1					
	Resonator connection				2.1	3.2					
LS (low-speed main) mode Note 5	fMX = 8 MHz Note 2, VDD = 3.0 V	Normal operation	Square wave input		1.2	1.9					
			Resonator connection		1.2	2.0					
	fMX = 8 MHz Note 2, VDD = 2.0 V	Normal operation	Square wave input		1.2	1.9					
			Resonator connection		1.2	2.0					
Subsystem clock operation	fSUB = 32.768 kHz Note 4 TA = -40°C	Normal operation	Square wave input		4.7	6.1					
			Resonator connection		4.7	6.1					
	fSUB = 32.768 kHz Note 4 TA = +25°C	Normal operation	Square wave input		4.7	6.1					
			Resonator connection		4.7	6.1					
	fSUB = 32.768 kHz Note 4 TA = +50°C	Normal operation	Square wave input		4.8	6.7					
			Resonator connection		4.8	6.7					
fSUB = 32.768 kHz Note 4 TA = +70°C	Normal operation	Square wave input		4.8	7.5						
		Resonator connection		4.8	7.5						
fSUB = 32.768 kHz Note 4 TA = +85°C	Normal operation	Square wave input		5.4	8.9						
		Resonator connection		5.4	8.9						

(Notes and Remarks are listed on the next page.)

- Note 1.** Total current flowing into V<sub>DD</sub> and EV<sub>DD0</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub> or V<sub>SS</sub>, EV<sub>SS0</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 3.** When high-speed system clock and subsystem clock are stopped.
- Note 4.** When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation). However, not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
- Note 5.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
- |                             |   |
|-----------------------------|---|
| HS (high-speed main) mode:  | 2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 32 MHz |
|                             | 2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 16 MHz |
| LS (low-speed main) mode:   | 1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 8 MHz  |
| LV (low-voltage main) mode: | 1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 4 MHz  |
- Remark 1.** f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** f<sub>HOCO</sub>: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** f<sub>IH</sub>: High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

## (1) Flash ROM: 16 to 64 KB of 30- to 64-pin products

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = 0 V)

(2/2)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit	
Supply current Note 1	I <sub>DD2</sub> Note 2	HALT mode Note 7	HS (high-speed main) mode Note 7	fHOCO = 64 MHz, fIH = 32 MHz Note 4	VDD = 5.0 V	0.80	3.09	mA
					VDD = 3.0 V	0.80	3.09	
				fHOCO = 32 MHz, fIH = 32 MHz Note 4	VDD = 5.0 V	0.49	2.40	
					VDD = 3.0 V	0.49	2.40	
				fHOCO = 48 MHz, fIH = 24 MHz Note 4	VDD = 5.0 V	0.62	2.40	
					VDD = 3.0 V	0.62	2.40	
			fHOCO = 24 MHz, fIH = 24 MHz Note 4	VDD = 5.0 V	0.4	1.83		
				VDD = 3.0 V	0.4	1.83		
			fHOCO = 16 MHz, fIH = 16 MHz Note 4	VDD = 5.0 V	0.37	1.38		
				VDD = 3.0 V	0.37	1.38		
			LS (low-speed main) mode Note 7	fHOCO = 8 MHz, fIH = 8 MHz Note 4	VDD = 3.0 V	260	710	μA
					VDD = 2.0 V	260	710	
			LV (low-voltage main) mode Note 7	fHOCO = 4 MHz, fIH = 4 MHz Note 4	VDD = 3.0 V	420	700	μA
					VDD = 2.0 V	420	700	
			HS (high-speed main) mode Note 7	fMX = 20 MHz Note 3, VDD = 5.0 V	Square wave input	0.28	1.55	mA
					Resonator connection	0.40	1.74	
				fMX = 20 MHz Note 3, VDD = 3.0 V	Square wave input	0.28	1.55	
					Resonator connection	0.40	1.74	
				fMX = 10 MHz Note 3, VDD = 5.0 V	Square wave input	0.19	0.86	
					Resonator connection	0.25	0.93	
				fMX = 10 MHz Note 3, VDD = 3.0 V	Square wave input	0.19	0.86	
					Resonator connection	0.25	0.93	
			LS (low-speed main) mode Note 7	fMX = 8 MHz Note 3, VDD = 3.0 V	Square wave input	95	550	μA
					Resonator connection	140	590	
				fMX = 8 MHz Note 3, VDD = 2.0 V	Square wave input	95	550	
					Resonator connection	140	590	
			Subsystem clock operation	fsUB = 32.768 kHz Note 5, TA = -40°C	Square wave input	0.25	0.57	μA
Resonator connection	0.44	0.76						
fsUB = 32.768 kHz Note 5, TA = +25°C	Square wave input	0.30		0.57				
	Resonator connection	0.49		0.76				
fsUB = 32.768 kHz Note 5, TA = +50°C	Square wave input	0.36		1.17				
	Resonator connection	0.59		1.36				
fsUB = 32.768 kHz Note 5, TA = +70°C	Square wave input	0.49		1.97				
	Resonator connection	0.72		2.16				
fsUB = 32.768 kHz Note 5, TA = +85°C	Square wave input	0.97	3.37					
	Resonator connection	1.16	3.56					
I <sub>DD3</sub> Note 6	STOP mode Note 8	TA = -40°C		0.18	0.51	μA		
		TA = +25°C		0.24	0.51			
		TA = +50°C		0.29	1.10			
		TA = +70°C		0.41	1.90			
		TA = +85°C		0.90	3.30			

(Notes and Remarks are listed on the next page.)

- Note 1.** Total current flowing into VDD and EVDD0, including the input leakage current flowing when the level of the input pin is fixed to VDD, EVDD0 or VSS, EVSS0. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** During HALT instruction execution by flash memory.
- Note 3.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 4.** When high-speed system clock and subsystem clock are stopped.
- Note 5.** When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 6.** Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
- Note 7.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
- |                             |   |
|-----------------------------|---|
| HS (high-speed main) mode:  | $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ @1 MHz to 32 MHz |
|                             | $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ @1 MHz to 16 MHz |
| LS (low-speed main) mode:   | $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ @1 MHz to 8 MHz  |
| LV (low-voltage main) mode: | $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ @1 MHz to 4 MHz  |
- Note 8.** Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.
- Remark 1.** fMX: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** fHOCO: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** fIH: High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** fSUB: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is TA = 25°C



(2) Flash ROM: 96 to 256 KB of 30- to 100-pin products

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(1/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit		
Supply current Note 1	I <sub>DD1</sub>	Operating mode	HS (high-speed main) mode Note 5	f <sub>HOCO</sub> = 64 MHz, f <sub>IIH</sub> = 32 MHz Note 3	Basic operation	V <sub>DD</sub> = 5.0 V		2.6		mA	
						V <sub>DD</sub> = 3.0 V		2.6			
					f <sub>HOCO</sub> = 32 MHz, f <sub>IIH</sub> = 32 MHz Note 3	Basic operation	V <sub>DD</sub> = 5.0 V		2.3		
							V <sub>DD</sub> = 3.0 V		2.3		
			HS (high-speed main) mode Note 5	f <sub>HOCO</sub> = 64 MHz, f <sub>IIH</sub> = 32 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		5.4	10.2	mA	
						V <sub>DD</sub> = 3.0 V		5.4	10.2		
		f <sub>HOCO</sub> = 32 MHz, f <sub>IIH</sub> = 32 MHz Note 3		Normal operation	V <sub>DD</sub> = 5.0 V		5.0	9.6			
					V <sub>DD</sub> = 3.0 V		5.0	9.6			
		f <sub>HOCO</sub> = 48 MHz, f <sub>IIH</sub> = 24 MHz Note 3		Normal operation	V <sub>DD</sub> = 5.0 V		4.2	7.8			
					V <sub>DD</sub> = 3.0 V		4.2	7.8			
		f <sub>HOCO</sub> = 24 MHz, f <sub>IIH</sub> = 24 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		4.0	7.4				
					V <sub>DD</sub> = 3.0 V		4.0		7.4		
		f <sub>HOCO</sub> = 16 MHz, f <sub>IIH</sub> = 16 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		3.0	5.3				
					V <sub>DD</sub> = 3.0 V		3.0		5.3		
		LS (low-speed main) mode Note 5	f <sub>HOCO</sub> = 8 MHz, f <sub>IIH</sub> = 8 MHz Note 3	Normal operation	V <sub>DD</sub> = 3.0 V		1.4	2.3	mA		
					V <sub>DD</sub> = 2.0 V		1.4	2.3			
		LV (low-voltage main) mode Note 5	f <sub>HOCO</sub> = 4 MHz, f <sub>IIH</sub> = 4 MHz Note 3	Normal operation	V <sub>DD</sub> = 3.0 V		1.3	1.9	mA		
					V <sub>DD</sub> = 2.0 V		1.3	1.9			
		HS (high-speed main) mode Note 5	f <sub>MX</sub> = 20 MHz Note 2, V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		3.4	6.2	mA		
					Resonator connection		3.6	6.4			
			f <sub>MX</sub> = 20 MHz Note 2, V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		3.4	6.2			
					Resonator connection		3.6	6.4			
			f <sub>MX</sub> = 10 MHz Note 2, V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		2.1	3.6			
					Resonator connection		2.2	3.7			
f <sub>MX</sub> = 10 MHz Note 2, V <sub>DD</sub> = 3.0 V	Normal operation		Square wave input		2.1	3.6					
			Resonator connection		2.2	3.7					
LS (low-speed main) mode Note 5	f <sub>MX</sub> = 8 MHz Note 2, V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		1.2	2.2	mA				
			Resonator connection		1.2	2.3					
	f <sub>MX</sub> = 8 MHz Note 2, V <sub>DD</sub> = 2.0 V	Normal operation	Square wave input		1.2	2.2					
			Resonator connection		1.2	2.3					
Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz Note 4 TA = -40°C	Normal operation	Square wave input		4.9	7.1	μA				
			Resonator connection		4.9	7.1					
	f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +25°C	Normal operation	Square wave input		4.9	7.1					
			Resonator connection		4.9	7.1					
	f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +50°C	Normal operation	Square wave input		5.1	8.8					
			Resonator connection		5.1	8.8					
f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +70°C	Normal operation	Square wave input		5.5	10.5						
		Resonator connection		5.5	10.5						
f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +85°C	Normal operation	Square wave input		6.5	14.5						
		Resonator connection		6.5	14.5						

(Notes and Remarks are listed on the next page.)

- Note 1.** Total current flowing into V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, or V<sub>SS</sub>, EV<sub>SS0</sub>, and EV<sub>SS1</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, comparator, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 3.** When high-speed system clock and subsystem clock are stopped.
- Note 4.** When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation). However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 5.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
- |                             |   |
|-----------------------------|---|
| HS (high-speed main) mode:  | 2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 32 MHz |
|                             | 2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 16 MHz |
| LS (low-speed main) mode:   | 1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 8 MHz  |
| LV (low-voltage main) mode: | 1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 4 MHz  |
- Remark 1.** f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** f<sub>HOCO</sub>: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** f<sub>IH</sub>: High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

## (2) Flash ROM: 96 to 256 KB of 30- to 100-pin products

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(2/2)

Parameter	Symbol	Conditions			MIN.	TYP.	MAX.	Unit			
Supply current Note 1	I <sub>DD2</sub> Note 2	HALT mode	HS (high-speed main) mode Note 7	f <sub>HOCO</sub> = 64 MHz, f <sub>IH</sub> = 32 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.79	3.32	mA		
					V <sub>DD</sub> = 3.0 V		0.79	3.32			
				f <sub>HOCO</sub> = 32 MHz, f <sub>IH</sub> = 32 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.49	2.63			
					V <sub>DD</sub> = 3.0 V		0.49	2.63			
				f <sub>HOCO</sub> = 48 MHz, f <sub>IH</sub> = 24 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.62	2.57			
					V <sub>DD</sub> = 3.0 V		0.62	2.57			
			f <sub>HOCO</sub> = 24 MHz, f <sub>IH</sub> = 24 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.4	2.00				
				V <sub>DD</sub> = 3.0 V		0.4	2.00				
			f <sub>HOCO</sub> = 16 MHz, f <sub>IH</sub> = 16 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.38	1.49				
				V <sub>DD</sub> = 3.0 V		0.38	1.49				
					LS (low-speed main) mode Note 7	f <sub>HOCO</sub> = 8 MHz, f <sub>IH</sub> = 8 MHz Note 4	V <sub>DD</sub> = 3.0 V		250	800	μA
							V <sub>DD</sub> = 2.0 V		250	800	
				LV (low-voltage main) mode Note 7	f <sub>HOCO</sub> = 4 MHz, f <sub>IH</sub> = 4 MHz Note 4	V <sub>DD</sub> = 3.0 V		420	755	μA	
						V <sub>DD</sub> = 2.0 V		420	755		
				HS (high-speed main) mode Note 7	f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 5.0 V	Square wave input		0.30	1.63	mA	
						Resonator connection		0.40	1.85		
						Square wave input		0.30	1.63		
						Resonator connection		0.40	1.85		
					f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 3.0 V	Square wave input		0.20	0.89		
						Resonator connection		0.25	0.97		
						Square wave input		0.20	0.89		
						Resonator connection		0.25	0.97		
				LS (low-speed main) mode Note 7	f <sub>MX</sub> = 8 MHz Note 3, V <sub>DD</sub> = 3.0 V	Square wave input		110	580	μA	
						Resonator connection		140	630		
					f <sub>MX</sub> = 8 MHz Note 3, V <sub>DD</sub> = 2.0 V	Square wave input		110	580		
						Resonator connection		140	630		
				Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz Note 5, TA = -40°C	Square wave input		0.28	0.66	μA	
						Resonator connection		0.47	0.85		
		f <sub>SUB</sub> = 32.768 kHz Note 5, TA = +25°C	Square wave input			0.34	0.66				
			Resonator connection			0.53	0.85				
		f <sub>SUB</sub> = 32.768 kHz Note 5, TA = +50°C	Square wave input			0.37	2.35				
			Resonator connection			0.56	2.54				
		f <sub>SUB</sub> = 32.768 kHz Note 5, TA = +70°C	Square wave input			0.61	4.08				
			Resonator connection			0.80	4.27				
		f <sub>SUB</sub> = 32.768 kHz Note 5, TA = +85°C	Square wave input			1.55	8.09				
			Resonator connection			1.74	8.28				
	I <sub>DD3</sub> Note 6	STOP mode Note 8	TA = -40°C				0.19	0.57	μA		
			TA = +25°C				0.25	0.57			
			TA = +50°C				0.33	2.26			
			TA = +70°C				0.52	3.99			
			TA = +85°C				1.46	8.00			

(Notes and Remarks are listed on the next page.)

- Note 1.** Total current flowing into VDD, EVDD0, and EVDD1, including the input leakage current flowing when the level of the input pin is fixed to VDD, EVDD0, and EVDD1, or Vss, EVss0, and EVss1. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, comparator, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** During HALT instruction execution by flash memory.
- Note 3.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 4.** When high-speed system clock and subsystem clock are stopped.
- Note 5.** When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 6.** Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
- Note 7.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
- HS (high-speed main) mode: 2.7 V ≤ VDD ≤ 5.5 V@1 MHz to 32 MHz  
2.4 V ≤ VDD ≤ 5.5 V@1 MHz to 16 MHz
- LS (low-speed main) mode: 1.8 V ≤ VDD ≤ 5.5 V@1 MHz to 8 MHz
- LV (low-voltage main) mode: 1.6 V ≤ VDD ≤ 5.5 V@1 MHz to 4 MHz
- Note 8.** Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.
- Remark 1.** fMX: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** fHOCO: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** fIH: High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** fSUB: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is TA = 25°C

**(3) Flash ROM: 384 to 512 KB of 48- to 100-pin products**

**(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

**(1/2)**

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit			
Supply current Note 1	I <sub>DD1</sub>	Operating mode	HS (high-speed main) mode Note 5	f <sub>HOCO</sub> = 64 MHz, f <sub>IIH</sub> = 32 MHz Note 3	Basic operation	V <sub>DD</sub> = 5.0 V		2.9		mA		
						V <sub>DD</sub> = 3.0 V		2.9				
					f <sub>HOCO</sub> = 32 MHz, f <sub>IIH</sub> = 32 MHz Note 3	Basic operation	V <sub>DD</sub> = 5.0 V		2.5			
							V <sub>DD</sub> = 3.0 V		2.5			
				HS (high-speed main) mode Note 5	f <sub>HOCO</sub> = 64 MHz, f <sub>IIH</sub> = 32 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		6.0	11.2	mA	
			V <sub>DD</sub> = 3.0 V					6.0	11.2			
			Normal operation			V <sub>DD</sub> = 5.0 V		5.5	10.6			
						V <sub>DD</sub> = 3.0 V		5.5	10.6			
			Normal operation			V <sub>DD</sub> = 5.0 V		4.7	8.6			
						V <sub>DD</sub> = 3.0 V		4.7	8.6			
			Normal operation	V <sub>DD</sub> = 5.0 V		4.4	8.2					
				V <sub>DD</sub> = 3.0 V		4.4	8.2					
				LS (low-speed main) mode Note 5	f <sub>HOCO</sub> = 8 MHz, f <sub>IIH</sub> = 8 MHz Note 3	Normal operation	V <sub>DD</sub> = 3.0 V		1.5	2.5	mA	
							V <sub>DD</sub> = 2.0 V		1.5	2.5		
				LV (low-voltage main) mode Note 5	f <sub>HOCO</sub> = 4 MHz, f <sub>IIH</sub> = 4 MHz Note 3	Normal operation	V <sub>DD</sub> = 3.0 V		1.5	2.1	mA	
							V <sub>DD</sub> = 2.0 V		1.5	2.1		
				HS (high-speed main) mode Note 5	f <sub>MX</sub> = 20 MHz Note 2, V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		3.7	6.8	mA	
							Resonator connection		3.9	7.0		
						Normal operation	f <sub>MX</sub> = 20 MHz Note 2, V <sub>DD</sub> = 3.0 V	Square wave input		3.7	6.8	
								Resonator connection		3.9	7.0	
						Normal operation	f <sub>MX</sub> = 10 MHz Note 2, V <sub>DD</sub> = 5.0 V	Square wave input		2.3	4.1	
								Resonator connection		2.3	4.2	
						Normal operation	f <sub>MX</sub> = 10 MHz Note 2, V <sub>DD</sub> = 3.0 V	Square wave input		2.3	4.1	
								Resonator connection		2.3	4.2	
		LS (low-speed main) mode Note 5	f <sub>MX</sub> = 8 MHz Note 2, V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		1.4	2.4	mA			
					Resonator connection		1.4	2.5				
				Normal operation	f <sub>MX</sub> = 8 MHz Note 2, V <sub>DD</sub> = 2.0 V	Square wave input		1.4	2.4			
						Resonator connection		1.4	2.5			
		Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz Note 4 TA = -40°C	Normal operation	Square wave input		5.2		μA			
					Resonator connection		5.2					
				Normal operation	f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +25°C	Square wave input		5.3	7.7			
						Resonator connection		5.3	7.7			
				Normal operation	f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +50°C	Square wave input		5.5	10.6			
						Resonator connection		5.5	10.6			
		Normal operation	f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +70°C	Square wave input		5.9	13.2					
				Resonator connection		6.0	13.2					
		Normal operation	f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +85°C	Square wave input		6.8	17.5					
				Resonator connection		6.9	17.5					

(Notes and Remarks are listed on the next page.)

- Note 1.** Total current flowing into V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, or V<sub>SS</sub>, EV<sub>SS0</sub>, and EV<sub>SS1</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, comparator, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 3.** When high-speed system clock and subsystem clock are stopped.
- Note 4.** When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation). However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 5.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
- |                             |   |
|-----------------------------|---|
| HS (high-speed main) mode:  | 2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 32 MHz |
|                             | 2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 16 MHz |
| LS (low-speed main) mode:   | 1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 8 MHz  |
| LV (low-voltage main) mode: | 1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V@1 MHz to 4 MHz  |
- Remark 1.** f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** f<sub>HOCO</sub>: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** f<sub>IH</sub>: High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

**(3) Flash ROM: 384 to 512 KB of 48- to 100-pin products****(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(2/2)**

Parameter	Symbol	Conditions			MIN.	TYP.	MAX.	Unit			
Supply current Note 1	I <sub>DD2</sub> Note 2	HALT mode	HS (high-speed main) mode Note 7	f <sub>HOCO</sub> = 64 MHz, f <sub>IH</sub> = 32 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.93	3.32	mA		
					V <sub>DD</sub> = 3.0 V		0.93	3.32			
				f <sub>HOCO</sub> = 32 MHz, f <sub>IH</sub> = 32 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.5	2.63			
					V <sub>DD</sub> = 3.0 V		0.5	2.63			
				f <sub>HOCO</sub> = 48 MHz, f <sub>IH</sub> = 24 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.72	2.60			
					V <sub>DD</sub> = 3.0 V		0.72	2.60			
			f <sub>HOCO</sub> = 24 MHz, f <sub>IH</sub> = 24 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.42	2.03				
				V <sub>DD</sub> = 3.0 V		0.42	2.03				
			f <sub>HOCO</sub> = 16 MHz, f <sub>IH</sub> = 16 MHz Note 4	V <sub>DD</sub> = 5.0 V		0.39	1.50				
				V <sub>DD</sub> = 3.0 V		0.39	1.50				
					LS (low-speed main) mode Note 7	f <sub>HOCO</sub> = 8 MHz, f <sub>IH</sub> = 8 MHz Note 4	V <sub>DD</sub> = 3.0 V		270	800	μA
							V <sub>DD</sub> = 2.0 V		270	800	
				LV (low-voltage main) mode Note 7	f <sub>HOCO</sub> = 4 MHz, f <sub>IH</sub> = 4 MHz Note 4	V <sub>DD</sub> = 3.0 V		450	755	μA	
						V <sub>DD</sub> = 2.0 V		450	755		
				HS (high-speed main) mode Note 7	f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 5.0 V	Square wave input		0.31	1.69	mA	
						Resonator connection		0.41	1.91		
					f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 3.0 V	Square wave input		0.31	1.69		
						Resonator connection		0.41	1.91		
					f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 5.0 V	Square wave input		0.21	0.94		
						Resonator connection		0.26	1.02		
					f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 3.0 V	Square wave input		0.21	0.94		
						Resonator connection		0.26	1.02		
				LS (low-speed main) mode Note 7	f <sub>MX</sub> = 8 MHz Note 3, V <sub>DD</sub> = 3.0 V	Square wave input		110	610	μA	
						Resonator connection		150	660		
					f <sub>MX</sub> = 8 MHz Note 3, V <sub>DD</sub> = 2.0 V	Square wave input		110	610		
						Resonator connection		150	660		
				Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz Note 5, T <sub>A</sub> = -40°C	Square wave input		0.31		μA	
		Resonator connection				0.50					
		f <sub>SUB</sub> = 32.768 kHz Note 5, T <sub>A</sub> = +25°C	Square wave input			0.38	0.76				
			Resonator connection			0.57	0.95				
		f <sub>SUB</sub> = 32.768 kHz Note 5, T <sub>A</sub> = +50°C	Square wave input			0.47	3.59				
			Resonator connection			0.70	3.78				
		f <sub>SUB</sub> = 32.768 kHz Note 5, T <sub>A</sub> = +70°C	Square wave input		0.80	6.20					
			Resonator connection		1.00	6.39					
		f <sub>SUB</sub> = 32.768 kHz Note 5, T <sub>A</sub> = +85°C	Square wave input		1.65	10.56					
			Resonator connection		1.84	10.75					
	I <sub>DD3</sub> Note 6	STOP mode Note 8	T <sub>A</sub> = -40°C				0.19		μA		
			T <sub>A</sub> = +25°C				0.30	0.59			
			T <sub>A</sub> = +50°C				0.41	3.42			
			T <sub>A</sub> = +70°C				0.80	6.03			
			T <sub>A</sub> = +85°C				1.53	10.39			

(Notes and Remarks are listed on the next page.)

- Note 1.** Total current flowing into V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, or V<sub>SS</sub>, EV<sub>SS0</sub>, and EV<sub>SS1</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, comparator, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** During HALT instruction execution by flash memory.
- Note 3.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 4.** When high-speed system clock and subsystem clock are stopped.
- Note 5.** When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 6.** Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
- Note 7.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
- HS (high-speed main) mode:   2.7 V ≤ V<sub>DD</sub> ≤ 5.5 V@1 MHz to 32 MHz  
   2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V@1 MHz to 16 MHz
- LS (low-speed main) mode:   1.8 V ≤ V<sub>DD</sub> ≤ 5.5 V@1 MHz to 8 MHz
- LV (low-voltage main) mode:  1.6 V ≤ V<sub>DD</sub> ≤ 5.5 V@1 MHz to 4 MHz
- Note 8.** Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.
- Remark 1.** f<sub>MX</sub>:   High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** f<sub>HOCO</sub>: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** f<sub>IH</sub>:   High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** f<sub>SUB</sub>:   Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T<sub>A</sub> = 25°C



**(4) Peripheral Functions (Common to all products)****(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed on-chip oscillator operating current	IFIL Note 1				0.20		μA
RTC operating current	IRTC Notes 1, 2, 3				0.02		μA
12-bit interval timer operating current	II_T Notes 1, 2, 4				0.02		μA
Watchdog timer operating current	IWDT Notes 1, 2, 5	fil = 15 kHz			0.22		μA
A/D converter operating current	IADC Notes 1, 6	When conversion at maximum speed	Normal mode, AVREFP = VDD = 5.0 V		1.3	1.7	mA
			Low voltage mode, AVREFP = VDD = 3.0 V		0.5	0.7	mA
A/D converter reference voltage current	IADREF Note 1				75.0		μA
Temperature sensor operating current	ITMPS Note 1				75.0		μA
D/A converter operating current	IDAC Notes 1, 11, 13	Per D/A converter channel				1.5	mA
Comparator operating current	ICMP Notes 1, 12, 13	VDD = 5.0 V, Regulator output voltage = 2.1 V	Window mode		12.5		μA
			Comparator high-speed mode		6.5		μA
			Comparator low-speed mode		1.7		μA
		VDD = 5.0 V, Regulator output voltage = 1.8 V	Window mode		8.0		μA
			Comparator high-speed mode		4.0		μA
			Comparator low-speed mode		1.3		μA
LVD operating current	ILVD Notes 1, 7				0.08		μA
Self-programming operating current	IFSP Notes 1, 9				2.50	12.20	mA
BGO operating current	IBGO Notes 1, 8				2.50	12.20	mA
SNOOZE operating current	ISNOZ Note 1	ADC operation	The mode is performed Note 10		0.50	0.60	mA
			The A/D conversion operations are performed, Low voltage mode, AVREFP = VDD = 3.0 V		1.20	1.44	
		CSI/JART operation		0.70	0.84		
		DTC operation		3.10			

**Note 1.** Current flowing to VDD.**Note 2.** When high speed on-chip oscillator and high-speed system clock are stopped.**Note 3.** Current flowing only to the real-time clock (RTC) (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IRTC, when the real-time clock operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added. IDD2 subsystem clock operation includes the operational current of the real-time clock.**Note 4.** Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and II\_T, when the 12-bit interval timer operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added.

- Note 5.** Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The supply current of the RL78 microcontrollers is the sum of I<sub>DD1</sub>, I<sub>DD2</sub> or I<sub>DD3</sub> and I<sub>WDT</sub> when the watchdog timer is in operation.
- Note 6.** Current flowing only to the A/D converter. The supply current of the RL78 microcontrollers is the sum of I<sub>DD1</sub> or I<sub>DD2</sub> and I<sub>ADC</sub> when the A/D converter operates in an operation mode or the HALT mode.
- Note 7.** Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of I<sub>DD1</sub>, I<sub>DD2</sub> or I<sub>DD3</sub> and I<sub>LVD</sub> when the LVD circuit is in operation.
- Note 8.** Current flowing during programming of the data flash.
- Note 9.** Current flowing during self-programming.
- Note 10.** For shift time to the SNOOZE mode, see **23.3.3 SNOOZE mode** in the RL78/G14 User's Manual.
- Note 11.** Current flowing only to the D/A converter. The supply current of the RL78 microcontrollers is the sum of I<sub>DD1</sub> or I<sub>DD2</sub> and I<sub>DAC</sub> when the D/A converter operates in an operation mode or the HALT mode.
- Note 12.** Current flowing only to the comparator circuit. The supply current of the RL78 microcontrollers is the sum of I<sub>DD1</sub>, I<sub>DD2</sub>, or I<sub>DD3</sub> and I<sub>COMP</sub> when the comparator circuit is in operation.
- Note 13.** A comparator and D/A converter are provided in products with 96 KB or more code flash memory.
- Remark 1.** f<sub>IL</sub>: Low-speed on-chip oscillator clock frequency
- Remark 2.** f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 3.** f<sub>CLK</sub>: CPU/peripheral hardware clock frequency
- Remark 4.** Temperature condition of the TYP. value is T<sub>A</sub> = 25°C

## 2.4 AC Characteristics

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(1/2)

Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit	
Instruction cycle (minimum instruction execution time)	Tcy	Main system clock (fMAIN) operation	HS (high-speed main) mode	2.7 V ≤ VDD ≤ 5.5 V	0.03125		1	μs
				2.4 V ≤ VDD < 2.7 V	0.0625		1	μs
			LS (low-speed main) mode	1.8 V ≤ VDD ≤ 5.5 V	0.125		1	μs
			LV (low-voltage main) mode	1.6 V ≤ VDD ≤ 5.5 V	0.25		1	μs
			Subsystem clock (fSUB) operation	1.8 V ≤ VDD ≤ 5.5 V	28.5	30.5	31.3	μs
		In the self- programming mode	HS (high-speed main) mode	2.7 V ≤ VDD ≤ 5.5 V	0.03125		1	μs
				2.4 V ≤ VDD < 2.7 V	0.0625		1	μs
			LS (low-speed main) mode	1.8 V ≤ VDD ≤ 5.5 V	0.125		1	μs
LV (low-voltage main) mode	1.8 V ≤ VDD ≤ 5.5 V		0.25		1	μs		
External system clock frequency	fex	2.7 V ≤ VDD ≤ 5.5 V		1.0		20.0	MHz	
		2.4 V ≤ VDD ≤ 2.7 V		1.0		16.0	MHz	
		1.8 V ≤ VDD < 2.4 V		1.0		8.0	MHz	
		1.6 V ≤ VDD < 1.8 V		1.0		4.0	MHz	
	fexs			32		35	kHz	
External system clock input high-level width, low-level width	tEXH, tEXL	2.7 V ≤ VDD ≤ 5.5 V		24			ns	
		2.4 V ≤ VDD ≤ 2.7 V		30			ns	
		1.8 V ≤ VDD < 2.4 V		60			ns	
		1.6 V ≤ VDD < 1.8 V		120			ns	
	tEXHS, tEXLS			13.7			μs	
T100 to T103, T110 to T113 input high-level width, low-level width	tT1H, tT1L			1/fMCK + 10 Note			ns	
Timer RJ input cycle	fc	TRJIO	2.7 V ≤ EVDD0 ≤ 5.5 V	100			ns	
			1.8 V ≤ EVDD0 < 2.7 V	300			ns	
			1.6 V ≤ EVDD0 < 1.8 V	500			ns	
Timer RJ input high- level width, low-level width	tTJH, tTJL	TRJIO	2.7 V ≤ EVDD0 ≤ 5.5 V	40			ns	
			1.8 V ≤ EVDD0 < 2.7 V	120			ns	
			1.6 V ≤ EVDD0 < 1.8 V	200			ns	

**Note** The following conditions are required for low voltage interface when EVDD0 < VDD

1.8 V ≤ EVDD0 < 2.7 V: MIN. 125 ns

1.6 V ≤ EVDD0 < 1.8 V: MIN. 250 ns

**Remark** fMCK: Timer array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of timer mode register mn (TMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3))

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(2/2)

Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Timer RD input high-level width, low-level width	tTDIH, tTDIL	TRDIOA0, TRDIOA1, TRDIOB0, TRDIOB1, TRDIOC0, TRDIOC1, TRDIOD0, TRDIOD1		3/fCLK			ns
Timer RD forced cutoff signal input low-level width	tTDSIL	P130/INTP0	2MHz < fCLK ≤ 32 MHz	1			μs
			fCLK ≤ 2 MHz	1/fCLK + 1			
Timer RG input high-level width, low-level width	tTGIH, tTGIL	TRGIOA, TRGIOB		2.5/fCLK			ns
TO00 to TO03, TO10 to TO13, TRJIO0, TRJO0, TRDIOA0, TRDIOA1, TRDIOB0, TRDIOB1, TRDIOC0, TRDIOC1, TRDIOD0, TRDIOD1, TRGIOA, TRGIOB output frequency	fTO	HS (high-speed main) mode	4.0 V ≤ EVDD0 ≤ 5.5 V			16	MHz
			2.7 V ≤ EVDD0 < 4.0 V			8	MHz
			1.8 V ≤ EVDD0 < 2.7 V			4	MHz
			1.6 V ≤ EVDD0 < 1.8 V			2	MHz
		LS (low-speed main) mode	1.8 V ≤ EVDD0 ≤ 5.5 V			4	MHz
			1.6 V ≤ EVDD0 < 1.8 V			2	MHz
LV (low-voltage main) mode	1.6 V ≤ EVDD0 ≤ 5.5 V			2	MHz		
PCLBUZ0, PCLBUZ1 output frequency	fPCL	HS (high-speed main) mode	4.0 V ≤ EVDD0 ≤ 5.5 V			16	MHz
			2.7 V ≤ EVDD0 < 4.0 V			8	MHz
			1.8 V ≤ EVDD0 < 2.7 V			4	MHz
			1.6 V ≤ EVDD0 < 1.8 V			2	MHz
		LS (low-speed main) mode	1.8 V ≤ EVDD0 ≤ 5.5 V			4	MHz
			1.6 V ≤ EVDD0 < 1.8 V			2	MHz
LV (low-voltage main) mode	1.8 V ≤ EVDD0 ≤ 5.5 V			4	MHz		
		1.6 V ≤ EVDD0 < 1.8 V			2	MHz	
Interrupt input high-level width, low-level width	tINTH, tINTL	INTP0	1.6 V ≤ VDD ≤ 5.5 V	1			μs
		INTP1 to INTP11	1.6 V ≤ EVDD0 ≤ 5.5 V	1			μs
Key interrupt input low-level width	tKR	KR0 to KR7	1.8 V ≤ EVDD0 ≤ 5.5 V	250			ns
			1.6 V ≤ EVDD0 < 1.8 V	1			μs
RESET low-level width	tRSL			10			μs

Minimum Instruction Execution Time during Main System Clock Operation

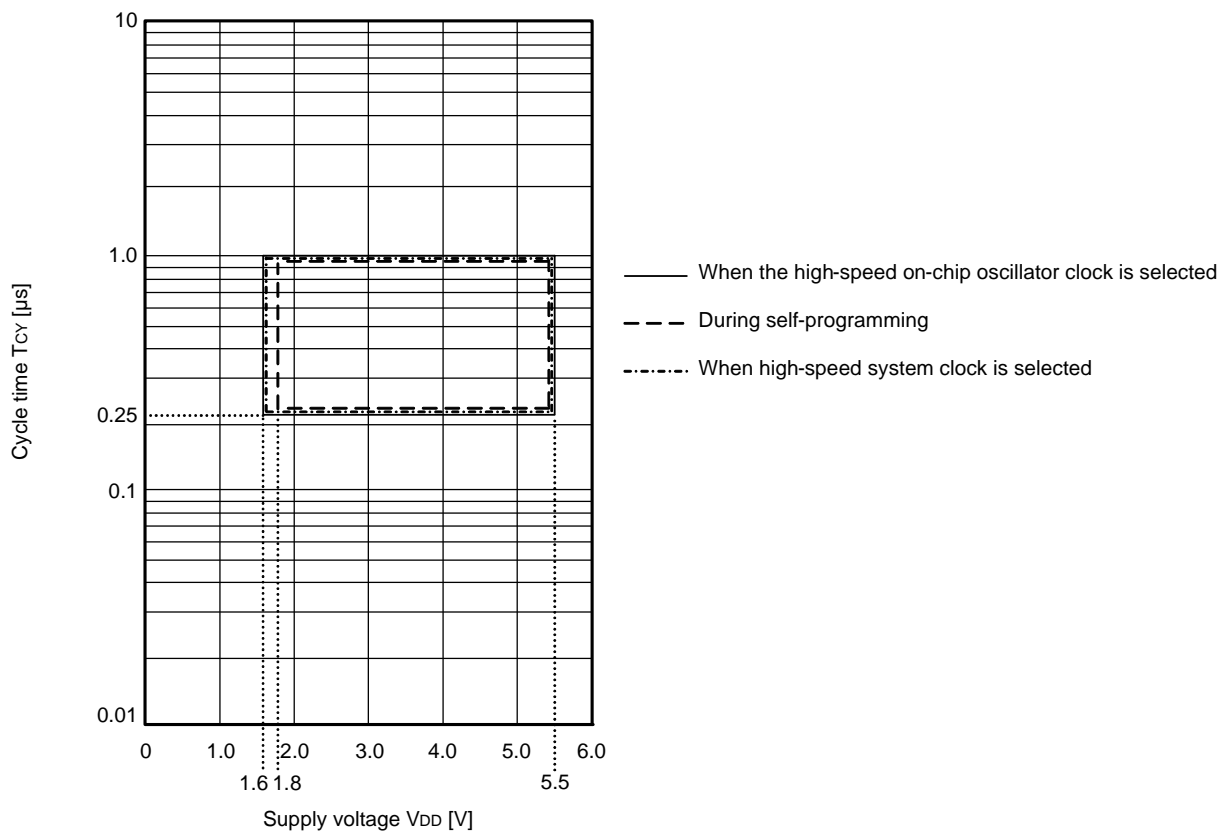
T<sub>cy</sub> vs V<sub>DD</sub> (HS (high-speed main) mode)



T<sub>CY</sub> vs V<sub>DD</sub> (LS (low-speed main) mode)



T<sub>CY</sub> vs V<sub>DD</sub> (LV (low-voltage main) mode)



AC Timing Test Points



External System Clock Timing



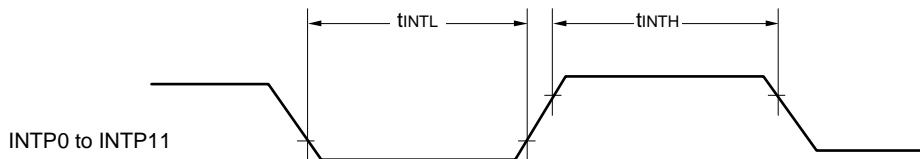
TI/TO Timing







Interrupt Request Input Timing



Key Interrupt Input Timing



RESET Input Timing



## 2.5 Peripheral Functions Characteristics

### AC Timing Test Points



### 2.5.1 Serial array unit

#### (1) During communication at same potential (UART mode)

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Transfer rate Note 1		2.4 V ≤ EVDD0 ≤ 5.5 V		fMCK/6 Note 2		fMCK/6		fMCK/6	bps
		Theoretical value of the maximum transfer rate fMCK = fCLK Note 3		5.3		1.3		0.6	Mbps
		1.8 V ≤ EVDD0 ≤ 5.5 V		fMCK/6 Note 2		fMCK/6		fMCK/6	bps
		Theoretical value of the maximum transfer rate fMCK = fCLK Note 3		5.3		1.3		0.6	Mbps
		1.7 V ≤ EVDD0 ≤ 5.5 V		fMCK/6 Note 2		fMCK/6 Note 2		fMCK/6	bps
		Theoretical value of the maximum transfer rate fMCK = fCLK Note 3		5.3		1.3		0.6	Mbps
		1.6 V ≤ EVDD0 ≤ 5.5 V	—			fMCK/6 Note 2		fMCK/6	bps
		Theoretical value of the maximum transfer rate fMCK = fCLK Note 3	—			1.3		0.6	Mbps

**Note 1.** Transfer rate in the SNOOZE mode is 4800 bps only.

However, the SNOOZE mode cannot be used when FRQSEL4 = 1.

**Note 2.** The following conditions are required for low voltage interface when EVDD0 < VDD.

2.4 V ≤ EVDD0 < 2.7 V: MAX. 2.6 Mbps

1.8 V ≤ EVDD0 < 2.4 V: MAX. 1.3 Mbps

1.6 V ≤ EVDD0 < 1.8 V: MAX. 0.6 Mbps

**Note 3.** The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:

HS (high-speed main) mode: 32 MHz (2.7 V ≤ VDD ≤ 5.5 V)

16 MHz (2.4 V ≤ VDD ≤ 5.5 V)

LS (low-speed main) mode: 8 MHz (1.8 V ≤ VDD ≤ 5.5 V)

LV (low-voltage main) mode: 4 MHz (1.6 V ≤ VDD ≤ 5.5 V)

**Caution** Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**UART mode connection diagram (during communication at same potential)**



**UART mode bit width (during communication at same potential) (reference)**



**Remark 1.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 5, 14)

**Remark 2.** f<sub>MCK</sub>: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**(2) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output, corresponding CSI00 only)****(TA = -40 to +85°C, 2.7 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	tkCY1	tkCY1 ≥ 2/fCLK 4.0 V ≤ EVDD0 ≤ 5.5 V	62.5		250		500		ns
			83.3		250		500		ns
SCKp high-/low-level width	tkH1, tkL1	4.0 V ≤ EVDD0 ≤ 5.5 V	tkCY1/2 - 7		tkCY1/2 - 50		tkCY1/2 - 50		ns
		2.7 V ≤ EVDD0 ≤ 5.5 V	tkCY1/2 - 10		tkCY1/2 - 50		tkCY1/2 - 50		ns
Slp setup time (to SCKp↑) Note 1	tsIK1	4.0 V ≤ EVDD0 ≤ 5.5 V	23		110		110		ns
		2.7 V ≤ EVDD0 ≤ 5.5 V	33		110		110		ns
Slp hold time (from SCKp↑) Note 2	tkSI1	2.7 V ≤ EVDD0 ≤ 5.5 V	10		10		10		ns
Delay time from SCKp↓ to SOp output Note 3	tkSO1	C = 20 pF Note 4		10		10		10	ns

**Note 1.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 2.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 3.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 4.** C is the load capacitance of the SCKp and SOp output lines.

**Caution** Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark 1.** This value is valid only when CSI00's peripheral I/O redirect function is not used.

**Remark 2.** p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0),  
g: PIM and POM numbers (g = 1)

**Remark 3.** fMCK: Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,  
n: Channel number (mn = 00))

**(3) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output)**  
**(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

Parameter	Symbol	Conditions		HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	tkCY1	tkCY1 ≥ 4/fCLK	2.7 V ≤ EVDD0 ≤ 5.5 V	125		500		1000		ns
			2.4 V ≤ EVDD0 ≤ 5.5 V	250		500		1000		ns
			1.8 V ≤ EVDD0 ≤ 5.5 V	500		500		1000		ns
			1.7 V ≤ EVDD0 ≤ 5.5 V	1000		1000		1000		ns
			1.6 V ≤ EVDD0 ≤ 5.5 V	—		1000		1000		ns
SCKp high-/low-level width	tkH1, tkL1	4.0 V ≤ EVDD0 ≤ 5.5 V	tkCY1/2 - 12		tkCY1/2 - 50		tkCY1/2 - 50		ns	
		2.7 V ≤ EVDD0 ≤ 5.5 V	tkCY1/2 - 18		tkCY1/2 - 50		tkCY1/2 - 50		ns	
		2.4 V ≤ EVDD0 ≤ 5.5 V	tkCY1/2 - 38		tkCY1/2 - 50		tkCY1/2 - 50		ns	
		1.8 V ≤ EVDD0 ≤ 5.5 V	tkCY1/2 - 50		tkCY1/2 - 50		tkCY1/2 - 50		ns	
		1.7 V ≤ EVDD0 ≤ 5.5 V	tkCY1/2 - 100		tkCY1/2 - 100		tkCY1/2 - 100		ns	
		1.6 V ≤ EVDD0 ≤ 5.5 V	—		tkCY1/2 - 100		tkCY1/2 - 100		ns	
Slp setup time (to SCKp↑) Note 1	tSIK1	4.0 V ≤ EVDD0 ≤ 5.5 V	44		110		110		ns	
		2.7 V ≤ EVDD0 ≤ 5.5 V	44		110		110		ns	
		2.4 V ≤ EVDD0 ≤ 5.5 V	75		110		110		ns	
		1.8 V ≤ EVDD0 ≤ 5.5 V	110		110		110		ns	
		1.7 V ≤ EVDD0 ≤ 5.5 V	220		220		220		ns	
		1.6 V ≤ EVDD0 ≤ 5.5 V	—		220		220		ns	
Slp hold time (from SCKp↑) Note 2	tKSI1	1.7 V ≤ EVDD0 ≤ 5.5 V	19		19		19		ns	
		1.6 V ≤ EVDD0 ≤ 5.5 V	—		19		19		ns	
Delay time from SCKp↓ to SOp output Note 3	tkSO1	1.7 V ≤ EVDD0 ≤ 5.5 V C = 30 pF Note 4		25		25		25	ns	
		1.6 V ≤ EVDD0 ≤ 5.5 V C = 30 pF Note 4		—		25		25	ns	

**Note 1.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 2.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 3.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 4.** C is the load capacitance of the SCKp and SOp output lines.

**Caution** Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM number (g = 0, 1, 3 to 5, 14)

**Remark 2.** fMCK: Serial array unit operation clock frequency  
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**(4) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)****(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(1/2)**

Parameter	Symbol	Conditions		HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time Note 5	tkCY2	4.0 V ≤ EVDD0 ≤ 5.5 V	20 MHz < fMCK	8/fMCK	—	—	—	—	ns	
			fMCK ≤ 20 MHz	6/fMCK	—	6/fMCK	6/fMCK	ns		
		2.7 V ≤ EVDD0 ≤ 5.5 V	16 MHz < fMCK	8/fMCK	—	—	—	ns		
			fMCK ≤ 16 MHz	6/fMCK	—	6/fMCK	6/fMCK	ns		
		2.4 V ≤ EVDD0 ≤ 5.5 V		6/fMCK and 500	6/fMCK and 500	6/fMCK and 500	6/fMCK and 500	ns		
		1.8 V ≤ EVDD0 ≤ 5.5 V		6/fMCK and 750	6/fMCK and 750	6/fMCK and 750	6/fMCK and 750	ns		
		1.7 V ≤ EVDD0 ≤ 5.5 V		6/fMCK and 1500	6/fMCK and 1500	6/fMCK and 1500	6/fMCK and 1500	ns		
		1.6 V ≤ EVDD0 ≤ 5.5 V		—	6/fMCK and 1500	6/fMCK and 1500	6/fMCK and 1500	ns		
SCKp high-/low-level width	tkH2, tkL2	4.0 V ≤ EVDD0 ≤ 5.5 V		tkCY2/2 - 7	tkCY2/2 - 7	tkCY2/2 - 7	tkCY2/2 - 7	ns		
		2.7 V ≤ EVDD0 ≤ 5.5 V		tkCY2/2 - 8	tkCY2/2 - 8	tkCY2/2 - 8	tkCY2/2 - 8	ns		
		1.8 V ≤ EVDD0 ≤ 5.5 V		tkCY2/2 - 18	tkCY2/2 - 18	tkCY2/2 - 18	tkCY2/2 - 18	ns		
		1.7 V ≤ EVDD0 ≤ 5.5 V		tkCY2/2 - 66	tkCY2/2 - 66	tkCY2/2 - 66	tkCY2/2 - 66	ns		
		1.6 V ≤ EVDD0 ≤ 5.5 V		—	tkCY2/2 - 66	tkCY2/2 - 66	tkCY2/2 - 66	ns		
Slp setup time (to SCKp↑) Note 1	tsIK2	2.7 V ≤ EVDD0 ≤ 5.5 V		1/fMCK + 20	1/fMCK + 30	1/fMCK + 30	1/fMCK + 30	ns		
		1.8 V ≤ EVDD0 ≤ 5.5 V		1/fMCK + 30	1/fMCK + 30	1/fMCK + 30	1/fMCK + 30	ns		
		1.7 V ≤ EVDD0 ≤ 5.5 V		1/fMCK + 40	1/fMCK + 40	1/fMCK + 40	1/fMCK + 40	ns		
		1.6 V ≤ EVDD0 ≤ 5.5 V		—	1/fMCK + 40	1/fMCK + 40	1/fMCK + 40	ns		
Slp hold time (from SCKp↑) Note 2	tkSI2	1.8 V ≤ EVDD0 ≤ 5.5 V		1/fMCK + 31	1/fMCK + 31	1/fMCK + 31	1/fMCK + 31	ns		
		1.7 V ≤ EVDD0 ≤ 5.5 V		1/fMCK + 250	1/fMCK + 250	1/fMCK + 250	1/fMCK + 250	ns		
		1.6 V ≤ EVDD0 ≤ 5.5 V		—	1/fMCK + 250	1/fMCK + 250	1/fMCK + 250	ns		
Delay time from SCKp↓ to SOp output Note 3	tkSO2	C = 30 pF Note 4	2.7 V ≤ EVDD0 ≤ 5.5 V	2/fMCK + 44	2/fMCK + 110	2/fMCK + 110	2/fMCK + 110	ns		
			2.4 V ≤ EVDD0 ≤ 5.5 V	2/fMCK + 75	2/fMCK + 110	2/fMCK + 110	2/fMCK + 110	ns		
			1.8 V ≤ EVDD0 ≤ 5.5 V	2/fMCK + 100	2/fMCK + 110	2/fMCK + 110	2/fMCK + 110	ns		
			1.7 V ≤ EVDD0 ≤ 5.5 V	2/fMCK + 220	2/fMCK + 220	2/fMCK + 220	2/fMCK + 220	ns		
			1.6 V ≤ EVDD0 ≤ 5.5 V	—	2/fMCK + 220	2/fMCK + 220	2/fMCK + 220	ns		

**Note 1.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 2.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 3.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 4.** C is the load capacitance of the SOp output lines.

**Note 5.** The maximum transfer rate when using the SNOOZE mode is 1 Mbps.

**Caution** Select the normal input buffer for the Slp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1),  
n: Channel number (n = 0 to 3), g: PIM number (g = 0, 1, 3 to 5, 14)

**Remark 2.** f<sub>MCK</sub>: Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,  
n: Channel number (mn = 00 to 03, 10 to 13))

**(4) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)**

**(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

**(2/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit	
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
SSI00 setup time	tSSIK	DAPmn = 0	2.7 V ≤ EVDD0 ≤ 5.5 V	120		120		120		ns
			1.8 V ≤ EVDD0 ≤ 5.5 V	200		200		200		ns
			1.7 V ≤ EVDD0 ≤ 5.5 V	400		400		400		ns
			1.6 V ≤ EVDD0 ≤ 5.5 V	—		400		400		ns
		DAPmn = 1	2.7 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 120		1/fMCK + 120		1/fMCK + 120		ns
			1.8 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 200		1/fMCK + 200		1/fMCK + 200		ns
			1.7 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 400		1/fMCK + 400		1/fMCK + 400		ns
			1.6 V ≤ EVDD0 ≤ 5.5 V	—		1/fMCK + 400		1/fMCK + 400		ns
SSI00 hold time	tkSSI	DAPmn = 0	2.7 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 120		1/fMCK + 120		1/fMCK + 120		ns
			1.8 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 200		1/fMCK + 200		1/fMCK + 200		ns
			1.7 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 400		1/fMCK + 400		1/fMCK + 400		ns
			1.6 V ≤ EVDD0 ≤ 5.5 V	—		1/fMCK + 400		1/fMCK + 400		ns
		DAPmn = 1	2.7 V ≤ EVDD0 ≤ 5.5 V	120		120		120		ns
			1.8 V ≤ EVDD0 ≤ 5.5 V	200		200		200		ns
			1.7 V ≤ EVDD0 ≤ 5.5 V	400		400		400		ns
			1.6 V ≤ EVDD0 ≤ 5.5 V	—		400		400		ns

**Caution** Select the normal input buffer for the SIp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark** p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0), g: PIM number (g = 3, 5)

**CSI mode connection diagram (during communication at same potential)**



**CSI mode connection diagram (during communication at same potential)  
(Slave Transmission of slave select input function (CSI00))**



**Remark 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31)

**Remark 2.** m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13)



**CSI mode serial transfer timing (during communication at same potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (during communication at same potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



**Remark 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31)

**Remark 2.** m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13)

**(5) During communication at same potential (simplified I<sup>2</sup>C mode)****(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(1/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCLr clock frequency	f <sub>SCL</sub>	2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ		1000 Note 1		400 Note 1		400 Note 1	kHz
		1.8 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ		400 Note 1		400 Note 1		400 Note 1	kHz
		1.8 V ≤ EVDD0 < 2.7 V, Cb = 100 pF, Rb = 5 kΩ		300 Note 1		300 Note 1		300 Note 1	kHz
		1.7 V ≤ EVDD0 < 1.8 V, Cb = 100 pF, Rb = 5 kΩ		250 Note 1		250 Note 1		250 Note 1	kHz
		1.6 V ≤ EVDD0 < 1.8 V, Cb = 100 pF, Rb = 5 kΩ		—		250 Note 1		250 Note 1	kHz
Hold time when SCLr = "L"	t <sub>LOW</sub>	2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ	475		1150		1150		ns
		1.8 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ	1150		1150		1150		ns
		1.8 V ≤ EVDD0 < 2.7 V, Cb = 100 pF, Rb = 5 kΩ	1550		1550		1550		ns
		1.7 V ≤ EVDD0 < 1.8 V, Cb = 100 pF, Rb = 5 kΩ	1850		1850		1850		ns
		1.6 V ≤ EVDD0 < 1.8 V, Cb = 100 pF, Rb = 5 kΩ	—		1850		1850		ns
Hold time when SCLr = "H"	t <sub>HIGH</sub>	2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ	475		1150		1150		ns
		1.8 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ	1150		1150		1150		ns
		1.8 V ≤ EVDD0 < 2.7 V, Cb = 100 pF, Rb = 5 kΩ	1550		1550		1550		ns
		1.7 V ≤ EVDD0 < 1.8 V, Cb = 100 pF, Rb = 5 kΩ	1850		1850		1850		ns
		1.6 V ≤ EVDD0 < 1.8 V, Cb = 100 pF, Rb = 5 kΩ	—		1850		1850		ns

(Notes and Caution are listed on the next page, and Remarks are listed on the page after the next page.)

**(5) During communication at same potential (simplified I<sup>2</sup>C mode)****(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(2/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Data setup time (reception)	tsu: DAT	2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ	1/fmck + 85 Note 2		1/fmck + 145 Note 2		1/fmck + 145 Note 2		ns
		1.8 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ	1/fmck + 145 Note 2		1/fmck + 145 Note 2		1/fmck + 145 Note 2		ns
		1.8 V ≤ EVDD0 < 2.7 V, Cb = 100 pF, Rb = 5 kΩ	1/fmck + 230 Note 2		1/fmck + 230 Note 2		1/fmck + 230 Note 2		ns
		1.7 V ≤ EVDD0 < 1.8 V, Cb = 100 pF, Rb = 5 kΩ	1/fmck + 290 Note 2		1/fmck + 290 Note 2		1/fmck + 290 Note 2		ns
		1.6 V ≤ EVDD0 < 1.8 V, Cb = 100 pF, Rb = 5 kΩ	—		1/fmck + 290 Note 2		1/fmck + 290 Note 2		ns
Data hold time (transmission)	thd: DAT	2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ	0	305	0	305	0	305	ns
		1.8 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ	0	355	0	355	0	355	ns
		1.8 V ≤ EVDD0 < 2.7 V, Cb = 100 pF, Rb = 5 kΩ	0	405	0	405	0	405	ns
		1.7 V ≤ EVDD0 < 1.8 V, Cb = 100 pF, Rb = 5 kΩ	0	405	0	405	0	405	ns
		1.6 V ≤ EVDD0 < 1.8 V, Cb = 100 pF, Rb = 5 kΩ	—		0	405	0	405	ns

**Note 1.** The value must also be equal to or less than fmck/4.

**Note 2.** Set the fmck value to keep the hold time of SCLr = "L" and SCLr = "H".

**Caution** Select the normal input buffer and the N-ch open drain output (V<sub>DD</sub> tolerance (for the 30- to 52-pin products)/EV<sub>DD</sub> tolerance (for the 64- to 100-pin products)) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

(Remarks are listed on the next page.)

**Simplified I<sup>2</sup>C mode connection diagram (during communication at same potential)**



**Simplified I<sup>2</sup>C mode serial transfer timing (during communication at same potential)**



**Remark 1.** R<sub>b</sub>[Ω]: Communication line (SDAr) pull-up resistance, C<sub>b</sub>[F]: Communication line (SDAr, SCLr) load capacitance

**Remark 2.** r: IIC number (r = 00, 01, 10, 11, 20, 21, 30, 31), g: PIM number (g = 0, 1, 3 to 5, 14),  
h: POM number (h = 0, 1, 3 to 5, 7, 14)

**Remark 3.** f<sub>MCK</sub>: Serial array unit operation clock frequency  
(Operation clock to be set by the CKS<sub>mn</sub> bit of serial mode register mn (SMR<sub>mn</sub>). m: Unit number (m = 0, 1),  
n: Channel number (n = 0 to 3), mn = 00 to 03, 10 to 13)

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)****(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(1/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit	
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
Transfer rate		reception	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V		fMCK/6 Note 1		fMCK/6 Note 1		fMCK/6 Note 1	bps
			Theoretical value of the maximum transfer rate fMCK = fCLK Note 4		5.3		1.3		0.6	Mbps
			2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V		fMCK/6 Note 1		fMCK/6 Note 1		fMCK/6 Note 1	bps
			Theoretical value of the maximum transfer rate fMCK = fCLK Note 4		5.3		1.3		0.6	Mbps
			1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V		fMCK/6 Notes 1, 2, 3		fMCK/6 Notes 1, 2		fMCK/6 Notes 1, 2	bps
			Theoretical value of the maximum transfer rate fMCK = fCLK Note 4		5.3		1.3		0.6	Mbps

**Note 1.** Transfer rate in the SNOOZE mode is 4800 bps only.

However, the SNOOZE mode cannot be used when FRQSEL4 = 1.

**Note 2.** Use it with EVDD0 ≥ Vb.

**Note 3.** The following conditions are required for low voltage interface when EVDD0 < VDD.

2.4 V ≤ EVDD0 < 2.7 V: MAX. 2.6 Mbps

1.8 V ≤ EVDD0 < 2.4 V: MAX. 1.3 Mbps

**Note 4.** The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:

HS (high-speed main) mode: 32 MHz (2.7 V ≤ VDD ≤ 5.5 V)

16 MHz (2.4 V ≤ VDD ≤ 5.5 V)

LS (low-speed main) mode: 8 MHz (1.8 V ≤ VDD ≤ 5.5 V)

LV (low-voltage main) mode: 4 MHz (1.6 V ≤ VDD ≤ 5.5 V)

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

**Remark 1.** Vb [V]: Communication line voltage

**Remark 2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 5, 14)

**Remark 3.** fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

n: Channel number (mn = 00 to 03, 10 to 13)

**Remark 4.** UART2 cannot communicate at different potential when bit 1 (PIOR01) of peripheral I/O redirection register 0 (PIOR0) is 1.

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)****(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(2/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit	
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
Transfer rate		transmission	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V		Note 1		Note 1		Note 1	bps
			Theoretical value of the maximum transfer rate Cb = 50 pF, Rb = 1.4 kΩ, Vb = 2.7 V		2.8 Note 2		2.8 Note 2		2.8 Note 2	Mbps
			2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V		Note 3		Note 3		Note 3	bps
			Theoretical value of the maximum transfer rate Cb = 50 pF, Rb = 2.7 kΩ, Vb = 2.3 V		1.2 Note 4		1.2 Note 4		1.2 Note 4	Mbps
			1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V		Notes 5, 6		Notes 5, 6		Notes 5, 6	bps
			Theoretical value of the maximum transfer rate Cb = 50 pF, Rb = 5.5 kΩ, Vb = 1.6 V		0.43 Note 7		0.43 Note 7		0.43 Note 7	Mbps

**Note 1.** The smaller maximum transfer rate derived by using  $f_{MCK}/6$  or the following expression is the valid maximum transfer rate. Expression for calculating the transfer rate when  $4.0\text{ V} \leq EVDD0 \leq 5.5\text{ V}$  and  $2.7\text{ V} \leq Vb \leq 4.0\text{ V}$

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides

**Note 2.** This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to **Note 1** above to calculate the maximum transfer rate under conditions of the customer.

**Note 3.** The smaller maximum transfer rate derived by using  $f_{MCK}/6$  or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when  $2.7\text{ V} \leq EVDD0 < 4.0\text{ V}$  and  $2.3\text{ V} \leq Vb \leq 2.7\text{ V}$

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides

**Note 4.** This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to **Note 3** above to calculate the maximum transfer rate under conditions of the customer.

**Note 5.** Use it with  $EV_{DD0} \geq V_b$ .

**Note 6.** The smaller maximum transfer rate derived by using  $f_{mck}/6$  or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when  $1.8 \text{ V} \leq EV_{DD0} < 3.3 \text{ V}$  and  $1.6 \text{ V} \leq V_b \leq 2.0 \text{ V}$

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\}}{\left(\frac{1}{\text{Transfer rate}}\right) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides

**Note 7.** This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to **Note 6** above to calculate the maximum transfer rate under conditions of the customer.

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output ( $V_{DD}$  tolerance (for the 30- to 52-pin products)/ $EV_{DD}$  tolerance (for the 64- to 100-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

**UART mode connection diagram (during communication at different potential)**



**UART mode bit width (during communication at different potential) (reference)**



- Remark 1.**  $R_b[\Omega]$ : Communication line (TxDq) pull-up resistance,  
 $C_b[F]$ : Communication line (TxDq) load capacitance,  $V_b[V]$ : Communication line voltage
- Remark 2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 5, 14)
- Remark 3.**  $f_{mck}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).  
 m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))
- Remark 4.** UART2 cannot communicate at different potential when bit 1 (PIOR01) of peripheral I/O redirection register 0 (PIOR0) is 1.



**(7) Communication at different potential (2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output, corresponding CSI00 only)****(TA = -40 to +85°C, 2.7 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(1/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	tkCY1	tkCY1 ≥ 2/fCLK 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 20 pF, Rb = 1.4 kΩ	200		1150		1150		ns
			300		1150		1150		ns
SCKp high-level width	tkH1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 20 pF, Rb = 1.4 kΩ	tkCY1/2 - 50		tkCY1/2 - 50		tkCY1/2 - 50		ns
			tkCY1/2 - 120		tkCY1/2 - 120		tkCY1/2 - 120		ns
SCKp low-level width	tkL1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 20 pF, Rb = 1.4 kΩ	tkCY1/2 - 7		tkCY1/2 - 50		tkCY1/2 - 50		ns
			tkCY1/2 - 10		tkCY1/2 - 50		tkCY1/2 - 50		ns
Slp setup time (to SCKp↑) <sup>Note 1</sup>	tSIK1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 20 pF, Rb = 1.4 kΩ	58		479		479		ns
			121		479		479		ns
Slp hold time (from SCKp↑) <sup>Note 1</sup>	tKSI1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 20 pF, Rb = 1.4 kΩ	10		10		10		ns
			10		10		10		ns
Delay time from SCKp↓ to SOp output <sup>Note 1</sup>	tkSO1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 20 pF, Rb = 1.4 kΩ		60		60		60	ns
				130		130		130	ns

(Notes, Caution, and Remarks are listed on the next page.)

**(7) Communication at different potential (2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output, corresponding CSI00 only)****(TA = -40 to +85°C, 2.7 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(2/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Slp setup time (to SCKp↓) Note 2	tsIK1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 20 pF, Rb = 1.4 kΩ	23		110		110		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 20 pF, Rb = 2.7 kΩ	33		110		110		ns
Slp hold time (from SCKp↓) Note 2	tKSI1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 20 pF, Rb = 1.4 kΩ	10		10		10		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 20 pF, Rb = 2.7 kΩ	10		10		10		ns
Delay time from SCKp↑ to SOp output Note 2	tKSO1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 20 pF, Rb = 1.4 kΩ		10		10		10	ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 20 pF, Rb = 2.7 kΩ		10		10		10	ns

**Note 1.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.

**Note 2.** When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

**Remark 1.** Rb[Ω]: Communication line (SCKp, SOp) pull-up resistance, Cb[F]: Communication line (SCKp, SOp) load capacitance, Vb[V]: Communication line voltage

**Remark 2.** p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0), g: PIM and POM number (g = 3, 5)

**Remark 3.** fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))

**Remark 4.** This value is valid only when CSI00's peripheral I/O redirect function is not used.

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output)****(TA = -40 to +85°C, 1.8 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(1/3)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	tkCY1	tkCY1 ≥ 4/fCLK 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	300		1150		1150		ns
			500		1150		1150		ns
			1150		1150		1150		ns
SCKp high-level width	tkH1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	tkCY1/2 - 75		tkCY1/2 - 75		tkCY1/2 - 75		ns
			tkCY1/2 - 170		tkCY1/2 - 170		tkCY1/2 - 170		ns
			tkCY1/2 - 458		tkCY1/2 - 458		tkCY1/2 - 458		ns
SCKp low-level width	tkL1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	tkCY1/2 - 12		tkCY1/2 - 50		tkCY1/2 - 50		ns
			tkCY1/2 - 18		tkCY1/2 - 50		tkCY1/2 - 50		ns
			tkCY1/2 - 50		tkCY1/2 - 50		tkCY1/2 - 50		ns

**Note** Use it with EVDD0 ≥ Vb.

**Caution** Select the TTL input buffer for the SIp pin and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the SOP pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

(Remarks are listed two pages after the next page.)

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output)****(TA = -40 to +85°C, 1.8 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(2/3)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Slp setup time (to SCKp↑) Note 1	tSIK1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	81		479		479		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ	177		479		479		ns
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 30 pF, Rb = 5.5 kΩ	479		479		479		ns
Slp hold time (from SCKp↑) Note 1	tKSI1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	19		19		19		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ	19		19		19		ns
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 30 pF, Rb = 5.5 kΩ	19		19		19		ns
Delay time from SCKp↓ to SOp output Note 1	tKSO1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ		100		100		100	ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ		195		195		195	ns
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 30 pF, Rb = 5.5 kΩ		483		483		483	ns

**Note 1.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.**Note 2.** Use it with EVDD0 ≥ Vb.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the page after the next page.)

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output)****(TA = -40 to +85°C, 1.8 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(3/3)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Slp setup time (to SCKp↓) Note 1	tSIK1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	44		110		110		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ	44		110		110		ns
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 30 pF, Rb = 5.5 kΩ	110		110		110		ns
Slp hold time (from SCKp↓) Note 1	tKSI1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	19		19		19		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ	19		19		19		ns
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 30 pF, Rb = 5.5 kΩ	19		19		19		ns
Delay time from SCKp↑ to SOp output Note 1	tKSO1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ		25		25		25	ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ		25		25		25	ns
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 30 pF, Rb = 5.5 kΩ		25		25		25	ns

**Note 1.** When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.**Note 2.** Use it with EVDD0 ≥ Vb.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

**CSI mode connection diagram (during communication at different potential)**



- Remark 1.** R<sub>b</sub>[Ω]: Communication line (SCK<sub>p</sub>, SO<sub>p</sub>) pull-up resistance, C<sub>b</sub>[F]: Communication line (SCK<sub>p</sub>, SO<sub>p</sub>) load capacitance, V<sub>b</sub>[V]: Communication line voltage
- Remark 2.** p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM and POM number (g = 0, 1, 3 to 5, 14)
- Remark 3.** f<sub>MCK</sub>: Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))
- Remark 4.** CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

**CSI mode serial transfer timing (master mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (master mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



**Remark 1.** p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM and POM number (g = 0, 1, 3 to 5, 14)

**Remark 2.** CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

**(9) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock input)****(TA = -40 to +85°C, 1.8 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit		
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.			
SCKp cycle time Note 1	tkcy2	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V	24 MHz < fmck	14/fmck	—	—	—	—	ns		
			20 MHz < fmck ≤ 24 MHz	12/fmck	—	—	—	—	ns		
			8 MHz < fmck ≤ 20 MHz	10/fmck	—	—	—	—	ns		
			4 MHz < fmck ≤ 8 MHz	8/fmck	—	16/fmck	—	—	ns		
			fmck ≤ 4 MHz	6/fmck	—	10/fmck	10/fmck	—	ns		
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V	24 MHz < fmck	20/fmck	—	—	—	—	ns		
			20 MHz < fmck ≤ 24 MHz	16/fmck	—	—	—	—	ns		
			16 MHz < fmck ≤ 20 MHz	14/fmck	—	—	—	—	ns		
			8 MHz < fmck ≤ 16 MHz	12/fmck	—	—	—	—	ns		
			4 MHz < fmck ≤ 8 MHz	8/fmck	—	16/fmck	—	—	ns		
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2	24 MHz < fmck	48/fmck	—	—	—	—	ns		
			20 MHz < fmck ≤ 24 MHz	36/fmck	—	—	—	—	ns		
			16 MHz < fmck ≤ 20 MHz	32/fmck	—	—	—	—	ns		
			8 MHz < fmck ≤ 16 MHz	26/fmck	—	—	—	—	ns		
			4 MHz < fmck ≤ 8 MHz	16/fmck	—	16/fmck	—	—	ns		
SCKp high-/ low-level width	tkH2, tkL2	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V	tkcy2/2	—	tkcy2/2	—	tkcy2/2	—	ns		
			- 12	—	- 50	—	- 50	—	ns		
			2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V	tkcy2/2	—	tkcy2/2	—	tkcy2/2	—	ns	
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2	tkcy2/2	—	tkcy2/2	—	tkcy2/2	—	ns		
			- 50	—	- 50	—	- 50	—	ns		
			Slp setup time (to SCKp↑) Note 3	tsik2	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V	1/fmck	—	1/fmck	—	1/fmck	—
			2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V	1/fmck	—	1/fmck	—	1/fmck	—	ns	
			1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2	1/fmck	—	1/fmck	—	1/fmck	—	ns	
			Slp hold time (from SCKp↑) Note 4	tksl2		1/fmck	—	1/fmck	—	1/fmck	—
	Delay time from SCKp↓ to SOp output Note 5	tkso2	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ		2/fmck	—	2/fmck	—	2/fmck	—	ns
			2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ		2/fmck	—	2/fmck	—	2/fmck	—	ns
			1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 30 pF, Rv = 5.5 kΩ		2/fmck	—	2/fmck	—	2/fmck	—	ns

(Notes, Caution, and Remarks are listed on the next page.)



- Note 1.** Transfer rate in the SNOOZE mode: MAX. 1 Mbps
- Note 2.** Use it with  $EV_{DD0} \geq V_b$ .
- Note 3.** When  $DAP_{mn} = 0$  and  $CKP_{mn} = 0$ , or  $DAP_{mn} = 1$  and  $CKP_{mn} = 1$ . The  $Slp$  setup time becomes “to  $SCKp\downarrow$ ” when  $DAP_{mn} = 0$  and  $CKP_{mn} = 1$ , or  $DAP_{mn} = 1$  and  $CKP_{mn} = 0$ .
- Note 4.** When  $DAP_{mn} = 0$  and  $CKP_{mn} = 0$ , or  $DAP_{mn} = 1$  and  $CKP_{mn} = 1$ . The  $Slp$  hold time becomes “from  $SCKp\downarrow$ ” when  $DAP_{mn} = 0$  and  $CKP_{mn} = 1$ , or  $DAP_{mn} = 1$  and  $CKP_{mn} = 0$ .
- Note 5.** When  $DAP_{mn} = 0$  and  $CKP_{mn} = 0$ , or  $DAP_{mn} = 1$  and  $CKP_{mn} = 1$ . The delay time to  $SOp$  output becomes “from  $SCKp\uparrow$ ” when  $DAP_{mn} = 0$  and  $CKP_{mn} = 1$ , or  $DAP_{mn} = 1$  and  $CKP_{mn} = 0$ .
- Caution** Select the TTL input buffer for the  $Slp$  pin and  $SCKp$  pin, and the N-ch open drain output ( $V_{DD}$  tolerance (for the 30- to 52-pin products)/ $EV_{DD}$  tolerance (for the 64- to 100-pin products)) mode for the  $SOp$  pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

**CSI mode connection diagram (during communication at different potential)**



- Remark 1.**  $R_b[\Omega]$ : Communication line ( $SOp$ ) pull-up resistance,  $C_b[F]$ : Communication line ( $SOp$ ) load capacitance,  $V_b[V]$ : Communication line voltage
- Remark 2.** p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM and POM number (g = 0, 1, 3 to 5, 14)
- Remark 3.**  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the  $CKSmn$  bit of serial mode register mn (SMRmn).  
m: Unit number, n: Channel number (mn = 00, 01, 02, 10, 12, 13))
- Remark 4.** CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.  
Also, communication at different potential cannot be performed during clock synchronous serial communication with the slave select function.

**CSI mode serial transfer timing (slave mode) (during communication at different potential)  
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (slave mode) (during communication at different potential)  
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



**Remark 1.** p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM and POM number (g = 0, 1, 3 to 5, 14)

**Remark 2.** CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

Also, communication at different potential cannot be performed during clock synchronous serial communication with the slave select function.

**(10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode)****(TA = -40 to +85°C, 1.8 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(1/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCLr clock frequency	fSCL	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 50 pF, Rb = 2.7 kΩ		1000 Note 1		300 Note 1		300 Note 1	kHz
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 50 pF, Rb = 2.7 kΩ		1000 Note 1		300 Note 1		300 Note 1	kHz
		4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 100 pF, Rb = 2.8 kΩ		400 Note 1		300 Note 1		300 Note 1	kHz
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 100 pF, Rb = 2.7 kΩ		400 Note 1		300 Note 1		300 Note 1	kHz
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 100 pF, Rb = 5.5 kΩ		300 Note 1		300 Note 1		300 Note 1	kHz
Hold time when SCLr = "L"	tLOW	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 50 pF, Rb = 2.7 kΩ	475		1550		1550		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 50 pF, Rb = 2.7 kΩ	475		1550		1550		ns
		4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 100 pF, Rb = 2.8 kΩ	1150		1550		1550		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 100 pF, Rb = 2.7 kΩ	1150		1550		1550		ns
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 100 pF, Rb = 5.5 kΩ	1550		1550		1550		ns
Hold time when SCLr = "H"	tHIGH	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 50 pF, Rb = 2.7 kΩ	245		610		610		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 50 pF, Rb = 2.7 kΩ	200		610		610		ns
		4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 100 pF, Rb = 2.8 kΩ	675		610		610		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 100 pF, Rb = 2.7 kΩ	600		610		610		ns
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 100 pF, Rb = 5.5 kΩ	610		610		610		ns

**(10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode)****(TA = -40 to +85°C, 1.8 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(2/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Data setup time (reception)	tsu:DAT	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 50 pF, Rb = 2.7 kΩ	1/fmck + 135 Note 3		1/fmck + 190 Note 3		1/fmck + 190 Note 3		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 50 pF, Rb = 2.7 kΩ	1/fmck + 135 Note 3		1/fmck + 190 Note 3		1/fmck + 190 Note 3		ns
		4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 100 pF, Rb = 2.8 kΩ	1/fmck + 190 Note 3		1/fmck + 190 Note 3		1/fmck + 190 Note 3		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 100 pF, Rb = 2.7 kΩ	1/fmck + 190 Note 3		1/fmck + 190 Note 3		1/fmck + 190 Note 3		ns
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 100 pF, Rb = 5.5 kΩ	1/fmck + 190 Note 3		1/fmck + 190 Note 3		1/fmck + 190 Note 3		ns
Data hold time (transmission)	thd:DAT	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 50 pF, Rb = 2.7 kΩ	0	305	0	305	0	305	ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 50 pF, Rb = 2.7 kΩ	0	305	0	305	0	305	ns
		4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 100 pF, Rb = 2.8 kΩ	0	355	0	355	0	355	ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 100 pF, Rb = 2.7 kΩ	0	355	0	355	0	355	ns
		1.8 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V Note 2, Cb = 100 pF, Rb = 5.5 kΩ	0	405	0	405	0	405	ns

**Note 1.** The value must also be equal to or less than fmck/4.

**Note 2.** Use it with EVDD0 ≥ Vb.

**Note 3.** Set the fmck value to keep the hold time of SCLr = "L" and SCLr = "H".

**Caution** Select the TTL input buffer and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the SDAr pin and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

**Simplified I<sup>2</sup>C mode connection diagram (during communication at different potential)**



**Simplified I<sup>2</sup>C mode serial transfer timing (during communication at different potential)**



**Remark 1.**  $R_b[\Omega]$ : Communication line (SDAr, SCLr) pull-up resistance,  $C_b[F]$ : Communication line (SDAr, SCLr) load capacitance,  $V_b[V]$ : Communication line voltage

**Remark 2.** r: IIC number (r = 00, 01, 10, 11, 20, 30, 31), g: PIM, POM number (g = 0, 1, 3 to 5, 14)

**Remark 3.**  $f_{MCK}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1),  
 n: Channel number (n = 0, 2), mn = 00, 01, 02, 10, 12, 13)

## 2.5.2 Serial interface IICA

### (1) I<sup>2</sup>C standard mode

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(1/2)

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit	
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
SCLA0 clock frequency	f <sub>SCL</sub>	Standard mode: f <sub>CLK</sub> ≥ 1 MHz	2.7 V ≤ EVDD0 ≤ 5.5 V	0	100	0	100	0	100	kHz
			1.8 V ≤ EVDD0 ≤ 5.5 V	0	100	0	100	0	100	kHz
			1.7 V ≤ EVDD0 ≤ 5.5 V	0	100	0	100	0	100	kHz
			1.6 V ≤ EVDD0 ≤ 5.5 V	—		0	100	0	100	kHz
Setup time of restart condition	t <sub>SU, STA</sub>	2.7 V ≤ EVDD0 ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.8 V ≤ EVDD0 ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.7 V ≤ EVDD0 ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.6 V ≤ EVDD0 ≤ 5.5 V	—		4.7		4.7		μs	
Hold time <sup>Note 1</sup>	t <sub>HD, STA</sub>	2.7 V ≤ EVDD0 ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.8 V ≤ EVDD0 ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.7 V ≤ EVDD0 ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.6 V ≤ EVDD0 ≤ 5.5 V	—		4.0		4.0		μs	
Hold time when SCLA0 = "L"	t <sub>LOW</sub>	2.7 V ≤ EVDD0 ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.8 V ≤ EVDD0 ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.7 V ≤ EVDD0 ≤ 5.5 V	4.7		4.7		4.7		μs	
		1.6 V ≤ EVDD0 ≤ 5.5 V	—		4.7		4.7		μs	
Hold time when SCLA0 = "H"	t <sub>HIGH</sub>	2.7 V ≤ EVDD0 ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.8 V ≤ EVDD0 ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.7 V ≤ EVDD0 ≤ 5.5 V	4.0		4.0		4.0		μs	
		1.6 V ≤ EVDD0 ≤ 5.5 V	—		4.0		4.0		μs	

(Notes, Caution, and Remark are listed on the next page.)

**(1) I<sup>2</sup>C standard mode****(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(2/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Data setup time (reception)	tsu: DAT	2.7 V ≤ EVDD0 ≤ 5.5 V	250		250		250		ns
		1.8 V ≤ EVDD0 ≤ 5.5 V	250		250		250		ns
		1.7 V ≤ EVDD0 ≤ 5.5 V	250		250		250		ns
		1.6 V ≤ EVDD0 ≤ 5.5 V	—		250		250		ns
Data hold time (transmission) Note 2	thd: DAT	2.7 V ≤ EVDD0 ≤ 5.5 V	0	3.45	0	3.45	0	3.45	μs
		1.8 V ≤ EVDD0 ≤ 5.5 V	0	3.45	0	3.45	0	3.45	μs
		1.7 V ≤ EVDD0 ≤ 5.5 V	0	3.45	0	3.45	0	3.45	μs
		1.6 V ≤ EVDD0 ≤ 5.5 V	—		0	3.45	0	3.45	μs
Setup time of stop condition	tsu: STO	2.7 V ≤ EVDD0 ≤ 5.5 V	4.0		4.0		4.0		μs
		1.8 V ≤ EVDD0 ≤ 5.5 V	4.0		4.0		4.0		μs
		1.7 V ≤ EVDD0 ≤ 5.5 V	4.0		4.0		4.0		μs
		1.6 V ≤ EVDD0 ≤ 5.5 V	—		4.0		4.0		μs
Bus-free time	tBUF	2.7 V ≤ EVDD0 ≤ 5.5 V	4.7		4.7		4.7		μs
		1.8 V ≤ EVDD0 ≤ 5.5 V	4.7		4.7		4.7		μs
		1.7 V ≤ EVDD0 ≤ 5.5 V	4.7		4.7		4.7		μs
		1.6 V ≤ EVDD0 ≤ 5.5 V	—		4.7		4.7		μs

**Note 1.** The first clock pulse is generated after this period when the start/restart condition is detected.

**Note 2.** The maximum value (MAX.) of thd: DAT is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.

**Caution** The values in the above table are applied even when bit 2 (PIOR02) in the peripheral I/O redirection register 0 (PIOR0) is 1. At this time, the pin characteristics (IOH1, IOL1, VOH1, VOL1) must satisfy the values in the redirect destination.

**Remark** The maximum value of C<sub>b</sub> (communication line capacitance) and the value of R<sub>b</sub> (communication line pull-up resistor) at that time in each mode are as follows.

Standard mode: C<sub>b</sub> = 400 pF, R<sub>b</sub> = 2.7 kΩ

(2) I<sup>2</sup>C fast mode

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit	
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
SCLA0 clock frequency	fSCL	Fast mode: fCLK ≥ 3.5 MHz	2.7 V ≤ EVDD0 ≤ 5.5 V	0	400	0	400	0	400	kHz
			1.8 V ≤ EVDD0 ≤ 5.5 V	0	400	0	400	0	400	kHz
Setup time of restart condition	tsu: STA	2.7 V ≤ EVDD0 ≤ 5.5 V	0.6		0.6		0.6		μs	
		1.8 V ≤ EVDD0 ≤ 5.5 V	0.6		0.6		0.6		μs	
Hold time <sup>Note 1</sup>	tHD: STA	2.7 V ≤ EVDD0 ≤ 5.5 V	0.6		0.6		0.6		μs	
		1.8 V ≤ EVDD0 ≤ 5.5 V	0.6		0.6		0.6		μs	
Hold time when SCLA0 = "L"	tLOW	2.7 V ≤ EVDD0 ≤ 5.5 V	1.3		1.3		1.3		μs	
		1.8 V ≤ EVDD0 ≤ 5.5 V	1.3		1.3		1.3		μs	
Hold time when SCLA0 = "H"	tHIGH	2.7 V ≤ EVDD0 ≤ 5.5 V	0.6		0.6		0.6		μs	
		1.8 V ≤ EVDD0 ≤ 5.5 V	0.6		0.6		0.6		μs	
Data setup time (reception)	tsu: DAT	2.7 V ≤ EVDD0 ≤ 5.5 V	100		100		100		ns	
		1.8 V ≤ EVDD0 ≤ 5.5 V	100		100		100		ns	
Data hold time (transmission) <sup>Note 2</sup>	tHD: DAT	2.7 V ≤ EVDD0 ≤ 5.5 V	0	0.9	0	0.9	0	0.9	μs	
		1.8 V ≤ EVDD0 ≤ 5.5 V	0	0.9	0	0.9	0	0.9	μs	
Setup time of stop condition	tsu: STO	2.7 V ≤ EVDD0 ≤ 5.5 V	0.6		0.6		0.6		μs	
		1.8 V ≤ EVDD0 ≤ 5.5 V	0.6		0.6		0.6		μs	
Bus-free time	tBUF	2.7 V ≤ EVDD0 ≤ 5.5 V	1.3		1.3		1.3		μs	
		1.8 V ≤ EVDD0 ≤ 5.5 V	1.3		1.3		1.3		μs	

**Note 1.** The first clock pulse is generated after this period when the start/restart condition is detected.

**Note 2.** The maximum value (MAX.) of tHD: DAT is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.

**Caution** The values in the above table are applied even when bit 2 (PIOR02) in the peripheral I/O redirection register 0 (PIOR0) is 1. At this time, the pin characteristics (IOH1, IOL1, VOH1, VOL1) must satisfy the values in the redirect destination.

**Remark** The maximum value of C<sub>b</sub> (communication line capacitance) and the value of R<sub>b</sub> (communication line pull-up resistor) at that time in each mode are as follows.

Fast mode: C<sub>b</sub> = 320 pF, R<sub>b</sub> = 1.1 kΩ



**(3) I<sup>2</sup>C fast mode plus**

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) mode		LS (low-speed main) mode		LV (low-voltage main) mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCLA0 clock frequency	fSCL	Fast mode plus: fCLK ≥ 10 MHz 2.7 V ≤ EVDD0 ≤ 5.5 V	0	1000	—	—	—	—	kHz
Setup time of restart condition	tSU: STA	2.7 V ≤ EVDD0 ≤ 5.5 V	0.26		—	—	—	—	μs
Hold time Note 1	tHD: STA	2.7 V ≤ EVDD0 ≤ 5.5 V	0.26		—	—	—	—	μs
Hold time when SCLA0 = "L"	tLOW	2.7 V ≤ EVDD0 ≤ 5.5 V	0.5		—	—	—	—	μs
Hold time when SCLA0 = "H"	tHIGH	2.7 V ≤ EVDD0 ≤ 5.5 V	0.26		—	—	—	—	μs
Data setup time (reception)	tSU: DAT	2.7 V ≤ EVDD0 ≤ 5.5 V	50		—	—	—	—	ns
Data hold time (transmission) Note 2	tHD: DAT	2.7 V ≤ EVDD0 ≤ 5.5 V	0	0.45	—	—	—	—	μs
Setup time of stop condition	tSU: STO	2.7 V ≤ EVDD0 ≤ 5.5 V	0.26		—	—	—	—	μs
Bus-free time	tBUF	2.7 V ≤ EVDD0 ≤ 5.5 V	0.5		—	—	—	—	μs

**Note 1.** The first clock pulse is generated after this period when the start/restart condition is detected.

**Note 2.** The maximum value (MAX.) of tHD: DAT is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.

**Caution** The values in the above table are applied even when bit 2 (PIOR02) in the peripheral I/O redirection register 0 (PIOR0) is 1. At this time, the pin characteristics (IOH1, IOL1, VOH1, VOL1) must satisfy the values in the redirect destination.

**Note 3.** The maximum value of C<sub>b</sub> (communication line capacitance) and the value of R<sub>b</sub> (communication line pull-up resistor) at that time in each mode are as follows.

Fast mode plus: C<sub>b</sub> = 120 pF, R<sub>b</sub> = 1.1 kΩ

**I<sup>2</sup>C serial transfer timing**



**Remark** n = 0, 1

## 2.6 Analog Characteristics

### 2.6.1 A/D converter characteristics

#### Classification of A/D converter characteristics

Input channel	Reference Voltage	Reference voltage (+) = AV <sub>REFP</sub> Reference voltage (-) = AV <sub>REFM</sub>	Reference voltage (+) = V <sub>DD</sub> Reference voltage (-) = V <sub>SS</sub>	Reference voltage (+) = V <sub>BGR</sub> Reference voltage (-) = AV <sub>REFM</sub>
ANI0 to ANI14		Refer to 2.6.1 (1).	Refer to 2.6.1 (3).	Refer to 2.6.1 (4).
ANI16 to ANI20		Refer to 2.6.1 (2).		
Internal reference voltage Temperature sensor output voltage		Refer to 2.6.1 (1).		

(1) When reference voltage (+) = AV<sub>REFP</sub>/ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AV<sub>REFM</sub>/ANI1 (ADREFM = 1), target pin: ANI2 to ANI14, internal reference voltage, and temperature sensor output voltage

(TA = -40 to +85°C, 1.6 V ≤ AV<sub>REFP</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V, Reference voltage (+) = AV<sub>REFP</sub>, Reference voltage (-) = AV<sub>REFM</sub> = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8		10	bit
Overall error Note 1	AINL	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> Note 3	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V	1.2	±3.5	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V Note 4	1.2	±7.0	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target pin: ANI2 to ANI14	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.125	39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.1875	39	μs
			1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	17	39	μs
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	57	95	μs
		10-bit resolution Target pin: Internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode)	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.375	39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.5625	39	μs
Zero-scale error Notes 1, 2	E <sub>ZS</sub>	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> Note 3	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±0.25	%FSR
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V Note 4		±0.50	%FSR
Full-scale error Notes 1, 2	E <sub>FS</sub>	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> Note 3	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±0.25	%FSR
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V Note 4		±0.50	%FSR
Integral linearity error Note 1	ILE	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> Note 3	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±2.5	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V Note 4		±5.0	LSB
Differential linearity error Note 1	DLE	10-bit resolution AV <sub>REFP</sub> = V <sub>DD</sub> Note 3	1.8 V ≤ AV <sub>REFP</sub> ≤ 5.5 V		±1.5	LSB
			1.6 V ≤ AV <sub>REFP</sub> ≤ 5.5 V Note 4		±2.0	LSB
Analog input voltage	V <sub>AIN</sub>	ANI2 to ANI14	0		AV <sub>REFP</sub>	V
		Internal reference voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)			V <sub>BGR</sub> Note 5	V
		Temperature sensor output voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)			V <sub>TMPS25</sub> Note 5	V

**Note 1.** Excludes quantization error (±1/2 LSB).

**Note 2.** This value is indicated as a ratio (%FSR) to the full-scale value.

**Note 3.** When AV<sub>REFP</sub> < V<sub>DD</sub>, the MAX. values are as follows.

Overall error: Add ±1.0 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Zero-scale error/Full-scale error: Add ±0.05%FSR to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

Integral linearity error/ Differential linearity error: Add ±0.5 LSB to the MAX. value when AV<sub>REFP</sub> = V<sub>DD</sub>.

**Note 4.** Values when the conversion time is set to 57 μs (min.) and 95 μs (max.).

**Note 5.** Refer to 2.6.2 Temperature sensor characteristics/internal reference voltage characteristic.

(2) When reference voltage (+) =  $AV_{REFP}/ANI0$  (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) =  $AV_{REFM}/ANI1$  (ADREFM = 1), target pin: ANI16 to ANI20

(TA = -40 to +85°C,  $1.6\text{ V} \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $1.6\text{ V} \leq AV_{REFP} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = EV_{SS0} = EV_{SS1} = 0\text{ V}$ , Reference voltage (+) =  $AV_{REFP}$ , Reference voltage (-) =  $AV_{REFM} = 0\text{ V}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Resolution	RES		8		10	bit	
Overall error Note 1	AINL	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4	$1.8\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$		1.2	±5.0	LSB
			$1.6\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ Note 5		1.2	±8.5	LSB
Conversion time	tCONV	10-bit resolution Target ANI pin: ANI16 to ANI20	$3.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	2.125		39	μs
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	3.1875		39	μs
			$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	17		39	μs
			$1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	57		95	μs
Zero-scale error Notes 1, 2	EzS	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4	$1.8\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$			±0.35	%FSR
			$1.6\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ Note 5			±0.60	%FSR
Full-scale error Notes 1, 2	EFS	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4	$1.8\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$			±0.35	%FSR
			$1.6\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ Note 5			±0.60	%FSR
Integral linearity error Note 1	ILE	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4	$1.8\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$			±3.5	LSB
			$1.6\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ Note 5			±6.0	LSB
Differential linearity error Note 1	DLE	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4	$1.8\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$			±2.0	LSB
			$1.6\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$ Note 5			±2.5	LSB
Analog input voltage	VAIN	ANI16 to ANI20	0		$AV_{REFP}$ and $EV_{DD0}$	V	

**Note 1.** Excludes quantization error ( $\pm 1/2$  LSB).

**Note 2.** This value is indicated as a ratio (%FSR) to the full-scale value.

**Note 3.** When  $EV_{DD0} \leq AV_{REFP} \leq V_{DD}$ , the MAX. values are as follows.

Overall error: Add  $\pm 1.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .

Zero-scale error/Full-scale error: Add  $\pm 0.05\%$ FSR to the MAX. value when  $AV_{REFP} = V_{DD}$ .

Integral linearity error/ Differential linearity error: Add  $\pm 0.5$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .

**Note 4.** When  $AV_{REFP} < EV_{DD0} \leq V_{DD}$ , the MAX. values are as follows.

Overall error: Add  $\pm 4.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .

Zero-scale error/Full-scale error: Add  $\pm 0.20\%$ FSR to the MAX. value when  $AV_{REFP} = V_{DD}$ .

Integral linearity error/ Differential linearity error: Add  $\pm 2.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .

**Note 5.** When the conversion time is set to 57 μs (min.) and 95 μs (max.).

- (3) When reference voltage (+) = V<sub>DD</sub> (ADREFP1 = 0, ADREFP0 = 0), reference voltage (-) = V<sub>SS</sub> (ADREFM = 0), target pin: ANI0 to ANI14, ANI16 to ANI20, internal reference voltage, and temperature sensor output voltage

(TA = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V, Reference voltage (+) = V<sub>DD</sub>, Reference voltage (-) = V<sub>SS</sub>)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Resolution	RES		8		10	bit	
Overall error Note 1	AINL	10-bit resolution	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V		1.2	±7.0	LSB
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V Note 3		1.2	±10.5	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target pin: ANI0 to ANI14, ANI16 to ANI20	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.125		39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.1875		39	μs
			1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V	17		39	μs
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	57		95	μs
		10-bit resolution Target pin: internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode)	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.375		39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.5625		39	μs
2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17			39	μs		
Zero-scale error Notes 1, 2	E <sub>ZS</sub>	10-bit resolution	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V			±0.60	%FSR
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V Note 3			±0.85	%FSR
Full-scale error Notes 1, 2	E <sub>FS</sub>	10-bit resolution	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V			±0.60	%FSR
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V Note 3			±0.85	%FSR
Integral linearity error Note 1	ILE	10-bit resolution	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V			±4.0	LSB
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V Note 3			±6.5	LSB
Differential linearity error Note 1	DLE	10-bit resolution	1.8 V ≤ V <sub>DD</sub> ≤ 5.5 V			±2.0	LSB
			1.6 V ≤ V <sub>DD</sub> ≤ 5.5 V Note 3			±2.5	LSB
Analog input voltage	V <sub>AIN</sub>	ANI0 to ANI14	0		V <sub>DD</sub>	V	
		ANI16 to ANI20	0		EV <sub>DD0</sub>	V	
		Internal reference voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)			V <sub>BGR</sub> Note 4	V	
		Temperature sensor output voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)			V <sub>TMPS25</sub> Note 4	V	

**Note 1.** Excludes quantization error (±1/2 LSB).

**Note 2.** This value is indicated as a ratio (% FSR) to the full-scale value.

**Note 3.** When the conversion time is set to 57 μs (min.) and 95 μs (max.).

**Note 4.** Refer to 2.6.2 Temperature sensor characteristics/internal reference voltage characteristic.

(4) When reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), reference voltage (-) = AVREFM/ANI1 (ADREFM = 1), target pin: ANI0, ANI2 to ANI14, ANI16 to ANI20

(TA = -40 to +85°C, 2.4 V ≤ VDD ≤ 5.5 V, 1.6 V ≤ EVDD = EVDD1 ≤ VDD, VSS = EVSS0 = EVSS1 = 0 V, Reference voltage (+) = VBGR <sup>Note 3</sup>, Reference voltage (-) = AVREFM = 0 V <sup>Note 4</sup>, HS (high-speed main) mode)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8			bit
Conversion time	tCONV	8-bit resolution	2.4 V ≤ VDD ≤ 5.5 V	17		39	μs
Zero-scale error <sup>Notes 1, 2</sup>	Ezs	8-bit resolution	2.4 V ≤ VDD ≤ 5.5 V			±0.60	% FSR
Integral linearity error <sup>Note 1</sup>	ILE	8-bit resolution	2.4 V ≤ VDD ≤ 5.5 V			±2.0	LSB
Differential linearity error <sup>Note 1</sup>	DLE	8-bit resolution	2.4 V ≤ VDD ≤ 5.5 V			±1.0	LSB
Analog input voltage	VAIN			0		VBGR <sup>Note 3</sup>	V

**Note 1.** Excludes quantization error (±1/2 LSB).

**Note 2.** This value is indicated as a ratio (% FSR) to the full-scale value.

**Note 3.** Refer to **2.6.2 Temperature sensor characteristics/internal reference voltage characteristic**.

**Note 4.** When reference voltage (-) = VSS, the MAX. values are as follows.

Zero-scale error: Add ±0.35%FSR to the MAX. value when reference voltage (-) = AVREFM.

Integral linearity error: Add ±0.5 LSB to the MAX. value when reference voltage (-) = AVREFM.

Differential linearity error: Add ±0.2 LSB to the MAX. value when reference voltage (-) = AVREFM.

## 2.6.2 Temperature sensor characteristics/internal reference voltage characteristic

(TA = -40 to +85°C, 2.4 V ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V, HS (high-speed main) mode)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Temperature sensor output voltage	VTMPS25	Setting ADS register = 80H, TA = +25°C		1.05		V
Internal reference voltage	VBGR	Setting ADS register = 81H	1.38	1.45	1.5	V
Temperature coefficient	FVTMPS	Temperature sensor that depends on the temperature		-3.6		mV/°C
Operation stabilization wait time	tAMP		5			μs

## 2.6.3 D/A converter characteristics

(TA = -40 to +85°C, 1.6 V ≤ EVSS0 = EVSS1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES					8	bit
Overall error	AINL	Rload = 4 MΩ	1.8 V ≤ VDD ≤ 5.5 V			±2.5	LSB
		Rload = 8 MΩ	1.8 V ≤ VDD ≤ 5.5 V			±2.5	LSB
Settling time	tSET	Cload = 20 pF	2.7 V ≤ VDD ≤ 5.5 V			3	μs
			1.6 V ≤ VDD < 2.7 V			6	μs

## 2.6.4 Comparator

(TA = -40 to +85°C, 1.6 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input voltage range	Ivref		0		EVDD0 - 1.4	V
	Ivcmp		-0.3		EVDD0 + 0.3	V
Output delay	td	VDD = 3.0 V Input slew rate > 50 mV/μs	Comparator high-speed mode, standard mode		1.2	μs
			Comparator high-speed mode, window mode		2.0	μs
			Comparator low-speed mode, standard mode	3.0	5.0	μs
High-electric-potential reference voltage	VTW+	Comparator high-speed mode, window mode		0.76 VDD		V
Low-electric-potential reference voltage	VTW-	Comparator high-speed mode, window mode		0.24 VDD		V
Operation stabilization wait time	tcMP		100			μs
Internal reference voltage Note	VBGR	2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed main) mode	1.38	1.45	1.50	V

**Note** Not usable in LS (low-speed main) mode, LV (low-voltage main) mode, sub-clock operation, or STOP mode.

## 2.6.5 POR circuit characteristics

(TA = -40 to +85°C, VSS = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power on/down reset threshold	VPOR	Voltage threshold on VDD rising	1.47	1.51	1.55	V
	VPDR	Voltage threshold on VDD falling Note 1	1.46	1.50	1.54	V
Minimum pulse width Note 2	TPW		300			μs

**Note 1.** However, when the operating voltage falls while the LVD is off, enter STOP mode, or enable the reset status using the external reset pin before the voltage falls below the operating voltage range shown in 2.4 AC Characteristics.

**Note 2.** Minimum time required for a POR reset when VDD exceeds below VPDR. This is also the minimum time required for a POR reset from when VDD exceeds below 0.7 V to when VDD exceeds VPOR while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



## 2.6.6 LVD circuit characteristics

### (1) Reset Mode and Interrupt Mode

(TA = -40 to +85°C, VPDR ≤ VDD ≤ 5.5 V, VSS = 0 V)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Voltage detection threshold	Supply voltage level	VLVD0	Rising edge	3.98	4.06	4.14	V
			Falling edge	3.90	3.98	4.06	V
		VLVD1	Rising edge	3.68	3.75	3.82	V
			Falling edge	3.60	3.67	3.74	V
		VLVD2	Rising edge	3.07	3.13	3.19	V
			Falling edge	3.00	3.06	3.12	V
		VLVD3	Rising edge	2.96	3.02	3.08	V
			Falling edge	2.90	2.96	3.02	V
		VLVD4	Rising edge	2.86	2.92	2.97	V
			Falling edge	2.80	2.86	2.91	V
		VLVD5	Rising edge	2.76	2.81	2.87	V
			Falling edge	2.70	2.75	2.81	V
		VLVD6	Rising edge	2.66	2.71	2.76	V
			Falling edge	2.60	2.65	2.70	V
		VLVD7	Rising edge	2.56	2.61	2.66	V
			Falling edge	2.50	2.55	2.60	V
		VLVD8	Rising edge	2.45	2.50	2.55	V
			Falling edge	2.40	2.45	2.50	V
		VLVD9	Rising edge	2.05	2.09	2.13	V
			Falling edge	2.00	2.04	2.08	V
		VLVD10	Rising edge	1.94	1.98	2.02	V
			Falling edge	1.90	1.94	1.98	V
		VLVD11	Rising edge	1.84	1.88	1.91	V
			Falling edge	1.80	1.84	1.87	V
		VLVD12	Rising edge	1.74	1.77	1.81	V
			Falling edge	1.70	1.73	1.77	V
VLVD13	Rising edge	1.64	1.67	1.70	V		
	Falling edge	1.60	1.63	1.66	V		
Minimum pulse width		tLW		300			μs
Detection delay time						300	μs



**(2) Interrupt & Reset Mode****(TA = -40 to +85°C, VPDR ≤ VDD ≤ 5.5 V, VSS = 0 V)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Voltage detection threshold	VLVDA0	VPOC2, VPOC1, VPOC0 = 0, 0, 0, falling reset voltage	1.60	1.63	1.66	V	
	VLVDA1	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	1.74	1.77	1.81	V
			Falling interrupt voltage	1.70	1.73	1.77	V
	VLVDA2	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	1.84	1.88	1.91	V
			Falling interrupt voltage	1.80	1.84	1.87	V
	VLVDA3	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	2.86	2.92	2.97	V
			Falling interrupt voltage	2.80	2.86	2.91	V
	VLVDB0	VPOC2, VPOC1, VPOC0 = 0, 0, 1, falling reset voltage	1.80	1.84	1.87	V	
	VLVDB1	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	1.94	1.98	2.02	V
			Falling interrupt voltage	1.90	1.94	1.98	V
	VLVDB2	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.05	2.09	2.13	V
			Falling interrupt voltage	2.00	2.04	2.08	V
VLVDB3	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.07	3.13	3.19	V	
		Falling interrupt voltage	3.00	3.06	3.12	V	
VLVDC0	VPOC2, VPOC1, VPOC0 = 0, 1, 0, falling reset voltage	2.40	2.45	2.50	V		
VLVDC1	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	2.56	2.61	2.66	V	
		Falling interrupt voltage	2.50	2.55	2.60	V	
VLVDC2	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.66	2.71	2.76	V	
		Falling interrupt voltage	2.60	2.65	2.70	V	
VLVDC3	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.68	3.75	3.82	V	
		Falling interrupt voltage	3.60	3.67	3.74	V	
VLVDD0	VPOC2, VPOC1, VPOC0 = 0, 1, 1, falling reset voltage	2.70	2.75	2.81	V		
VLVDD1	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	2.86	2.92	2.97	V	
		Falling interrupt voltage	2.80	2.86	2.91	V	
VLVDD2	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.96	3.02	3.08	V	
		Falling interrupt voltage	2.90	2.96	3.02	V	
VLVDD3	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.98	4.06	4.14	V	
		Falling interrupt voltage	3.90	3.98	4.06	V	

**2.6.7 Power supply voltage rising slope characteristics****(TA = -40 to +85°C, VSS = 0 V)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	SVDD				54	V/ms

**Caution** Make sure to keep the internal reset state by the LVD circuit or an external reset until VDD reaches the operating voltage range shown in 2.4 AC Characteristics.

## 2.7 RAM Data Retention Characteristics

(TA = -40 to +85°C, VSS = 0V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	VDDDR		1.46 Note		5.5	V

**Note** The value depends on the POR detection voltage. When the voltage drops, the RAM data is retained before a POR reset is effected, but RAM data is not retained when a POR reset is effected.



## 2.8 Flash Memory Programming Characteristics

(TA = -40 to +85°C, 1.8 V ≤ VDD ≤ 5.5 V, VSS = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
System clock frequency	fCLK	1.8 V ≤ VDD ≤ 5.5 V	1		32	MHz
Number of code flash rewrites Notes 1, 2, 3	C <sub>erwr</sub>	Retained for 20 years TA = 85°C	1,000			Times
Number of data flash rewrites Notes 1, 2, 3		Retained for 1 year TA = 25°C		1,000,000		
		Retained for 5 years TA = 85°C	100,000			
		Retained for 20 years TA = 85°C	10,000			

**Note 1.** 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.

**Note 2.** When using flash memory programmer and Renesas Electronics self-programming library

**Note 3.** These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

## 2.9 Dedicated Flash Memory Programmer Communication (UART)

(TA = -40 to +85°C, 1.8 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During serial programming	115,200		1,000,000	bps

## 2.10 Timing of Entry to Flash Memory Programming Modes

(TA = -40 to +85°C, 1.8 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
How long from when an external reset ends until the initial communication settings are specified	tsuINIT	POR and LVD reset must end before the external reset ends.			100	ms
How long from when the TOOL0 pin is placed at the low level until an external reset ends	tsu	POR and LVD reset must end before the external reset ends.	10			μs
How long the TOOL0 pin must be kept at the low level after an external reset ends (excluding the processing time of the firmware to control the flash memory)	tHD	POR and LVD reset must end before the external reset ends.	1			ms



- <1> The low level is input to the TOOL0 pin.
- <2> The external reset ends (POR and LVD reset must end before the external reset ends).
- <3> The TOOL0 pin is set to the high level.
- <4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

**Remark** tsuINIT: The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the external resets end.

tsu: How long from when the TOOL0 pin is placed at the low level until a pin reset ends

tHD: How long to keep the TOOL0 pin at the low level from when the external resets end (excluding the processing time of the firmware to control the flash memory)

### 3. ELECTRICAL SPECIFICATIONS (G: INDUSTRIAL APPLICATIONS $T_A = -40$ to $+105^\circ\text{C}$ )

This chapter describes the following electrical specifications.

Target products G: Industrial applications  $T_A = -40$  to  $+105^\circ\text{C}$

R5F104xxGxx

**Caution 1.** The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.

**Caution 2.** With products not provided with an EVDD0, EVDD1, EVSS0, or EVSS1 pin, replace EVDD0 and EVDD1 with VDD, or replace EVSS0 and EVSS1 with VSS.

**Caution 3.** The pins mounted depend on the product. Refer to 2.1 Port Functions to 2.2.1 Functions for each product in the RL78/G14 User's Manual.

**Caution 4.** Please contact Renesas Electronics sales office for derating of operation under  $T_A = +85$  to  $+105^\circ\text{C}$ . Derating is the systematic reduction of load for the sake of improved reliability.

**Remark** When RL78/G14 is used in the range of  $T_A = -40$  to  $+85^\circ\text{C}$ , see 2. ELECTRICAL SPECIFICATIONS ( $T_A = -40$  to  $+85^\circ\text{C}$ ).

Operation of products rated “G: Industrial applications (TA = -40 to + 105°C)” at ambient operating temperatures above 85°C differs from that of products rated “A: Consumer applications” and “D: Industrial applications” in the ways listed below.

Parameter	A: Consumer applications, D: Industrial applications	G: Industrial applications
Operating ambient temperature	TA = -40 to +85°C	TA = -40 to +105°C
Operating mode Operating voltage range	HS (high-speed main) mode: 2.7 V ≤ VDD ≤ 5.5 V@1 MHz to 32 MHz 2.4 V ≤ VDD ≤ 5.5 V@1 MHz to 16 MHz LS (low-speed main) mode: 1.8 V ≤ VDD ≤ 5.5 V@1 MHz to 8 MHz LV (low-voltage main) mode: 1.6 V ≤ VDD ≤ 5.5 V@1 MHz to 4 MHz	HS (high-speed main) mode only: 2.7 V ≤ VDD ≤ 5.5 V@1 MHz to 32 MHz 2.4 V ≤ VDD ≤ 5.5 V@1 MHz to 16 MHz
High-speed on-chip oscillator clock accuracy	1.8 V ≤ VDD ≤ 5.5 V: ±1.0% @ TA = -20 to +85°C ±1.5% @ TA = -40 to -20°C 1.6 V ≤ VDD < 1.8 V: ±5.0% @ TA = -20 to +85°C ±5.5% @ TA = -40 to -20°C	2.4 V ≤ VDD ≤ 5.5 V: ±2.0% @ TA = +85 to +105°C ±1.0% @ TA = -20 to +85°C ±1.5% @ TA = -40 to -20°C
Serial array unit	UART CSI: fCLK/2 (16 Mbps supported), fCLK/4 Simplified I <sup>2</sup> C communication	UART CSI: fCLK/4 Simplified I <sup>2</sup> C communication
IICA	Standard mode Fast mode Fast mode plus	Standard mode Fast mode
Voltage detector	<ul style="list-style-type: none"> <li>Rising: 1.67 V to 4.06 V (14 stages)</li> <li>Falling: 1.63 V to 3.98 V (14 stages)</li> </ul>	<ul style="list-style-type: none"> <li>Rising: 2.61 V to 4.06 V (8 stages)</li> <li>Falling: 2.55 V to 3.98 V (8 stages)</li> </ul>

**Remark** The electrical characteristics of products rated “G: Industrial applications (TA = -40 to + 105°C)” at ambient operating temperatures above 85°C differ from those of products rated “A: Consumer applications” and “D: Industrial applications”. For details, refer to 3.1 to 3.10.

### 3.1 Absolute Maximum Ratings

#### Absolute Maximum Ratings

(1/2)

Parameter	Symbols	Conditions	Ratings	Unit
Supply voltage	V <sub>DD</sub>		-0.5 to +6.5	V
	EV <sub>DD0</sub> , EV <sub>DD1</sub>	EV <sub>DD0</sub> = EV <sub>DD1</sub>	-0.5 to +6.5	V
	EV <sub>SS0</sub> , EV <sub>SS1</sub>	EV <sub>SS0</sub> = EV <sub>SS1</sub>	-0.5 to +0.3	V
REGC pin input voltage	V <sub>IREGC</sub>	REGC	-0.3 to +2.8 and -0.3 to V <sub>DD</sub> +0.3 Note 1	V
Input voltage	V <sub>I1</sub>	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147	-0.3 to EV <sub>DD0</sub> +0.3 and -0.3 to V <sub>DD</sub> +0.3 Note 2	V
	V <sub>I2</sub>	P60 to P63 (N-ch open-drain)	-0.3 to +6.5	V
	V <sub>I3</sub>	P20 to P27, P121 to P124, P137, P150 to P156, EXCLK, EXCLKS, $\overline{\text{RESET}}$	-0.3 to V <sub>DD</sub> +0.3 Note 2	V
Output voltage	V <sub>O1</sub>	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147	-0.3 to EV <sub>DD0</sub> +0.3 and -0.3 to V <sub>DD</sub> +0.3 Note 2	V
	V <sub>O2</sub>	P20 to P27, P150 to P156	-0.3 to V <sub>DD</sub> +0.3 Note 2	V
Analog input voltage	V <sub>AI1</sub>	ANI16 to ANI20	-0.3 to EV <sub>DD0</sub> +0.3 and -0.3 to AV <sub>REF</sub> (+) +0.3 Notes 2, 3	V
	V <sub>AI2</sub>	ANI0 to ANI14	-0.3 to V <sub>DD</sub> +0.3 and -0.3 to AV <sub>REF</sub> (+) +0.3 Notes 2, 3	V

**Note 1.** Connect the REGC pin to V<sub>SS</sub> via a capacitor (0.47 to 1 μF). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.

**Note 2.** Must be 6.5 V or lower.

**Note 3.** Do not exceed AV<sub>REF</sub> (+) + 0.3 V in case of A/D conversion target pin.

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remark 1.** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

**Remark 2.** AV<sub>REF</sub> (+): + side reference voltage of the A/D converter.

**Remark 3.** V<sub>SS</sub>: Reference voltage

**Absolute Maximum Ratings****(2/2)**

Parameter	Symbols	Conditions		Ratings	Unit
Output current, high	IOH1	Per pin	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147	-40	mA
		Total of all pins -170 mA	P00 to P04, P40 to P47, P102, P120, P130, P140 to P145	-70	mA
			P05, P06, P10 to P17, P30, P31, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100, P101, P110, P111, P146, P147	-100	mA
	IOH2	Per pin	P20 to P27, P150 to P156	-0.5	mA
		Total of all pins		-2	mA
	Output current, low	IOL1	Per pin	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147	40
Total of all pins 170 mA			P00 to P04, P40 to P47, P102, P120, P130, P140 to P145	70	mA
			P05, P06, P10 to P17, P30, P31, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P100, P101, P110, P111, P146, P147	100	mA
IOL2		Per pin	P20 to P27, P150 to P156	1	mA
		Total of all pins		5	mA
Operating ambient temperature		TA	In normal operation mode		-40 to +105
	In flash memory programming mode				
Storage temperature	Tstg			-65 to +150	°C

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## 3.2 Oscillator Characteristics

### 3.2.1 X1, XT1 characteristics

(TA = -40 to +105°C, 2.4 V ≤ VDD ≤ 5.5 V, VSS = 0 V)

Resonator	Resonator	Conditions	MIN.	TYP.	MAX.	Unit
X1 clock oscillation frequency (fX) <sup>Note</sup>	Ceramic resonator/ crystal resonator	2.7 V ≤ VDD ≤ 5.5 V	1.0		20.0	MHz
		2.4 V ≤ VDD < 2.7 V	1.0		16.0	
XT1 clock oscillation frequency (fXT) <sup>Note</sup>	Crystal resonator		32	32.768	35	kHz

**Note** Indicates only permissible oscillator frequency ranges. Refer to **AC Characteristics** for instruction execution time. Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

**Caution** Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.

**Remark** When using the X1 oscillator and XT1 oscillator, refer to **5.4 System Clock Oscillator** in the RL78/G14 User's Manual.

### 3.2.2 On-chip oscillator characteristics

(TA = -40 to +105°C, 2.4 V ≤ VDD ≤ 5.5 V, VSS = 0 V)

Oscillators	Parameters	Conditions		MIN.	TYP.	MAX.	Unit
High-speed on-chip oscillator clock frequency Notes 1, 2	f <sub>H</sub>			1		32	MHz
High-speed on-chip oscillator clock frequency accuracy		-20 to +85°C	2.4 V ≤ VDD ≤ 5.5 V	-1.0		+1.0	%
		-40 to -20°C	2.4 V ≤ VDD ≤ 5.5 V	-1.5		+1.5	%
		+85 to +105°C	2.4 V ≤ VDD ≤ 5.5 V	-2.0		+2.0	%
Low-speed on-chip oscillator clock frequency	f <sub>L</sub>				15		kHz
Low-speed on-chip oscillator clock frequency accuracy				-15		+15	%

**Note 1.** High-speed on-chip oscillator frequency is selected with bits 0 to 4 of the option byte (000C2H) and bits 0 to 2 of the HOCODIV register.

**Note 2.** This only indicates the oscillator characteristics. Refer to **AC Characteristics** for instruction execution time.



### 3.3 DC Characteristics

#### 3.3.1 Pin characteristics

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(1/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Output current, high <sup>Note 1</sup>	IOH1	Per pin for P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147	2.4 V ≤ EVDD0 ≤ 5.5 V			-3.0 Note 2	mA
		Total of P00 to P04, P40 to P47, P102, P120, P130, P140 to P145 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EVDD0 ≤ 5.5 V			-30.0	mA
			2.7 V ≤ EVDD0 < 4.0 V			-10.0	mA
			2.4 V ≤ EVDD0 < 2.7 V			-5.0	mA
		Total of P05, P06, P10 to P17, P30, P31, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100, P101, P110, P111, P146, P147 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EVDD0 ≤ 5.5 V			-30.0	mA
			2.7 V ≤ EVDD0 < 4.0 V			-19.0	mA
	2.4 V ≤ EVDD0 < 2.7 V				-10.0	mA	
	Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )	2.4 V ≤ EVDD0 ≤ 5.5 V			-60.0	mA	
	IOH2	Per pin for P20 to P27, P150 to P156	2.4 V ≤ VDD ≤ 5.5 V			-0.1 Note 2	mA
		Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )	2.4 V ≤ VDD ≤ 5.5 V			-1.5	mA

**Note 1.** Value of current at which the device operation is guaranteed even if the current flows from the EVDD0, EVDD1, VDD pins to an output pin.

**Note 2.** Do not exceed the total current value.

**Note 3.** Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (IOH × 0.7)/(n × 0.01)  
<Example> Where n = 80% and IOH = -10.0 mA  
Total output current of pins = (-10.0 × 0.7)/(80 × 0.01) ≈ -8.7 mA

However, the current that is allowed to flow into one pin does not vary depending on the duty factor.  
A current higher than the absolute maximum rating must not flow into one pin.

**Caution** P00, P02 to P04, P10, P11, P13 to P15, P17, P30, P43 to P45, P50 to P55, P71, P74, P80 to P82, and P142 to P144 do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(2/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output current, low <sup>Note 1</sup>	IOL1	Per pin for P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147			8.5 Note 2	mA
					15.0 Note 2	mA
					40.0	mA
		Total of P00 to P04, P40 to P47, P102, P120, P130, P140 to P145 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EVDD0 ≤ 5.5 V		40.0	mA
			2.7 V ≤ EVDD0 < 4.0 V		15.0	mA
			2.4 V ≤ EVDD0 < 2.7 V		9.0	mA
		Total of P05, P06, P10 to P17, P30, P31, P50 to P57, P60 to P67, P70 to P77, P80 to P87, P100, P101, P110, P111, P146, P147 (When duty ≤ 70% <sup>Note 3</sup> )	4.0 V ≤ EVDD0 ≤ 5.5 V		40.0	mA
	2.7 V ≤ EVDD0 < 4.0 V			35.0	mA	
	2.4 V ≤ EVDD0 < 2.7 V			20.0	mA	
	Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )			80.0	mA	
IOL2	Per pin for P20 to P27, P150 to P156			0.4 Note 2	mA	
		2.4 V ≤ VDD ≤ 5.5 V		5.0	mA	

**Note 1.** Value of current at which the device operation is guaranteed even if the current flows from an output pin to the EVSS0, EVSS1, and VSS pins.

**Note 2.** Do not exceed the total current value.

**Note 3.** Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (IOL × 0.7)/(n × 0.01)

<Example> Where n = 80% and IOL = 10.0 mA

$$\text{Total output current of pins} = (10.0 \times 0.7)/(80 \times 0.01) \approx 8.7 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor.

A current higher than the absolute maximum rating must not flow into one pin.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(3/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input voltage, high	VIH1	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147	Normal input buffer	0.8 EVDD0		EVDD0	V
			TTL input buffer 4.0 V ≤ EVDD0 ≤ 5.5 V	2.2		EVDD0	V
				TTL input buffer 3.3 V ≤ EVDD0 < 4.0 V	2.0		EVDD0
	VIH2	P01, P03, P04, P10, P14 to P17, P30, P43, P44, P50, P53 to P55, P80, P81, P142, P143	TTL input buffer 2.4 V ≤ EVDD0 < 3.3 V	1.5		EVDD0	V
			VIH3	P20 to P27, P150 to P156	0.7 VDD		VDD
	VIH4	P60 to P63	0.7 EVDD0		6.0		V
VIH5	P121 to P124, P137, EXCLK, EXCLKS, RESET	0.8 VDD		VDD		V	
Input voltage, low	VIL1	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147	Normal input buffer	0		0.2 EVDD0	V
			TTL input buffer 4.0 V ≤ EVDD0 ≤ 5.5 V	0		0.8	V
				TTL input buffer 3.3 V ≤ EVDD0 < 4.0 V	0		0.5
	VIL2	P01, P03, P04, P10, P14 to P17, P30, P43, P44, P50, P53 to P55, P80, P81, P142, P143	TTL input buffer 2.4 V ≤ EVDD0 < 3.3 V	0		0.32	V
			VIL3	P20 to P27, P150 to P156	0		0.3 VDD
	VIL4	P60 to P63	0		0.3 EVDD0		V
VIL5	P121 to P124, P137, EXCLK, EXCLKS, RESET	0		0.2 VDD		V	

**Caution** The maximum value of VIH of pins P00, P02 to P04, P10, P11, P13 to P15, P17, P30, P43 to P45, P50 to P55, P71, P74, P80 to P82, and P142 to P144 is EVDD0, even in the N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(4/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output voltage, high	VOH1	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147	4.0 V ≤ EVDD0 ≤ 5.5 V, IOH1 = -3.0 mA			V
			2.7 V ≤ EVDD0 ≤ 5.5 V, IOH1 = -2.0 mA			V
			2.4 V ≤ EVDD0 ≤ 5.5 V, IOH1 = -1.5 mA			V
	VOH2	P20 to P27, P150 to P156	2.4 V ≤ VDD ≤ 5.5 V, IOH2 = -100 μA			V
Output voltage, low	VOL1	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P130, P140 to P147	4.0 V ≤ EVDD0 ≤ 5.5 V, IOL1 = 8.5 mA		0.7	V
			2.7 V ≤ EVDD0 ≤ 5.5 V, IOL1 = 3.0 mA		0.6	V
			2.7 V ≤ EVDD0 ≤ 5.5 V, IOL1 = 1.5 mA		0.4	V
			2.4 V ≤ EVDD0 ≤ 5.5 V, IOL1 = 0.6 mA		0.4	V
	VOL2	P20 to P27, P150 to P156	2.4 V ≤ VDD ≤ 5.5 V, IOL2 = 400 μA		0.4	V
	VOL3	P60 to P63	4.0 V ≤ EVDD0 ≤ 5.5 V, IOL3 = 15.0 mA		2.0	V
			4.0 V ≤ EVDD0 ≤ 5.5 V, IOL3 = 5.0 mA		0.4	V
			2.7 V ≤ EVDD0 ≤ 5.5 V, IOL3 = 3.0 mA		0.4	V
			2.4 V ≤ EVDD0 ≤ 5.5 V, IOL3 = 2.0 mA		0.4	V

**Caution** P00, P02 to P04, P10, P11, P13 to P15, P17, P30, P43 to P45, P50 to P55, P71, P74, P80 to P82, P142 to P144 do not output high level in N-ch open-drain mode.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(5/5)

Items	Symbol	Conditions	MIN.	TYP.	MAX.	Unit		
Input leakage current, high	ILIH1	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147	Vi = EVDD0			1	μA	
	ILIH2	P20 to P27, P137, P150 to P156, RESET	Vi = VDD			1	μA	
	ILIH3	P121 to P124 (X1, X2, EXCLK, XT1, XT2, EXCLKS)	Vi = VDD	In input port or external clock input			1	μA
				In resonator connection			10	μA
Input leakage current, low	ILIL1	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147	Vi = EVSS0			-1	μA	
	ILIL2	P20 to P27, P137, P150 to P156, RESET	Vi = VSS			-1	μA	
	ILIL3	P121 to P124 (X1, X2, EXCLK, XT1, XT2, EXCLKS)	Vi = VSS	In input port or external clock input			-1	μA
				In resonator connection			-10	μA
On-chip pull-up resistance	Ru	P00 to P06, P10 to P17, P30, P31, P40 to P47, P50 to P57, P64 to P67, P70 to P77, P80 to P87, P100 to P102, P110, P111, P120, P140 to P147	Vi = EVSS0, In input port		10	20	100	kΩ

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

### 3.3.2 Supply current characteristics

#### (1) Flash ROM: 16 to 64 KB of 30- to 64-pin products

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = 0 V)

(1/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit		
Supply current Note 1	IDD1	Operating mode	HS (high-speed main) mode Note 5	fHOCO = 64 MHz, fIH = 32 MHz Note 3	Basic operation	VDD = 5.0 V		2.4		mA	
						VDD = 3.0 V		2.4			
					fHOCO = 32 MHz, fIH = 32 MHz Note 3	Basic operation	VDD = 5.0 V		2.1		
					VDD = 3.0 V			2.1			
				HS (high-speed main) mode Note 5	fHOCO = 64 MHz, fIH = 32 MHz Note 3	Normal operation	VDD = 5.0 V		5.1		9.3
							VDD = 3.0 V		5.1		9.3
					fHOCO = 32 MHz, fIH = 32 MHz Note 3	Normal operation	VDD = 5.0 V		4.8	8.7	
					VDD = 3.0 V			4.8	8.7		
					fHOCO = 48 MHz, fIH = 24 MHz Note 3	Normal operation	VDD = 5.0 V		4.0	7.3	
					VDD = 3.0 V			4.0	7.3		
				fHOCO = 24 MHz, fIH = 24 MHz Note 3	Normal operation	VDD = 5.0 V		3.8	6.7		
				VDD = 3.0 V			3.8	6.7			
			fHOCO = 16 MHz, fIH = 16 MHz Note 3	Normal operation	VDD = 5.0 V		2.8	4.9			
			VDD = 3.0 V			2.8	4.9				
		HS (high-speed main) mode Note 5	fMX = 20 MHz Note 2, VDD = 5.0 V	Normal operation	Square wave input		3.3	5.7			
					Resonator connection		3.4	5.8			
				Normal operation	Square wave input		3.3	5.7			
					Resonator connection		3.4	5.8			
				Normal operation	Square wave input		2.0	3.4			
					Resonator connection		2.1	3.5			
				Normal operation	Square wave input		2.0	3.4			
Resonator connection					2.1	3.5					
Subsystem clock operation	fsUB = 32.768 kHz Note 4 TA = -40°C		Normal operation	Square wave input		4.7	6.1				
				Resonator connection		4.7	6.1				
	Normal operation		Square wave input		4.7	6.1					
			Resonator connection		4.7	6.1					
	Normal operation	Square wave input		4.8	6.7						
		Resonator connection		4.8	6.7						
Normal operation	Square wave input		4.8	7.5							
	Resonator connection		4.8	7.5							
Normal operation	Square wave input		5.4	8.9							
	Resonator connection		5.4	8.9							
Normal operation	Square wave input		7.2	21.0							
	Resonator connection		7.3	21.1							

(Notes and Remarks are listed on the next page.)

- Note 1.** Total current flowing into  $V_{DD}$  and  $EV_{DD0}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$ ,  $EV_{DD0}$  or  $V_{SS}$ ,  $EV_{SS0}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 3.** When high-speed system clock and subsystem clock are stopped.
- Note 4.** When high-speed on-chip oscillator and high-speed system clock are stopped. When AMPHS1 = 1 (Ultra-low power consumption oscillation). However, not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
- Note 5.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$

**Remark 1.**  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

**Remark 2.**  $f_{HOCO}$ : High-speed on-chip oscillator clock frequency (64 MHz max.)

**Remark 3.**  $f_{IH}$ : High-speed on-chip oscillator clock frequency (32 MHz max.)

**Remark 4.**  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)

**Remark 5.** Except subsystem clock operation, temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$

## (1) Flash ROM: 16 to 64 KB of 30- to 64-pin products

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = 0 V)

(2/2)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit		
Supply current Note 1	IDD2 Note 2	HALT mode	HS (high-speed main) mode Note 7	fHOCO = 64 MHz, fIH = 32 MHz Note 4	VDD = 5.0 V	0.80	4.36	mA	
					VDD = 3.0 V	0.80	4.36		
				fHOCO = 32 MHz, fIH = 32 MHz Note 4	VDD = 5.0 V	0.49	3.67		
					VDD = 3.0 V	0.49	3.67		
				fHOCO = 48 MHz, fIH = 24 MHz Note 4	VDD = 5.0 V	0.62	3.42		
					VDD = 3.0 V	0.62	3.42		
			fHOCO = 24 MHz, fIH = 24 MHz Note 4	VDD = 5.0 V	0.4	2.85			
				VDD = 3.0 V	0.4	2.85			
			fHOCO = 16 MHz, fIH = 16 MHz Note 4	VDD = 5.0 V	0.37	2.08			
				VDD = 3.0 V	0.37	2.08			
			HS (high-speed main) mode Note 7	fMX = 20 MHz Note 3, VDD = 5.0 V	Square wave input	0.28	2.45	mA	
					Resonator connection	0.40	2.57		
		fMX = 20 MHz Note 3, VDD = 3.0 V		Square wave input	0.28	2.45			
				Resonator connection	0.40	2.57			
		fMX = 10 MHz Note 3, VDD = 5.0 V		Square wave input	0.19	1.28			
				Resonator connection	0.25	1.36			
		fMX = 10 MHz Note 3, VDD = 3.0 V		Square wave input	0.19	1.28			
				Resonator connection	0.25	1.36			
		Subsystem clock operation		fSUB = 32.768 kHz Note 5, TA = -40°C	Square wave input	0.25	0.57		μA
					Resonator connection	0.44	0.76		
				fSUB = 32.768 kHz Note 5, TA = +25°C	Square wave input	0.30	0.57		
					Resonator connection	0.49	0.76		
			fSUB = 32.768 kHz Note 5, TA = +50°C	Square wave input	0.36	1.17			
				Resonator connection	0.59	1.36			
fSUB = 32.768 kHz Note 5, TA = +70°C	Square wave input	0.49	1.97						
	Resonator connection	0.72	2.16						
fSUB = 32.768 kHz Note 5, TA = +85°C	Square wave input	0.97	3.37						
	Resonator connection	1.16	3.56						
fSUB = 32.768 kHz Note 5, TA = +105°C	Square wave input	3.20	17.10						
	Resonator connection	3.40	17.50						
IDD3 Note 6	STOP mode Note 8	TA = -40°C		0.18	0.51	μA			
		TA = +25°C		0.24	0.51				
		TA = +50°C		0.29	1.10				
		TA = +70°C		0.41	1.90				
		TA = +85°C		0.90	3.30				
		TA = +105°C		3.10	17.00				

(Notes and Remarks are listed on the next page.)



- Note 1.** Total current flowing into V<sub>DD</sub> and EV<sub>DD0</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub> or V<sub>SS</sub>, EV<sub>SS0</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** During HALT instruction execution by flash memory.
- Note 3.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 4.** When high-speed system clock and subsystem clock are stopped.
- Note 5.** When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 6.** Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
- Note 7.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
 HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$
- Note 8.** Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.
- Remark 1.** f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** f<sub>HOCO</sub>: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** f<sub>IH</sub>: High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is TA = 25°C

(2) Flash ROM: 96 to 256 KB of 30- to 100-pin products

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(1/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit	
Supply current Note 1	I <sub>DD1</sub>	Operating mode	HS (high-speed main) mode Note 5	f <sub>HOCO</sub> = 64 MHz, f <sub>IH</sub> = 32 MHz Note 3	Basic operation	V <sub>DD</sub> = 5.0 V		2.6		mA
				V <sub>DD</sub> = 3.0 V		2.6				
			f <sub>HOCO</sub> = 32 MHz, f <sub>IH</sub> = 32 MHz Note 3	Basic operation	V <sub>DD</sub> = 5.0 V		2.3			
			V <sub>DD</sub> = 3.0 V		2.3					
			HS (high-speed main) mode Note 5	f <sub>HOCO</sub> = 64 MHz, f <sub>IH</sub> = 32 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		5.4	10.9	
				V <sub>DD</sub> = 3.0 V		5.4	10.9			
		f <sub>HOCO</sub> = 32 MHz, f <sub>IH</sub> = 32 MHz Note 3		Normal operation	V <sub>DD</sub> = 5.0 V		5.0	10.3		
		V <sub>DD</sub> = 3.0 V			5.0	10.3				
		f <sub>HOCO</sub> = 48 MHz, f <sub>IH</sub> = 24 MHz Note 3		Normal operation	V <sub>DD</sub> = 5.0 V		4.2	8.2		
		V <sub>DD</sub> = 3.0 V			4.2	8.2				
		HS (high-speed main) mode Note 5	f <sub>HOCO</sub> = 24 MHz, f <sub>IH</sub> = 24 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		4.0	7.8		
			V <sub>DD</sub> = 3.0 V		4.0	7.8				
			f <sub>HOCO</sub> = 16 MHz, f <sub>IH</sub> = 16 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		3.0	5.6		
			V <sub>DD</sub> = 3.0 V		3.0	5.6				
			HS (high-speed main) mode Note 5	f <sub>MX</sub> = 20 MHz Note 2, V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		3.4	6.6	
						Resonator connection		3.6	6.7	
		f <sub>MX</sub> = 20 MHz Note 2, V <sub>DD</sub> = 3.0 V		Normal operation	Square wave input		3.4	6.6		
					Resonator connection		3.6	6.7		
		f <sub>MX</sub> = 10 MHz Note 2, V <sub>DD</sub> = 5.0 V		Normal operation	Square wave input		2.1	3.9		
					Resonator connection		2.2	4.0		
		f <sub>MX</sub> = 10 MHz Note 2, V <sub>DD</sub> = 3.0 V		Normal operation	Square wave input		2.1	3.9		
					Resonator connection		2.2	4.0		
		Subsystem clock operation		f <sub>SUB</sub> = 32.768 kHz Note 4 TA = -40°C	Normal operation	Square wave input		4.9	7.1	
						Resonator connection		4.9	7.1	
Normal operation	Square wave input					4.9	7.1			
	Resonator connection					4.9	7.1			
Normal operation	Square wave input					5.1	8.8			
	Resonator connection					5.1	8.8			
Normal operation	Square wave input				5.5	10.5				
	Resonator connection				5.5	10.5				
f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +25°C	Normal operation			Square wave input		6.5	14.5			
				Resonator connection		6.5	14.5			
f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +50°C	Normal operation			Square wave input		13.0	58.0			
				Resonator connection		13.0	58.0			
f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +70°C	Normal operation	Square wave input		13.0	58.0					
		Resonator connection		13.0	58.0					
f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +85°C	Normal operation	Square wave input		13.0	58.0					
		Resonator connection		13.0	58.0					
f <sub>SUB</sub> = 32.768 kHz Note 4 TA = +105°C	Normal operation	Square wave input		13.0	58.0					
		Resonator connection		13.0	58.0					

(Notes and Remarks are listed on the next page.)

- Note 1.** Total current flowing into  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , or  $V_{SS}$ ,  $EV_{SS0}$ , and  $EV_{SS1}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, comparator, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 3.** When high-speed system clock and subsystem clock are stopped.
- Note 4.** When high-speed on-chip oscillator and high-speed system clock are stopped. When  $AMPHS1 = 1$  (Ultra-low power consumption oscillation). However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 5.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
- HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$

**Remark 1.**  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

**Remark 2.**  $f_{HOCO}$ : High-speed on-chip oscillator clock frequency (64 MHz max.)

**Remark 3.**  $f_{IH}$ : High-speed on-chip oscillator clock frequency (32 MHz max.)

**Remark 4.**  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)

**Remark 5.** Except subsystem clock operation, temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$

(2) Flash ROM: 96 to 256 KB of 30- to 100-pin products

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(2/2)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit		
Supply current Note 1	I <sub>DD2</sub> Note 2	HALT mode	HS (high-speed main) mode Note 7	f <sub>HOCO</sub> = 64 MHz, f <sub>IH</sub> = 32 MHz Note 4	V <sub>DD</sub> = 5.0 V	0.79	4.86	mA	
					V <sub>DD</sub> = 3.0 V	0.79	4.86		
				f <sub>HOCO</sub> = 32 MHz, f <sub>IH</sub> = 32 MHz Note 4	V <sub>DD</sub> = 5.0 V	0.49	4.17		
					V <sub>DD</sub> = 3.0 V	0.49	4.17		
				f <sub>HOCO</sub> = 48 MHz, f <sub>IH</sub> = 24 MHz Note 4	V <sub>DD</sub> = 5.0 V	0.62	3.82		
					V <sub>DD</sub> = 3.0 V	0.62	3.82		
			f <sub>HOCO</sub> = 24 MHz, f <sub>IH</sub> = 24 MHz Note 4	V <sub>DD</sub> = 5.0 V	0.4	3.25			
				V <sub>DD</sub> = 3.0 V	0.4	3.25			
			f <sub>HOCO</sub> = 16 MHz, f <sub>IH</sub> = 16 MHz Note 4	V <sub>DD</sub> = 5.0 V	0.38	2.28			
				V <sub>DD</sub> = 3.0 V	0.38	2.28			
			HS (high-speed main) mode Note 7	f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 5.0 V	Square wave input	0.30	2.65	mA	
					Resonator connection	0.40	2.77		
		f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 3.0 V		Square wave input	0.30	2.65			
				Resonator connection	0.40	2.77			
		f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 5.0 V		Square wave input	0.20	1.36			
				Resonator connection	0.25	1.46			
		f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 3.0 V		Square wave input	0.20	1.36			
				Resonator connection	0.25	1.46			
		Subsystem clock operation		f <sub>SUB</sub> = 32.768 kHz Note 5, T <sub>A</sub> = -40°C	Square wave input	0.28	0.66		μA
					Resonator connection	0.47	0.85		
				f <sub>SUB</sub> = 32.768 kHz Note 5, T <sub>A</sub> = +25°C	Square wave input	0.34	0.66		
					Resonator connection	0.53	0.85		
			f <sub>SUB</sub> = 32.768 kHz Note 5, T <sub>A</sub> = +50°C	Square wave input	0.37	2.35			
				Resonator connection	0.56	2.54			
STOP mode Note 8	T <sub>A</sub> = -40°C		0.19	0.57	μA				
	T <sub>A</sub> = +25°C		0.25	0.57					
	T <sub>A</sub> = +50°C		0.33	2.26					
	T <sub>A</sub> = +70°C		0.52	3.99					
	T <sub>A</sub> = +85°C		1.46	8.00					
	T <sub>A</sub> = +105°C		5.50	50.00					

(Notes and Remarks are listed on the next page.)

- Note 1.** Total current flowing into VDD, EVDD0, and EVDD1, including the input leakage current flowing when the level of the input pin is fixed to VDD, EVDD0, and EVDD1, or VSS, EVSS0, and EVSS1. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, comparator, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** During HALT instruction execution by flash memory.
- Note 3.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 4.** When high-speed system clock and subsystem clock are stopped.
- Note 5.** When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 6.** Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
- Note 7.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
 HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$
- Note 8.** Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.
- Remark 1.** fMX: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** fHOCO: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** fIH: High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** fSUB: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is TA = 25°C

**(3) Flash ROM: 384 to 512 KB of 48- to 100-pin products**

**(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

**(1/2)**

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit		
Supply current Note 1	I <sub>DD1</sub>	Operating mode	HS (high-speed main) mode Note 5	f <sub>HOCO</sub> = 64 MHz, f <sub>IH</sub> = 32 MHz Note 3	Basic operation	V <sub>DD</sub> = 5.0 V		2.9		mA	
						V <sub>DD</sub> = 3.0 V		2.9			
					f <sub>HOCO</sub> = 32 MHz, f <sub>IH</sub> = 32 MHz Note 3	Basic operation	V <sub>DD</sub> = 5.0 V		2.5		
							V <sub>DD</sub> = 3.0 V		2.5		
			HS (high-speed main) mode Note 5	f <sub>HOCO</sub> = 64 MHz, f <sub>IH</sub> = 32 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		6.0	11.2	mA	
						V <sub>DD</sub> = 3.0 V		6.0	11.2		
		f <sub>HOCO</sub> = 32 MHz, f <sub>IH</sub> = 32 MHz Note 3		Normal operation	V <sub>DD</sub> = 5.0 V		5.5	10.6			
					V <sub>DD</sub> = 3.0 V		5.5	10.6			
		f <sub>HOCO</sub> = 48 MHz, f <sub>IH</sub> = 24 MHz Note 3		Normal operation	V <sub>DD</sub> = 5.0 V		4.7	8.6			
					V <sub>DD</sub> = 3.0 V		4.7	8.6			
		HS (high-speed main) mode Note 5	f <sub>HOCO</sub> = 24 MHz, f <sub>IH</sub> = 24 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		4.4	8.2	mA		
					V <sub>DD</sub> = 3.0 V		4.4	8.2			
			f <sub>HOCO</sub> = 16 MHz, f <sub>IH</sub> = 16 MHz Note 3	Normal operation	V <sub>DD</sub> = 5.0 V		3.3	5.9			
					V <sub>DD</sub> = 3.0 V		3.3	5.9			
			HS (high-speed main) mode Note 5	f <sub>MX</sub> = 20 MHz Note 2, V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		3.7	6.8	mA	
						Resonator connection		3.9	7.0		
		f <sub>MX</sub> = 20 MHz Note 2, V <sub>DD</sub> = 3.0 V		Normal operation	Square wave input		3.7	6.8			
					Resonator connection		3.9	7.0			
		HS (high-speed main) mode Note 5	f <sub>MX</sub> = 10 MHz Note 2, V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		2.3	4.1	mA		
					Resonator connection		2.3	4.2			
			f <sub>MX</sub> = 10 MHz Note 2, V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		2.3	4.1			
			Resonator connection		2.3	4.2					
Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz Note 4	TA = -40°C	Normal operation	Square wave input		5.2	7.7	μA			
				Resonator connection		5.2	7.7				
		TA = +25°C	Normal operation	Square wave input		5.3	7.7				
				Resonator connection		5.3	7.7				
		TA = +50°C	Normal operation	Square wave input		5.5	10.6				
				Resonator connection		5.5	10.6				
TA = +70°C	Normal operation	Square wave input		5.9	13.2						
		Resonator connection		6.0	13.2						
TA = +85°C	Normal operation	Square wave input		6.8	17.5						
		Resonator connection		6.9	17.5						
TA = +105°C	Normal operation	Square wave input		15.5	77.8						
		Resonator connection		15.5	77.8						

(Notes and Remarks are listed on the next page.)

- Note 1.** Total current flowing into  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$ ,  $EV_{DD0}$ , and  $EV_{DD1}$ , or  $V_{SS}$ ,  $EV_{SS0}$ , and  $EV_{SS1}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, comparator, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 3.** When high-speed system clock and subsystem clock are stopped.
- Note 4.** When high-speed on-chip oscillator and high-speed system clock are stopped. When  $AMPHS1 = 1$  (Ultra-low power consumption oscillation). However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 5.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
- HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$

**Remark 1.**  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

**Remark 2.**  $f_{HOCO}$ : High-speed on-chip oscillator clock frequency (64 MHz max.)

**Remark 3.**  $f_{IH}$ : High-speed on-chip oscillator clock frequency (32 MHz max.)

**Remark 4.**  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)

**Remark 5.** Except subsystem clock operation, temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$

**(3) Flash ROM: 384 to 512 KB of 48- to 100-pin products**

**(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

**(2/2)**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit	
Supply current Note 1	I <sub>DD2</sub> Note 2	HALT mode	HS (high-speed main) mode Note 7	f <sub>HOCO</sub> = 64 MHz, f <sub>IH</sub> = 32 MHz Note 4	V <sub>DD</sub> = 5.0 V	0.93	5.16	mA
					V <sub>DD</sub> = 3.0 V	0.93	5.16	
				f <sub>HOCO</sub> = 32 MHz, f <sub>IH</sub> = 32 MHz Note 4	V <sub>DD</sub> = 5.0 V	0.5	4.47	
					V <sub>DD</sub> = 3.0 V	0.5	4.47	
				f <sub>HOCO</sub> = 48 MHz, f <sub>IH</sub> = 24 MHz Note 4	V <sub>DD</sub> = 5.0 V	0.72	4.08	
					V <sub>DD</sub> = 3.0 V	0.72	4.08	
			f <sub>HOCO</sub> = 24 MHz, f <sub>IH</sub> = 24 MHz Note 4	V <sub>DD</sub> = 5.0 V	0.42	3.51		
				V <sub>DD</sub> = 3.0 V	0.42	3.51		
			f <sub>HOCO</sub> = 16 MHz, f <sub>IH</sub> = 16 MHz Note 4	V <sub>DD</sub> = 5.0 V	0.39	2.38		
				V <sub>DD</sub> = 3.0 V	0.39	2.38		
			HS (high-speed main) mode Note 7	f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 5.0 V	Square wave input	0.31	2.83	mA
					Resonator connection	0.41	2.92	
		f <sub>MX</sub> = 20 MHz Note 3, V <sub>DD</sub> = 3.0 V		Square wave input	0.31	2.83		
				Resonator connection	0.41	2.92		
		f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 5.0 V		Square wave input	0.21	1.46		
				Resonator connection	0.26	1.57		
		f <sub>MX</sub> = 10 MHz Note 3, V <sub>DD</sub> = 3.0 V		Square wave input	0.21	1.46		
				Resonator connection	0.26	1.57		
		Subsystem clock operation		f <sub>SUB</sub> = 32.768 kHz Note 5, TA = -40°C	Square wave input	0.31	0.76	μA
					Resonator connection	0.50	0.95	
				f <sub>SUB</sub> = 32.768 kHz Note 5, TA = +25°C	Square wave input	0.38	0.76	
					Resonator connection	0.57	0.95	
			f <sub>SUB</sub> = 32.768 kHz Note 5, TA = +50°C	Square wave input	0.47	3.59		
				Resonator connection	0.70	3.78		
f <sub>SUB</sub> = 32.768 kHz Note 5, TA = +70°C	Square wave input		0.80	6.20				
	Resonator connection		1.00	6.39				
f <sub>SUB</sub> = 32.768 kHz Note 5, TA = +85°C	Square wave input		1.65	10.56				
	Resonator connection		1.84	10.75				
f <sub>SUB</sub> = 32.768 kHz Note 5, TA = +105°C	Square wave input		8.00	65.7				
	Resonator connection		8.00	65.7				
I <sub>DD3</sub> Note 6	STOP mode Note 8	TA = -40°C			0.19	0.63	μA	
		TA = +25°C			0.30	0.63		
		TA = +50°C			0.41	3.47		
		TA = +70°C			0.80	6.08		
		TA = +85°C			1.53	10.44		
		TA = +105°C			6.50	67.14		

(Notes and Remarks are listed on the next page.)



- Note 1.** Total current flowing into V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub>, and EV<sub>DD1</sub>, or V<sub>SS</sub>, EV<sub>SS0</sub>, and EV<sub>SS1</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, comparator, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
- Note 2.** During HALT instruction execution by flash memory.
- Note 3.** When high-speed on-chip oscillator and subsystem clock are stopped.
- Note 4.** When high-speed system clock and subsystem clock are stopped.
- Note 5.** When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
- Note 6.** Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
- Note 7.** Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.  
 HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}@1\text{ MHz to }16\text{ MHz}$
- Note 8.** Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.
- Remark 1.** f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
- Remark 2.** f<sub>HOCO</sub>: High-speed on-chip oscillator clock frequency (64 MHz max.)
- Remark 3.** f<sub>IH</sub>: High-speed on-chip oscillator clock frequency (32 MHz max.)
- Remark 4.** f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 5.** Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is TA = 25°C

**(4) Peripheral Functions (Common to all products)****(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed on-chip oscillator operating current	IFIL Note 1				0.20		μA
RTC operating current	IRTC Notes 1, 2, 3				0.02		μA
12-bit interval timer operating current	IIT Notes 1, 2, 4				0.02		μA
Watchdog timer operating current	IWDT Notes 1, 2, 5	fil = 15 kHz			0.22		μA
A/D converter operating current	IADC Notes 1, 6	When conversion at maximum speed	Normal mode, AVREFP = VDD = 5.0 V		1.3	1.7	mA
			Low voltage mode, AVREFP = VDD = 3.0 V		0.5	0.7	mA
A/D converter reference voltage current	IADREF Note 1				75.0		μA
Temperature sensor operating current	ITMPS Note 1				75.0		μA
D/A converter operating current	IDAC Notes 1, 11, 13	Per D/A converter channel				1.5	mA
Comparator operating current	ICMP Notes 1, 12, 13	VDD = 5.0 V, Regulator output voltage = 2.1 V	Window mode		12.5		μA
			Comparator high-speed mode		6.5		μA
			Comparator low-speed mode		1.7		μA
		VDD = 5.0 V, Regulator output voltage = 1.8 V	Window mode		8.0		μA
			Comparator high-speed mode		4.0		μA
			Comparator low-speed mode		1.3		μA
LVD operating current	ILVD Notes 1, 7				0.08		μA
Self-programming operating current	IFSP Notes 1, 9				2.50	12.20	mA
BGO operating current	IBGO Notes 1, 8				2.50	12.20	mA
SNOOZE operating current	ISNOZ Note 1	ADC operation	The mode is performed Note 10		0.50	1.10	mA
			The A/D conversion operations are performed, Low voltage mode, AVREFP = VDD = 3.0 V		1.20	2.04	
		CSI/JART operation		0.70	1.54		
		DTC operation		3.10			

**Note 1.** Current flowing to VDD.**Note 2.** When high speed on-chip oscillator and high-speed system clock are stopped.**Note 3.** Current flowing only to the real-time clock (RTC) (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IRTC, when the real-time clock operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added. IDD2 subsystem clock operation includes the operational current of the real-time clock.**Note 4.** Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either IDD1 or IDD2, and IIT, when the 12-bit interval timer operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected, IFIL should be added.

- Note 5.** Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The supply current of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{WDT}$  when the watchdog timer is in operation.
- Note 6.** Current flowing only to the A/D converter. The supply current of the RL78 microcontrollers is the sum of  $I_{DD1}$  or  $I_{DD2}$  and  $I_{ADC}$  when the A/D converter operates in an operation mode or the HALT mode.
- Note 7.** Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{LVD}$  when the LVD circuit is in operation.
- Note 8.** Current flowing during programming of the data flash.
- Note 9.** Current flowing during self-programming.
- Note 10.** For shift time to the SNOOZE mode, see **23.3.3 SNOOZE mode** in the RL78/G14 User's Manual.
- Note 11.** Current flowing only to the D/A converter. The supply current of the RL78 microcontrollers is the sum of  $I_{DD1}$  or  $I_{DD2}$  and  $I_{DAC}$  when the D/A converter operates in an operation mode or the HALT mode.
- Note 12.** Current flowing only to the comparator circuit. The supply current of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$ , or  $I_{DD3}$  and  $I_{CMP}$  when the comparator circuit is in operation.
- Note 13.** A comparator and D/A converter are provided in products with 96 KB or more code flash memory.
- Remark 1.**  $f_{IL}$ : Low-speed on-chip oscillator clock frequency
- Remark 2.**  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)
- Remark 3.**  $f_{CLK}$ : CPU/peripheral hardware clock frequency
- Remark 4.** Temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$

### 3.4 AC Characteristics

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(1/2)

Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit	
Instruction cycle (minimum instruction execution time)	Tcy	Main system clock (fMAIN) operation	HS (high-speed main) mode	2.7 V ≤ VDD ≤ 5.5 V	0.03125		1	μs
				2.4 V ≤ VDD < 2.7 V	0.0625		1	μs
		Subsystem clock (fSUB) operation		2.4 V ≤ VDD ≤ 5.5 V	28.5	30.5	31.3	μs
		In the self- programming mode	HS (high-speed main) mode	2.7 V ≤ VDD ≤ 5.5 V	0.03125		1	μs
2.4 V ≤ VDD < 2.7 V	0.0625				1	μs		
External system clock frequency	fex	2.7 V ≤ VDD ≤ 5.5 V		1.0		20.0	MHz	
		2.4 V ≤ VDD ≤ 2.7 V		1.0		16.0	MHz	
	fexs			32		35	kHz	
External system clock input high-level width, low-level width	tEXH,	2.7 V ≤ VDD ≤ 5.5 V		24			ns	
	tEXL	2.4 V ≤ VDD ≤ 2.7 V		30			ns	
	tEXHS, tEXLS			13.7			μs	
T100 to T103, T110 to T113 input high-level width, low-level width	tT1H, tT1L			1/fMCK + 10 Note			ns	
Timer RJ input cycle	fc	TRJIO		2.7 V ≤ EVDD0 ≤ 5.5 V	100		ns	
				2.4 V ≤ EVDD0 < 2.7 V	300		ns	
Timer RJ input high- level width, low-level width	tTJH, tTJL	TRJIO		2.7 V ≤ EVDD0 ≤ 5.5 V	40		ns	
				2.4 V ≤ EVDD0 < 2.7 V	120		ns	

**Note** The following conditions are required for low voltage interface when EVDD0 < VDD  
2.4 V ≤ EVDD0 < 2.7 V: MIN. 125 ns

**Remark** fMCK: Timer array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of timer mode register mn (TMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3))

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

(2/2)

Items	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Timer RD input high-level width, low-level width	tTDIH, tTDIL	TRDIOA0, TRDIOA1, TRDIOB0, TRDIOB1, TRDIOC0, TRDIOC1, TRDIOD0, TRDIOD1		3/fCLK			ns
Timer RD forced cutoff signal input low-level width	tTDSIL	P130/INTP0	2MHz < fCLK ≤ 32 MHz	1			μs
			fCLK ≤ 2 MHz	1/fCLK + 1			
Timer RG input high-level width, low-level width	tTGIH, tTGIL	TRGIOA, TRGIOB		2.5/fCLK			ns
TO00 to TO03, TO10 to TO13, TRJIO0, TRJO0, TRDIOA0, TRDIOA1, TRDIOB0, TRDIOB1, TRDIOC0, TRDIOC1, TRDIOD0, TRDIOD1, TRGIOA, TRGIOB output frequency	fTO	HS (high-speed main) mode	4.0 V ≤ EVDD0 ≤ 5.5 V			16	MHz
			2.7 V ≤ EVDD0 < 4.0 V			8	MHz
			2.4 V ≤ EVDD0 < 2.7 V			4	MHz
PCLBUZ0, PCLBUZ1 output frequency	fPCL	HS (high-speed main) mode	4.0 V ≤ EVDD0 ≤ 5.5 V			16	MHz
			2.7 V ≤ EVDD0 < 4.0 V			8	MHz
			2.4 V ≤ EVDD0 < 2.7 V			4	MHz
Interrupt input high-level width, low-level width	tINTH, tINTL	INTP0	2.4 V ≤ VDD ≤ 5.5 V	1			μs
		INTP1 to INTP11	2.4 V ≤ EVDD0 ≤ 5.5 V	1			μs
Key interrupt input low-level width	tKR	KR0 to KR7	2.4 V ≤ EVDD0 ≤ 5.5 V	250			ns
RESET low-level width	tRSL			10			μs

Minimum Instruction Execution Time during Main System Clock Operation

Tcy vs VDD (HS (high-speed main) mode)



AC Timing Test Points



External System Clock Timing



TI/TO Timing







Interrupt Request Input Timing



Key Interrupt Input Timing



$\overline{\text{RESET}}$  Input Timing



### 3.5 Peripheral Functions Characteristics

AC Timing Test Points



#### 3.5.1 Serial array unit

##### (1) During communication at same potential (UART mode)

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Transfer rate Note 1		2.4 V ≤ EVDD0 ≤ 5.5 V		fMCK/12 Note 2	bps
		Theoretical value of the maximum transfer rate fMCK = fCLK Note 3		2.6	Mbps

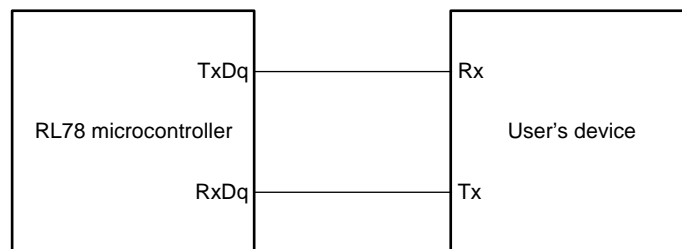
**Note 1.** Transfer rate in the SNOOZE mode is 4800 bps only. However, the SNOOZE mode cannot be used when FRQSEL4 = 1.

**Note 2.** The following conditions are required for low voltage interface when EVDD0 < VDD. 2.4 V ≤ EVDD0 < 2.7 V: MAX. 1.3 Mbps

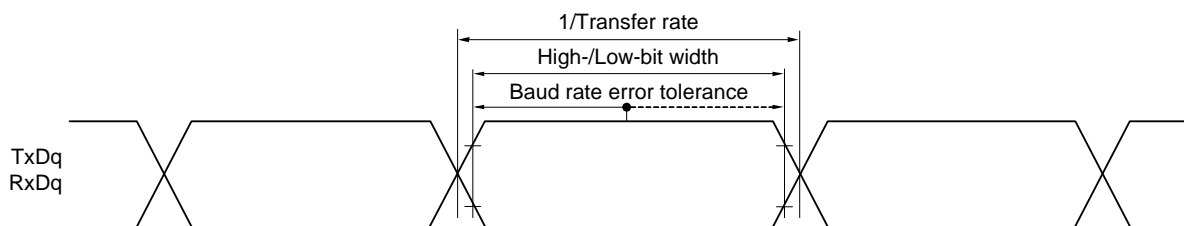
**Note 3.** The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:  
 HS (high-speed main) mode: 32 MHz (2.7 V ≤ VDD ≤ 5.5 V)  
 16 MHz (2.4 V ≤ VDD ≤ 5.5 V)

**Caution** Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

##### UART mode connection diagram (during communication at same potential)



##### UART mode bit width (during communication at same potential) (reference)



**Remark 1.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 5, 14)

**Remark 2.** fMCK: Serial array unit operation clock frequency  
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**(2) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output)**  
**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EVDD0} = \text{EVDD1} \leq \text{VDD} \leq 5.5\text{ V}$ ,  $\text{VSS} = \text{EVSS0} = \text{EVSS1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit	
			MIN.	MAX.		
SCKp cycle time	tkCY1	$\text{tkCY1} \geq 4/f_{\text{CLK}}$	$2.7\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$	250		ns
			$2.4\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$	500		ns
SCKp high-/low-level width	tkH1, tkL1	$4.0\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$	$\text{tkCY1}/2 - 24$		ns	
		$2.7\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$	$\text{tkCY1}/2 - 36$		ns	
		$2.4\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$	$\text{tkCY1}/2 - 76$		ns	
Slp setup time (to SCKp $\uparrow$ ) Note 1	tsIK1	$4.0\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$	66		ns	
		$2.7\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$	66		ns	
		$2.4\text{ V} \leq \text{EVDD0} \leq 5.5\text{ V}$	113		ns	
Slp hold time (from SCKp $\uparrow$ ) Note 2	tkSH1		38		ns	
Delay time from SCKp $\downarrow$ to SOp output Note 3	tkSO1	$C = 30\text{ pF}$ Note 4		50	ns	

**Note 1.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp $\downarrow$ ” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 2.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp $\downarrow$ ” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 3.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp $\uparrow$ ” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 4.** C is the load capacitance of the SCKp and SOp output lines.

**Caution** Select the normal input buffer for the Slp pin and the normal output mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM number (g = 0, 1, 3 to 5, 14)

**Remark 2.** f<sub>MCK</sub>: Serial array unit operation clock frequency  
 (Operation clock to be set by the CKS<sub>mn</sub> bit of serial mode register mn (SMR<sub>mn</sub>). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**(3) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)****(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(1/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SCKp cycle time <sup>Note 5</sup>	tkCY2	4.0 V ≤ EVDD0 ≤ 5.5 V	20 MHz < fMCK	16/fMCK	ns
			fMCK ≤ 20 MHz	12/fMCK	ns
		2.7 V ≤ EVDD0 ≤ 5.5 V	16 MHz < fMCK	16/fMCK	ns
			fMCK ≤ 16 MHz	12/fMCK	ns
		2.4 V ≤ EVDD0 ≤ 5.5 V	12/fMCK and 1000	ns	
SCKp high-/low-level width	tkH2, tkL2	4.0 V ≤ EVDD0 ≤ 5.5 V	tkCY2/2 - 14	ns	
		2.7 V ≤ EVDD0 ≤ 5.5 V	tkCY2/2 - 16	ns	
		2.4 V ≤ EVDD0 ≤ 5.5 V	tkCY2/2 - 36	ns	
Slp setup time (to SCKp↑) <sup>Note 1</sup>	tSIK2	2.7 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 40	ns	
		2.4 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 60	ns	
Slp hold time (from SCKp↑) <sup>Note 2</sup>	tKSI2		1/fMCK + 62	ns	
Delay time from SCKp↓ to SOp output <sup>Note 3</sup>	tkSO2	C = 30 pF <sup>Note 4</sup>	2.7 V ≤ EVDD0 ≤ 5.5 V	2/fMCK + 66	ns
			2.4 V ≤ EVDD0 ≤ 5.5 V	2/fMCK + 113	ns

**Note 1.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes “to SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 2.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp hold time becomes “from SCKp↓” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 3.** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes “from SCKp↑” when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Note 4.** C is the load capacitance of the SOp output lines.

**Note 5.** The maximum transfer rate when using the SNOOZE mode is 1 Mbps.

**Caution** Select the normal input buffer for the Slp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1),  
n: Channel number (n = 0 to 3), g: PIM number (g = 0, 1, 3 to 5, 14)

**Remark 2.** fMCK: Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,  
n: Channel number (mn = 00 to 03, 10 to 13))

**(3) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)**

**(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

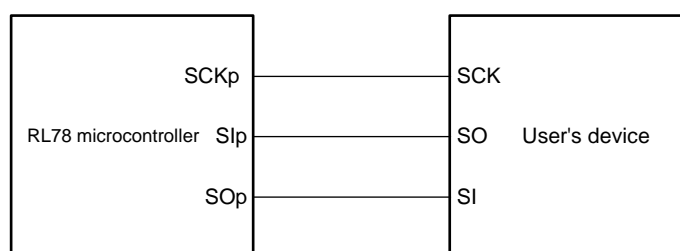
**(2/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit	
			MIN.	MAX.		
$\overline{\text{SSI00}}$ setup time	tSSIK	DAPmn = 0	2.7 V ≤ EVDD0 ≤ 5.5 V	240		ns
			2.4 V ≤ EVDD0 ≤ 5.5 V	400		ns
		DAPmn = 1	2.7 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 240		ns
			2.4 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 400		ns
$\overline{\text{SSI00}}$ hold time	tkSSI	DAPmn = 0	2.7 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 240		ns
			2.4 V ≤ EVDD0 ≤ 5.5 V	1/fMCK + 400		ns
		DAPmn = 1	2.7 V ≤ EVDD0 ≤ 5.5 V	240		ns
			2.4 V ≤ EVDD0 ≤ 5.5 V	400		ns

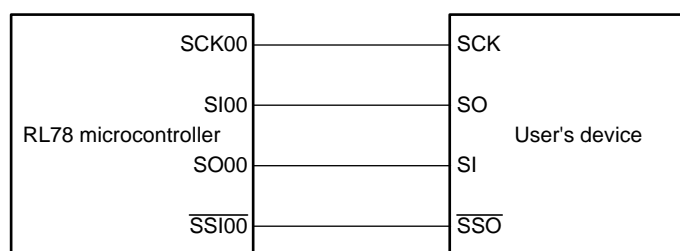
**Caution** Select the normal input buffer for the Slp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

**Remark** p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0), g: PIM number (g = 3, 5)

**CSI mode connection diagram (during communication at same potential)**



**CSI mode connection diagram (during communication at same potential)  
(Slave Transmission of slave select input function (CSI00))**



**Remark 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31)

**Remark 2.** m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13)

**CSI mode serial transfer timing (during communication at same potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (during communication at same potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



**Remark 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31)

**Remark 2.** m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13)

**(4) During communication at same potential (simplified I<sup>2</sup>C mode)****(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SCLr clock frequency	f <sub>SCL</sub>	2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ		400 Note 1	kHz
		2.4 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ		100 Note 1	kHz
Hold time when SCLr = "L"	t <sub>LOW</sub>	2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ	1200		ns
		2.4 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ	4600		ns
Hold time when SCLr = "H"	t <sub>HIGH</sub>	2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ	1200		ns
		2.4 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ	4600		ns
Data setup time (reception)	t <sub>SU: DAT</sub>	2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ	1/f <sub>MCK</sub> + 220 Note 2		ns
		2.4 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ	1/f <sub>MCK</sub> + 580 Note 2		ns
Data hold time (transmission)	t <sub>HD: DAT</sub>	2.7 V ≤ EVDD0 ≤ 5.5 V, Cb = 50 pF, Rb = 2.7 kΩ	0	770	ns
		2.4 V ≤ EVDD0 ≤ 5.5 V, Cb = 100 pF, Rb = 3 kΩ	0	1420	ns

**Note 1.** The value must also be equal to or less than f<sub>MCK</sub>/4.**Note 2.** Set the f<sub>MCK</sub> value to keep the hold time of SCLr = "L" and SCLr = "H".

**Caution** Select the normal input buffer and the N-ch open drain output (V<sub>DD</sub> tolerance (for the 30- to 52-pin products)/EV<sub>DD</sub> tolerance (for the 64- to 100-pin products)) mode for the SDAr pin and the normal output mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register h (POMh).

(Remarks are listed on the next page.)

**Simplified I<sup>2</sup>C mode connection diagram (during communication at same potential)**



**Simplified I<sup>2</sup>C mode serial transfer timing (during communication at same potential)**



**Remark 1.**  $R_b[\Omega]$ : Communication line (SDAr) pull-up resistance,  $C_b[F]$ : Communication line (SDAr, SCLr) load capacitance

**Remark 2.** r: IIC number (r = 00, 01, 10, 11, 20, 21, 30, 31), g: PIM number (g = 0, 1, 3 to 5, 14),  
h: POM number (h = 0, 1, 3 to 5, 7, 14)

**Remark 3.**  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1),  
n: Channel number (n = 0 to 3), mn = 00 to 03, 10 to 13)



**(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)****(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(1/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit	
			MIN.	MAX.		
Transfer rate		reception	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V		fMCK/12 Note 1	bps
			Theoretical value of the maximum transfer rate fMCK = fCLK Note 3		2.6	Mbps
			2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V		fMCK/12 Note 1	bps
			Theoretical value of the maximum transfer rate fMCK = fCLK Note 3		2.6	Mbps
			2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V		fMCK/12 Notes 1, 2	bps
			Theoretical value of the maximum transfer rate fMCK = fCLK Note 3		2.6	Mbps

**Note 1.** Transfer rate in the SNOOZE mode is 4800 bps only.

However, the SNOOZE mode cannot be used when FRQSEL4 = 1.

**Note 2.** The following conditions are required for low voltage interface when EVDD0 < VDD.

2.4 V ≤ EVDD0 < 2.7 V: MAX. 1.3 Mbps

**Note 3.** The maximum operating frequencies of the CPU/peripheral hardware clock (fCLK) are:

HS (high-speed main) mode: 32 MHz (2.7 V ≤ VDD ≤ 5.5 V)

16 MHz (2.4 V ≤ VDD ≤ 5.5 V)

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

**Remark 1.** Vb [V]: Communication line voltage

**Remark 2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 5, 14)

**Remark 3.** fMCK: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number,

n: Channel number (mn = 00 to 03, 10 to 13)

**Remark 4.** UART2 cannot communicate at different potential when bit 1 (PIOR01) of peripheral I/O redirection register 0 (PIOR0) is 1.

**(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)****(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(2/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit	
			MIN.	MAX.		
Transfer rate		transmission	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V		Note 1	bps
			Theoretical value of the maximum transfer rate Cb = 50 pF, Rb = 1.4 kΩ, Vb = 2.7 V		2.6 Note 2	Mbps
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V		Note 3	bps	
		Theoretical value of the maximum transfer rate Cb = 50 pF, Rb = 2.7 kΩ, Vb = 2.3 V		1.2 Note 4	Mbps	
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V		Note 5	bps	
		Theoretical value of the maximum transfer rate Cb = 50 pF, Rb = 5.5 kΩ, Vb = 1.6 V		0.43 Note 6	Mbps	

**Note 1.** The smaller maximum transfer rate derived by using fmck/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 4.0 V ≤ EVDD0 ≤ 5.5 V and 2.7 V ≤ Vb ≤ 4.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides

**Note 2.** This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to **Note 1** above to calculate the maximum transfer rate under conditions of the customer.

**Note 3.** The smaller maximum transfer rate derived by using fmck/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.7 V ≤ EVDD0 < 4.0 V and 2.3 V ≤ Vb ≤ 2.7 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides

**Note 4.** This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to **Note 3** above to calculate the maximum transfer rate under conditions of the customer.

**Note 5.** The smaller maximum transfer rate derived by using  $f_{MCK}/12$  or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when  $2.4\text{ V} \leq E_{VDD0} < 3.3\text{ V}$  and  $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} \times 3} \text{ [bps]}$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\}}{\left(\frac{1}{\text{Transfer rate}}\right) \times \text{Number of transferred bits}} \times 100 \text{ [%]}$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides

**Note 6.** This value as an example is calculated when the conditions described in the "Conditions" column are met. Refer to **Note 5** above to calculate the maximum transfer rate under conditions of the customer.

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output ( $V_{DD}$  tolerance (for the 30- to 52-pin products)/ $E_{VDD}$  tolerance (for the 64- to 100-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

**UART mode connection diagram (during communication at different potential)**



**UART mode bit width (during communication at different potential) (reference)**



- Remark 1.**  $R_b[\Omega]$ : Communication line (TxDq) pull-up resistance,  
 $C_b[F]$ : Communication line (TxDq) load capacitance,  $V_b[V]$ : Communication line voltage
- Remark 2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 5, 14)
- Remark 3.**  $f_{mck}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).  
 m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))
- Remark 4.** UART2 cannot communicate at different potential when bit 1 (PIOR01) of peripheral I/O redirection register 0 (PIOR0) is 1.

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output)****(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(1/3)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SCKp cycle time	tkCY1	tkCY1 ≥ 4/fCLK 4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	600		ns
			1000		ns
			2300		ns
SCKp high-level width	tkH1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	tkCY1/2 - 150		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ	tkCY1/2 - 340		ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V, Cb = 30 pF, Rb = 5.5 kΩ	tkCY1/2 - 916		ns
SCKp low-level width	tkL1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	tkCY1/2 - 24		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ	tkCY1/2 - 36		ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V, Cb = 30 pF, Rb = 5.5 kΩ	tkCY1/2 - 100		ns

**Caution** Select the TTL input buffer for the SIp pin and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

(Remarks are listed two pages after the next page.)

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output)****(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(2/3)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
Slp setup time (to SCKp↑) <sup>Note</sup>	tsIK1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	162		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ	354		ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V, Cb = 30 pF, Rb = 5.5 kΩ	958		ns
Slp hold time (from SCKp↑) <sup>Note</sup>	tkSH1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	38		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ	38		ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V, Cb = 30 pF, Rb = 5.5 kΩ	38		ns
Delay time from SCKp↓ to SOp output <sup>Note</sup>	tkSO1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ		200	ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ		390	ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V, Cb = 30 pF, Rb = 5.5 kΩ		966	ns

**Note** When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the page after the next page.)

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output)****(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(3/3)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
Slp setup time (to SCKp↓) <sup>Note</sup>	tsIK1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	88		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ	88		ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V, Cb = 30 pF, Rb = 5.5 kΩ	220		ns
Slp hold time (from SCKp↓) <sup>Note</sup>	tkSH1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ	38		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ	38		ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V, Cb = 30 pF, Rb = 5.5 kΩ	38		ns
Delay time from SCKp↑ to SOp output <sup>Note</sup>	tkSO1	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ		50	ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ		50	ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V, Cb = 30 pF, Rb = 5.5 kΩ		50	ns

**Note** When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (VDD tolerance (for the 30- to 52-pin products)/EVDD tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For VIH and VIL, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

**CSI mode connection diagram (during communication at different potential)**

**Remark 5.**  $R_b[\Omega]$ : Communication line (SCKp, SOp) pull-up resistance,  $C_b[F]$ : Communication line (SCKp, SOp) load capacitance,  $V_b[V]$ : Communication line voltage

**Remark 6.** p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM and POM number (g = 0, 1, 3 to 5, 14)

**Remark 7.**  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))

**Remark 8.** CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.



**CSI mode serial transfer timing (master mode) (during communication at different potential)  
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (master mode) (during communication at different potential)  
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



**Remark 1.** p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3),  
g: PIM and POM number (g = 0, 1, 3 to 5, 14)

**Remark 2.** CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

**(7) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (slave mode, SCKp... external clock input)****(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit	
			MIN.	MAX.		
SCKp cycle time <sup>Note 1</sup>	tkcy2	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V	24 MHz < fmck	28/fmck		ns
			20 MHz < fmck ≤ 24 MHz	24/fmck		ns
			8 MHz < fmck ≤ 20 MHz	20/fmck		ns
			4 MHz < fmck ≤ 8 MHz	16/fmck		ns
			fmck ≤ 4 MHz	12/fmck		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V	24 MHz < fmck	40/fmck		ns
			20 MHz < fmck ≤ 24 MHz	32/fmck		ns
			16 MHz < fmck ≤ 20 MHz	28/fmck		ns
			8 MHz < fmck ≤ 16 MHz	24/fmck		ns
			4 MHz < fmck ≤ 8 MHz	16/fmck		ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V	24 MHz < fmck	96/fmck		ns
			20 MHz < fmck ≤ 24 MHz	72/fmck		ns
			16 MHz < fmck ≤ 20 MHz	64/fmck		ns
			8 MHz < fmck ≤ 16 MHz	52/fmck		ns
			4 MHz < fmck ≤ 8 MHz	32/fmck		ns
		fmck ≤ 4 MHz	20/fmck		ns	
		SCKp high-/low-level width		tkcy2/2 - 24		ns
		4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V				
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V				
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V		tkcy2/2 - 100		ns
Slp setup time (to SCKp↑) <sup>Note 2</sup>	tsik2	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V	1/fmck + 40		ns	
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V	1/fmck + 40		ns	
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V	1/fmck + 60		ns	
Slp hold time (from SCKp↑) <sup>Note 3</sup>	tksl2		1/fmck + 62		ns	
Delay time from SCKp↓ to SOp output <sup>Note 4</sup>	tkso2	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 30 pF, Rb = 1.4 kΩ		2/fmck + 240	ns	
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 30 pF, Rb = 2.7 kΩ		2/fmck + 428	ns	
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V, Cb = 30 pF, Rv = 5.5 kΩ		2/fmck + 1146	ns	

(Notes, Caution, and Remarks are listed on the next page.)

- Note 1.** Transfer rate in the SNOOZE mode: MAX. 1 Mbps
- Note 2.** When  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 0$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 1$ . The  $\text{Slp}$  setup time becomes “to  $\text{SCKp}\downarrow$ ” when  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 1$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 0$ .
- Note 3.** When  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 0$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 1$ . The  $\text{Slp}$  hold time becomes “from  $\text{SCKp}\downarrow$ ” when  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 1$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 0$ .
- Note 4.** When  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 0$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 1$ . The delay time to  $\text{SOp}$  output becomes “from  $\text{SCKp}\uparrow$ ” when  $\text{DAPmn} = 0$  and  $\text{CKPmn} = 1$ , or  $\text{DAPmn} = 1$  and  $\text{CKPmn} = 0$ .

**Caution** Select the TTL input buffer for the  $\text{Slp}$  pin and  $\text{SCKp}$  pin, and the N-ch open drain output ( $V_{DD}$  tolerance (for the 30- to 52-pin products)/ $\text{EV}_{DD}$  tolerance (for the 64- to 100-pin products)) mode for the  $\text{SOp}$  pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

**CSI mode connection diagram (during communication at different potential)**

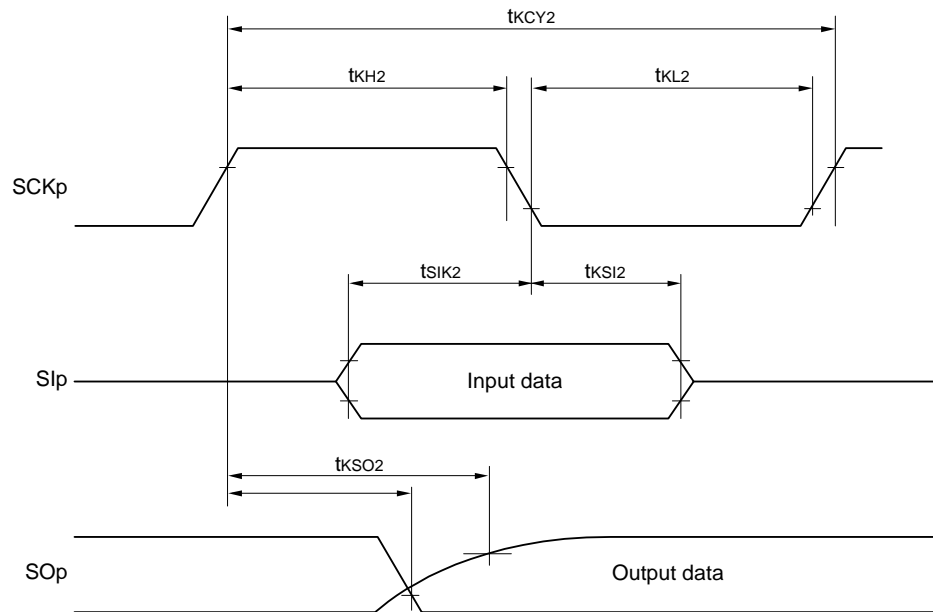


- Remark 1.**  $R_b[\Omega]$ : Communication line ( $\text{SOp}$ ) pull-up resistance,  $C_b[\text{F}]$ : Communication line ( $\text{SOp}$ ) load capacitance,  $V_b[\text{V}]$ : Communication line voltage
- Remark 2.** p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM and POM number (g = 0, 1, 3 to 5, 14)
- Remark 3.**  $f_{\text{MCK}}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the  $\text{CKSmn}$  bit of serial mode register mn ( $\text{SMRmn}$ ).  
m: Unit number, n: Channel number (mn = 00, 01, 02, 10, 12, 13))
- Remark 4.** CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.  
Also, communication at different potential cannot be performed during clock synchronous serial communication with the slave select function.

**CSI mode serial transfer timing (slave mode) (during communication at different potential)  
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (slave mode) (during communication at different potential)  
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



**Remark 1.** p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3), g: PIM and POM number (g = 0, 1, 3 to 5, 14)

**Remark 2.** CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential. Use other CSI for communication at different potential.

Also, communication at different potential cannot be performed during clock synchronous serial communication with the slave select function.

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode)****(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)****(1/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
SCLr clock frequency	f <sub>SCL</sub>	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 50 pF, Rb = 2.7 kΩ		400 Note 1	kHz
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 50 pF, Rb = 2.7 kΩ		400 Note 1	kHz
		4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 100 pF, Rb = 2.8 kΩ		100 Note 1	kHz
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 100 pF, Rb = 2.7 kΩ		100 Note 1	kHz
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V, Cb = 100 pF, Rb = 5.5 kΩ		100 Note 1	kHz
Hold time when SCLr = "L"	t <sub>LOW</sub>	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 50 pF, Rb = 2.7 kΩ	1200		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 50 pF, Rb = 2.7 kΩ	1200		ns
		4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 100 pF, Rb = 2.8 kΩ	4600		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 100 pF, Rb = 2.7 kΩ	4600		ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V, Cb = 100 pF, Rb = 5.5 kΩ	4650		ns
Hold time when SCLr = "H"	t <sub>HIGH</sub>	4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 50 pF, Rb = 2.7 kΩ	620		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 50 pF, Rb = 2.7 kΩ	500		ns
		4.0 V ≤ EVDD0 ≤ 5.5 V, 2.7 V ≤ Vb ≤ 4.0 V, Cb = 100 pF, Rb = 2.8 kΩ	2700		ns
		2.7 V ≤ EVDD0 < 4.0 V, 2.3 V ≤ Vb ≤ 2.7 V, Cb = 100 pF, Rb = 2.7 kΩ	2400		ns
		2.4 V ≤ EVDD0 < 3.3 V, 1.6 V ≤ Vb ≤ 2.0 V, Cb = 100 pF, Rb = 5.5 kΩ	1830		ns

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EVDD0} = \text{EVDD1} \leq \text{VDD} \leq 5.5\text{ V}$ ,  $\text{VSS} = \text{EVSS0} = \text{EVSS1} = 0\text{ V}$ )****(2/2)**

Parameter	Symbol	Conditions	HS (high-speed main) mode		Unit
			MIN.	MAX.	
Data setup time (reception)	t <sub>SU:DAT</sub>	4.0 V $\leq$ EVDD0 $\leq$ 5.5 V, 2.7 V $\leq$ V <sub>b</sub> $\leq$ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 k $\Omega$	1/f <sub>MCK</sub> + 340 Note 2		ns
		2.7 V $\leq$ EVDD0 < 4.0 V, 2.3 V $\leq$ V <sub>b</sub> $\leq$ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 k $\Omega$	1/f <sub>MCK</sub> + 340 Note 2		ns
		4.0 V $\leq$ EVDD0 $\leq$ 5.5 V, 2.7 V $\leq$ V <sub>b</sub> $\leq$ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 k $\Omega$	1/f <sub>MCK</sub> + 760 Note 2		ns
		2.7 V $\leq$ EVDD0 < 4.0 V, 2.3 V $\leq$ V <sub>b</sub> $\leq$ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 k $\Omega$	1/f <sub>MCK</sub> + 760 Note 2		ns
		2.4 V $\leq$ EVDD0 < 3.3 V, 1.6 V $\leq$ V <sub>b</sub> $\leq$ 2.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 k $\Omega$	1/f <sub>MCK</sub> + 570 Note 2		ns
Data hold time (transmission)	t <sub>HD:DAT</sub>	4.0 V $\leq$ EVDD0 $\leq$ 5.5 V, 2.7 V $\leq$ V <sub>b</sub> $\leq$ 4.0 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 k $\Omega$	0	770	ns
		2.7 V $\leq$ EVDD0 < 4.0 V, 2.3 V $\leq$ V <sub>b</sub> $\leq$ 2.7 V, C <sub>b</sub> = 50 pF, R <sub>b</sub> = 2.7 k $\Omega$	0	770	ns
		4.0 V $\leq$ EVDD0 $\leq$ 5.5 V, 2.7 V $\leq$ V <sub>b</sub> $\leq$ 4.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.8 k $\Omega$	0	1420	ns
		2.7 V $\leq$ EVDD0 < 4.0 V, 2.3 V $\leq$ V <sub>b</sub> $\leq$ 2.7 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 2.7 k $\Omega$	0	1420	ns
		2.4 V $\leq$ EVDD0 < 3.3 V, 1.6 V $\leq$ V <sub>b</sub> $\leq$ 2.0 V, C <sub>b</sub> = 100 pF, R <sub>b</sub> = 5.5 k $\Omega$	0	1215	ns

**Note 1.** The value must also be equal to or less than f<sub>MCK</sub>/4.

**Note 2.** Set the f<sub>MCK</sub> value to keep the hold time of SCLr = "L" and SCLr = "H".

**Caution** Select the TTL input buffer and the N-ch open drain output (V<sub>DD</sub> tolerance (for the 30- to 52-pin products)/EV<sub>DD</sub> tolerance (for the 64- to 100-pin products)) mode for the SDAr pin and the N-ch open drain output (V<sub>DD</sub> tolerance (for the 30- to 52-pin products)/EV<sub>DD</sub> tolerance (for the 64- to 100-pin products)) mode for the SCLr pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)

**Simplified I<sup>2</sup>C mode connection diagram (during communication at different potential)**



**Simplified I<sup>2</sup>C mode serial transfer timing (during communication at different potential)**



- Remark 1.**  $R_b[\Omega]$ : Communication line (SDAr, SCLr) pull-up resistance,  $C_b[F]$ : Communication line (SDAr, SCLr) load capacitance,  $V_b[V]$ : Communication line voltage
- Remark 2.** r: IIC number (r = 00, 01, 10, 11, 20, 30, 31), g: PIM, POM number (g = 0, 1, 3 to 5, 14)
- Remark 3.**  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0, 2), mn = 00, 01, 02, 10, 12, 13)

### 3.5.2 Serial interface IICA

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) mode				Unit
			Standard mode		Fast mode		
			MIN.	MAX.	MIN.	MAX.	
SCLA0 clock frequency	fSCL	Fast mode: fCLK ≥ 3.5 MHz	—	—	0	400	kHz
		Standard mode: fCLK ≥ 1 MHz	0	100	—	—	kHz
Setup time of restart condition	tSU: STA		4.7		0.6		μs
Hold time Note 1	tHD: STA		4.0		0.6		μs
Hold time when SCLA0 = "L"	tLOW		4.7		1.3		μs
Hold time when SCLA0 = "H"	tHIGH		4.0		0.6		μs
Data setup time (reception)	tSU: DAT		250		100		ns
Data hold time (transmission) Note 2	tHD: DAT		0	3.45	0	0.9	μs
Setup time of stop condition	tSU: STO		4.0		0.6		μs
Bus-free time	tBUF		4.7		1.3		μs

**Note 1.** The first clock pulse is generated after this period when the start/restart condition is detected.

**Note 2.** The maximum value (MAX.) of tHD: DAT is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.

**Caution** The values in the above table are applied even when bit 2 (PIOR02) in the peripheral I/O redirection register 0 (PIOR0) is 1. At this time, the pin characteristics (IOH1, IOL1, VOH1, VOL1) must satisfy the values in the redirect destination.

**Remark** The maximum value of Cb (communication line capacitance) and the value of Rb (communication line pull-up resistor) at that time in each mode are as follows.

Standard mode: Cb = 400 pF, Rb = 2.7 kΩ

Fast mode: Cb = 320 pF, Rb = 1.1 kΩ

IICA serial transfer timing



**Remark** n = 0, 1



## 3.6 Analog Characteristics

### 3.6.1 A/D converter characteristics

#### Classification of A/D converter characteristics

Input channel	Reference Voltage	Reference voltage (+) = AVREFP Reference voltage (-) = AVREFM	Reference voltage (+) = VDD Reference voltage (-) = VSS	Reference voltage (+) = VBGR Reference voltage (-) = AVREFM
ANI0 to ANI14		Refer to 3.6.1 (1).	Refer to 3.6.1 (3).	Refer to 3.6.1 (4).
ANI16 to ANI20		Refer to 3.6.1 (2).		
Internal reference voltage Temperature sensor output voltage		Refer to 3.6.1 (1).		

(1) When reference voltage (+) = AVREFP/ANI0 (ADREFP1 = 0, ADREFP0 = 1), reference voltage (-) = AVREFM/ANI1 (ADREFM = 1), target pin: ANI2 to ANI14, internal reference voltage, and temperature sensor output voltage

(TA = -40 to +105°C, 2.4 V ≤ AVREFP ≤ VDD ≤ 5.5 V, VSS = 0 V, Reference voltage (+) = AVREFP,  
Reference voltage (-) = AVREFM = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8		10	bit
Overall error Note 1	AINL	10-bit resolution AVREFP = VDD Note 3	2.4 V ≤ AVREFP ≤ 5.5 V	1.2	±3.5	LSB
Conversion time	tCONV	10-bit resolution Target pin: ANI2 to ANI14	3.6 V ≤ VDD ≤ 5.5 V	2.125	39	μs
			2.7 V ≤ VDD ≤ 5.5 V	3.1875	39	μs
			2.4 V ≤ VDD ≤ 5.5 V	17	39	μs
		10-bit resolution Target pin: Internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode)	3.6 V ≤ VDD ≤ 5.5 V	2.375	39	μs
			2.7 V ≤ VDD ≤ 5.5 V	3.5625	39	μs
			2.4 V ≤ VDD ≤ 5.5 V	17	39	μs
Zero-scale error Notes 1, 2	EzS	10-bit resolution AVREFP = VDD Note 3	2.4 V ≤ AVREFP ≤ 5.5 V		±0.25	%FSR
Full-scale error Notes 1, 2	EFS	10-bit resolution AVREFP = VDD Note 3	2.4 V ≤ AVREFP ≤ 5.5 V		±0.25	%FSR
Integral linearity error Note 1	ILE	10-bit resolution AVREFP = VDD Note 3	2.4 V ≤ AVREFP ≤ 5.5 V		±2.5	LSB
Differential linearity error Note 1	DLE	10-bit resolution AVREFP = VDD Note 3	2.4 V ≤ AVREFP ≤ 5.5 V		±1.5	LSB
Analog input voltage	VAIN	ANI2 to ANI14		0	AVREFP	V
		Internal reference voltage output (2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed main) mode)			VBGR Note 4	V
		Temperature sensor output voltage (2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed main) mode)			VTMPS25 Note 4	V

**Note 1.** Excludes quantization error (±1/2 LSB).

**Note 2.** This value is indicated as a ratio (%FSR) to the full-scale value.

**Note 3.** When AVREFP < VDD, the MAX. values are as follows.

Overall error: Add ±1.0 LSB to the MAX. value when AVREFP = VDD.

Zero-scale error/Full-scale error: Add ±0.05%FSR to the MAX. value when AVREFP = VDD.

Integral linearity error/ Differential linearity error: Add ±0.5 LSB to the MAX. value when AVREFP = VDD.

**Note 4.** Refer to 3.6.2 Temperature sensor characteristics/internal reference voltage characteristic.

(2) When reference voltage (+) =  $AV_{REFP}/ANI0$  ( $ADREFP1 = 0$ ,  $ADREFP0 = 1$ ), reference voltage (-) =  $AV_{REFM}/ANI1$  ( $ADREFM = 1$ ), target pin: ANI16 to ANI20

(TA = -40 to +105°C,  $2.4\text{ V} \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $2.4\text{ V} \leq AV_{REFP} \leq V_{DD} \leq 5.5\text{ V}$ ,

$V_{SS} = EV_{SS0} = EV_{SS1} = 0\text{ V}$ , Reference voltage (+) =  $AV_{REFP}$ , Reference voltage (-) =  $AV_{REFM} = 0\text{ V}$ )

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8		10	bit
Overall error Note 1	AINL	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$		1.2	$\pm 5.0$	LSB
Conversion time	tCONV	10-bit resolution Target ANI pin: ANI16 to ANI20	$3.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	2.125		39	$\mu\text{s}$
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	3.1875		39	$\mu\text{s}$
			$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	17		39	$\mu\text{s}$
Zero-scale error Notes 1, 2	E <sub>ZS</sub>	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$			$\pm 0.35$	%FSR
Full-scale error Notes 1, 2	E <sub>FS</sub>	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$			$\pm 0.35$	%FSR
Integral linearity error Note 1	ILE	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$			$\pm 3.5$	LSB
Differential linearity error Note 1	DLE	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ Notes 3, 4	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$			$\pm 2.0$	LSB
Analog input voltage	V <sub>AIN</sub>	ANI16 to ANI20		0		$AV_{REFP}$ and $EV_{DD0}$	V

**Note 1.** Excludes quantization error ( $\pm 1/2$  LSB).

**Note 2.** This value is indicated as a ratio (%FSR) to the full-scale value.

**Note 3.** When  $EV_{DD0} \leq AV_{REFP} \leq V_{DD}$ , the MAX. values are as follows.

Overall error: Add  $\pm 1.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .  
 Zero-scale error/Full-scale error: Add  $\pm 0.05\%$ FSR to the MAX. value when  $AV_{REFP} = V_{DD}$ .  
 Integral linearity error/ Differential linearity error: Add  $\pm 0.5$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .

**Note 4.** When  $AV_{REFP} < EV_{DD0} \leq V_{DD}$ , the MAX. values are as follows.

Overall error: Add  $\pm 4.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .  
 Zero-scale error/Full-scale error: Add  $\pm 0.20\%$ FSR to the MAX. value when  $AV_{REFP} = V_{DD}$ .  
 Integral linearity error/ Differential linearity error: Add  $\pm 2.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .

- (3) When reference voltage (+) = V<sub>DD</sub> (ADREFP1 = 0, ADREFP0 = 0), reference voltage (-) = V<sub>SS</sub> (ADREFM = 0), target pin: ANI0 to ANI14, ANI16 to ANI20, internal reference voltage, and temperature sensor output voltage

(TA = -40 to +105°C, 2.4 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V, Reference voltage (+) = V<sub>DD</sub>, Reference voltage (-) = V<sub>SS</sub>)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8		10	bit
Overall error Note 1	AINL	10-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V		1.2	±7.0	LSB
Conversion time	t <sub>CONV</sub>	10-bit resolution Target pin: ANI0 to ANI14, ANI16 to ANI20	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.125		39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.1875		39	μs
			2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17		39	μs
		10-bit resolution Target pin: internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode)	3.6 V ≤ V <sub>DD</sub> ≤ 5.5 V	2.375		39	μs
			2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	3.5625		39	μs
			2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	17		39	μs
Zero-scale error Notes 1, 2	E <sub>ZS</sub>	10-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±0.60	%FSR
Full-scale error Notes 1, 2	E <sub>FS</sub>	10-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±0.60	%FSR
Integral linearity error Note 1	ILE	10-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±4.0	LSB
Differential linearity error Note 1	DLE	10-bit resolution	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V			±2.0	LSB
Analog input voltage	V <sub>AIN</sub>	ANI0 to ANI14		0		V <sub>DD</sub>	V
		ANI16 to ANI20		0		EV <sub>DD0</sub>	V
		Internal reference voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)		V <sub>BGR</sub> Note 3			V
		Temperature sensor output voltage (2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V, HS (high-speed main) mode)		V <sub>TMPS25</sub> Note 3			V

**Note 1.** Excludes quantization error (±1/2 LSB).

**Note 2.** This value is indicated as a ratio (% FSR) to the full-scale value.

**Note 3.** Refer to 3.6.2 Temperature sensor characteristics/internal reference voltage characteristic.

(4) When reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), reference voltage (-) = AVREFM/ANI1 (ADREFM = 1), target pin: ANI0, ANI2 to ANI14, ANI16 to ANI20

(TA = -40 to +105°C, 2.4 V ≤ VDD ≤ 5.5 V, 1.6 V ≤ EVDD = EVDD1 ≤ VDD, VSS = EVSS0 = EVSS1 = 0 V,

Reference voltage (+) = VBGR Note 3, Reference voltage (-) = AVREFM = 0 V Note 4, HS (high-speed main) mode)

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES			8			bit
Conversion time	tCONV	8-bit resolution	2.4 V ≤ VDD ≤ 5.5 V	17		39	μs
Zero-scale error Notes 1, 2	Ezs	8-bit resolution	2.4 V ≤ VDD ≤ 5.5 V			±0.60	% FSR
Integral linearity error Note 1	ILE	8-bit resolution	2.4 V ≤ VDD ≤ 5.5 V			±2.0	LSB
Differential linearity error Note 1	DLE	8-bit resolution	2.4 V ≤ VDD ≤ 5.5 V			±1.0	LSB
Analog input voltage	VAIN			0		VBGR Note 3	V

**Note 1.** Excludes quantization error (±1/2 LSB).

**Note 2.** This value is indicated as a ratio (% FSR) to the full-scale value.

**Note 3.** Refer to 3.6.2 Temperature sensor characteristics/internal reference voltage characteristic.

**Note 4.** When reference voltage (-) = VSS, the MAX. values are as follows.

Zero-scale error: Add ±0.35%FSR to the MAX. value when reference voltage (-) = AVREFM.

Integral linearity error: Add ±0.5 LSB to the MAX. value when reference voltage (-) = AVREFM.

Differential linearity error: Add ±0.2 LSB to the MAX. value when reference voltage (-) = AVREFM.

### 3.6.2 Temperature sensor characteristics/internal reference voltage characteristic

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = EV_{SS0} = EV_{SS1} = 0\text{ V}$ , HS (high-speed main) mode)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Temperature sensor output voltage	VTMPS25	Setting ADS register = 80H, $T_A = +25^\circ\text{C}$		1.05		V
Internal reference voltage	VBGR	Setting ADS register = 81H	1.38	1.45	1.5	V
Temperature coefficient	FVTMPS	Temperature sensor that depends on the temperature		-3.6		mV/ $^\circ\text{C}$
Operation stabilization wait time	tAMP		5			$\mu\text{s}$

### 3.6.3 D/A converter characteristics

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq EV_{SS0} = EV_{SS1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = EV_{SS0} = EV_{SS1} = 0\text{ V}$ )

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Resolution	RES					8	bit
Overall error	AINL	Rload = 4 M $\Omega$	$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$			$\pm 2.5$	LSB
		Rload = 8 M $\Omega$	$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$			$\pm 2.5$	LSB
Settling time	tSET	Cload = 20 pF	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$			3	$\mu\text{s}$
			$2.4\text{ V} \leq V_{DD} < 2.7\text{ V}$			6	$\mu\text{s}$

### 3.6.4 Comparator

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input voltage range	Ivref		0		EVDD0 - 1.4	V	
	Ivcmp		-0.3		EVDD0 + 0.3	V	
Output delay	td	VDD = 3.0 V Input slew rate > 50 mV/μs	Comparator high-speed mode, standard mode			1.2	μs
			Comparator high-speed mode, window mode			2.0	μs
			Comparator low-speed mode, standard mode		3.0	5.0	μs
High-electric-potential reference voltage	VTW+	Comparator high-speed mode, window mode		0.76 VDD		V	
Low-electric-potential reference voltage	VTW-	Comparator high-speed mode, window mode		0.24 VDD		V	
Operation stabilization wait time	tcMP		100			μs	
Internal reference voltage Note	VBGR	2.4 V ≤ VDD ≤ 5.5 V, HS (high-speed main) mode	1.38	1.45	1.50	V	

**Note** Not usable in sub-clock operation or STOP mode.

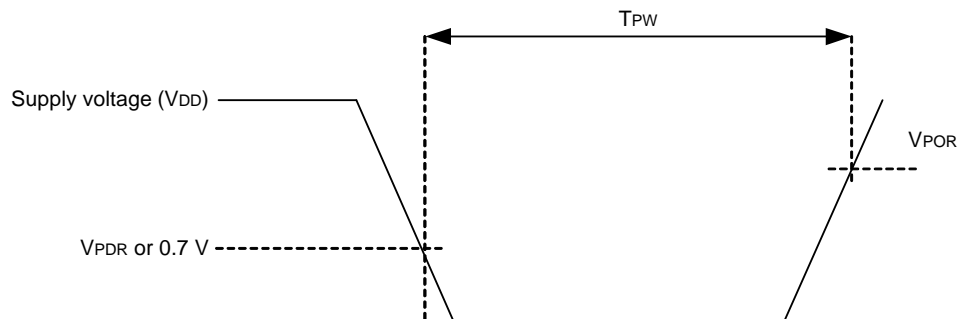
### 3.6.5 POR circuit characteristics

(TA = -40 to +105°C, VSS = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power on/down reset threshold	VPOR	Voltage threshold on VDD rising	1.45	1.51	1.57	V
	VPDR	Voltage threshold on VDD falling Note 1	1.44	1.50	1.56	V
Minimum pulse width Note 2	TPW		300			μs

**Note 1.** However, when the operating voltage falls while the LVD is off, enter STOP mode, or enable the reset status using the external reset pin before the voltage falls below the operating voltage range shown in 3.4 AC Characteristics.

**Note 2.** Minimum time required for a POR reset when VDD exceeds below VPDR. This is also the minimum time required for a POR reset from when VDD exceeds below 0.7 V to when VDD exceeds VPOR while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



### 3.6.6 LVD circuit characteristics

#### (1) Reset Mode and Interrupt Mode

(TA = -40 to +105°C, VPDR ≤ VDD ≤ 5.5 V, VSS = 0 V)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit		
Voltage detection threshold	Supply voltage level	VLVD0	Rising edge	3.90	4.06	4.22	V		
			Falling edge	3.83	3.98	4.13	V		
		VLVD1	Rising edge	3.60	3.75	3.90	V		
			Falling edge	3.53	3.67	3.81	V		
		VLVD2	Rising edge	3.01	3.13	3.25	V		
			Falling edge	2.94	3.06	3.18	V		
		VLVD3	Rising edge	2.90	3.02	3.14	V		
			Falling edge	2.85	2.96	3.07	V		
		VLVD4	Rising edge	2.81	2.92	3.03	V		
			Falling edge	2.75	2.86	2.97	V		
		VLVD5	Rising edge	2.70	2.81	2.92	V		
			Falling edge	2.64	2.75	2.86	V		
		VLVD6	Rising edge	2.61	2.71	2.81	V		
			Falling edge	2.55	2.65	2.75	V		
		VLVD7	Rising edge	2.51	2.61	2.71	V		
			Falling edge	2.45	2.55	2.65	V		
		Minimum pulse width		tlw		300			μs
		Detection delay time						300	μs

**(2) Interrupt & Reset Mode****(TA = -40 to +105°C, VPDR ≤ VDD ≤ 5.5 V, VSS = 0 V)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Voltage detection threshold	VLVDD0	VPOC2, VPOC1, VPOC0 = 0, 1, 1, falling reset voltage	2.64	2.75	2.86	V	
	VLVDD1	LVIS1, LVIS0 = 1, 0	Rising release reset voltage	2.81	2.92	3.03	V
			Falling interrupt voltage	2.75	2.86	2.97	V
	VLVDD2	LVIS1, LVIS0 = 0, 1	Rising release reset voltage	2.90	3.02	3.14	V
			Falling interrupt voltage	2.85	2.96	3.07	V
	VLVDD3	LVIS1, LVIS0 = 0, 0	Rising release reset voltage	3.90	4.06	4.22	V
			Falling interrupt voltage	3.83	3.98	4.13	V

**3.6.7 Power supply voltage rising slope characteristics****(TA = -40 to +105°C, VSS = 0 V)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	SVDD				54	V/ms

**Caution** Make sure to keep the internal reset state by the LVD circuit or an external reset until VDD reaches the operating voltage range shown in 3.4 AC Characteristics.



### 3.7 RAM Data Retention Characteristics

(TA = -40 to +105°C, VSS = 0V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	VDDDR		1.44 Note		5.5	V

**Note** The value depends on the POR detection voltage. When the voltage drops, the RAM data is retained before a POR reset is effected, but RAM data is not retained when a POR reset is effected.



### 3.8 Flash Memory Programming Characteristics

(TA = -40 to +105°C, 2.4 V ≤ VDD ≤ 5.5 V, VSS = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
System clock frequency	fCLK	2.4 V ≤ VDD ≤ 5.5 V	1		32	MHz
Number of code flash rewrites Notes 1, 2, 3	C <sub>erwr</sub>	Retained for 20 years TA = 85°C Note 4	1,000			Times
Number of data flash rewrites Notes 1, 2, 3		Retained for 1 year TA = 25°C		1,000,000		
		Retained for 5 years TA = 85°C Note 4	100,000			
		Retained for 20 years TA = 85°C Note 4	10,000			

- Note 1.** 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.
- Note 2.** When using flash memory programmer and Renesas Electronics self-programming library
- Note 3.** These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.
- Note 4.** This temperature is the average value at which data are retained.

### 3.9 Dedicated Flash Memory Programmer Communication (UART)

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During serial programming	115,200		1,000,000	bps

### 3.10 Timing of Entry to Flash Memory Programming Modes

(TA = -40 to +105°C, 2.4 V ≤ EVDD0 = EVDD1 ≤ VDD ≤ 5.5 V, VSS = EVSS0 = EVSS1 = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
How long from when an external reset ends until the initial communication settings are specified	tsuINIT	POR and LVD reset must end before the external reset ends.			100	ms
How long from when the TOOL0 pin is placed at the low level until an external reset ends	tsu	POR and LVD reset must end before the external reset ends.	10			μs
How long the TOOL0 pin must be kept at the low level after an external reset ends (excluding the processing time of the firmware to control the flash memory)	tHD	POR and LVD reset must end before the external reset ends.	1			ms



- <1> The low level is input to the TOOL0 pin.
- <2> The external reset ends (POR and LVD reset must end before the external reset ends).
- <3> The TOOL0 pin is set to the high level.
- <4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

**Remark** tsuINIT: The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the external resets end.

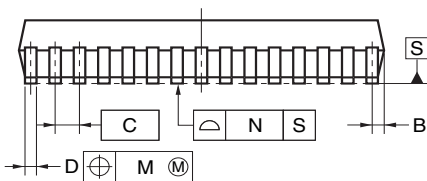
tsu: How long from when the TOOL0 pin is placed at the low level until a pin reset ends

tHD: How long to keep the TOOL0 pin at the low level from when the external resets end (excluding the processing time of the firmware to control the flash memory)

## 4. PACKAGE DRAWINGS

### <R> 4.1 30-pin Package

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LSSOP30-0300-0.65	PLSP0030JB-B	S30MC-65-5A4-3	0.18



**NOTE**  
Each lead centerline is located within 0.13 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
A	9.85±0.15
B	0.45 MAX.
C	0.65 (T.P.)
D	0.24 <sup>+0.08</sup> <sub>-0.07</sub>
E	0.1±0.05
F	1.3±0.1
G	1.2
H	8.1±0.2
I	6.1±0.2
J	1.0±0.2
K	0.17±0.03
L	0.5
M	0.13
N	0.10
P	3° <sup>+5°</sup> <sub>-3°</sub>
T	0.25
U	0.6±0.15

©2012 Renesas Electronics Corporation. All rights reserved.

<R> 4.2 32-pin Package

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-HWQFN32-5x5-0.50	PWQN0032KB-A	P32K8-50-3B4-4	0.06



DETAIL OF (A) PART



Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	4.95	5.00	5.05
E	4.95	5.00	5.05
A	0.70	0.75	0.80
b	0.18	0.25	0.30
e	—	0.50	—
Lp	0.30	0.40	0.50
x	—	—	0.05
y	—	—	0.05



ITEM	A	D2			E2		
		MIN	NOM	MAX	MIN	NOM	MAX
EXPOSED DIE PAD VARIATIONS		3.45	3.50	3.55	3.45	3.50	3.55

© 2012 Renesas Electronics Corporation. All rights reserved.

<R>

JEITA Package code	RENESAS code	MASS(TYP.)[g]
P-HWQFN032-5x5-0.50	PWQN0032KE-A	0.06



Reference Symbol	Dimension in Millimeters		
	Min.	Nom.	Max.
A	—	—	0.80
A <sub>1</sub>	0.00	0.02	0.05
A <sub>2</sub>	0.203 REF.		
b	0.18	0.25	0.30
D	5.00 BSC		
E	5.00 BSC		
e	0.50 BSC		
L	0.35	0.40	0.45
K	0.20	—	—
D <sub>2</sub>	3.15	3.20	3.25
E <sub>2</sub>	3.15	3.20	3.25
aaa	0.15		
bbb	0.10		
ccc	0.10		
ddd	0.05		
eee	0.08		
fff	0.10		

<R>

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LQFP32-7x7-0.80	PLQP0032GB-A	P32GA-80-GBT-1	0.2



(UNIT:mm)

ITEM	DIMENSIONS
D	7.00±0.10
E	7.00±0.10
HD	9.00±0.20
HE	9.00±0.20
A	1.70 MAX.
A1	0.10±0.10
A2	1.40
b	0.37±0.05
c	0.145±0.055
L	0.50±0.20
$\theta$	0° to 8°
e	0.80
x	0.20
y	0.10

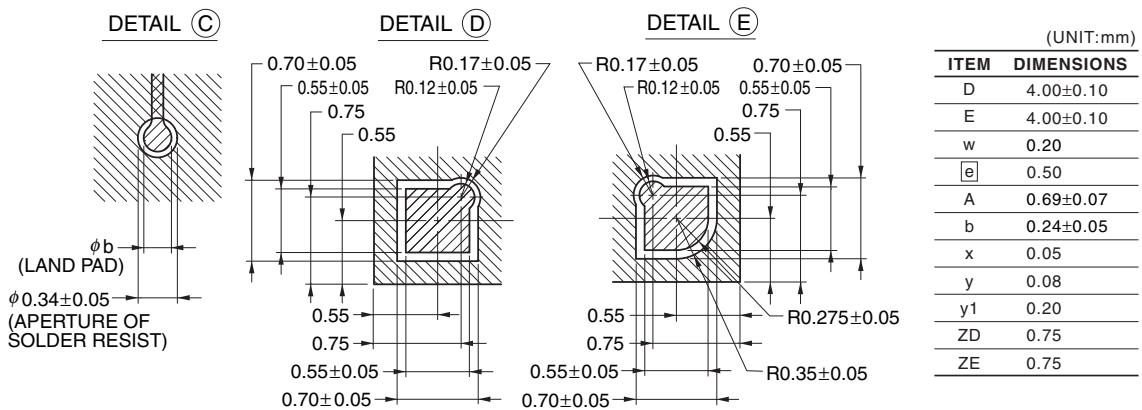
**NOTE**

1. Dimensions “ $\ast 1$ ” and “ $\ast 2$ ” do not include mold flash.
2. Dimension “ $\ast 3$ ” does not include trim offset.

© 2012 Renesas Electronics Corporation. All rights reserved.

<R> 4.3 36-pin Package

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-WFLGA36-4x4-0.50	PWLG0036KA-A	P36FC-50-AA4-2	0.023



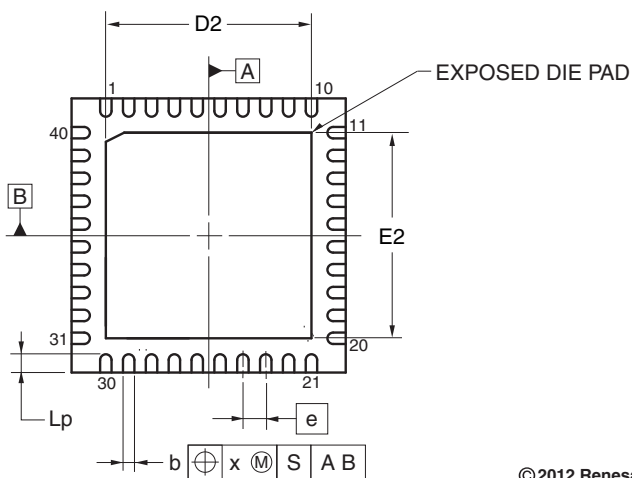
©2012 Renesas Electronics Corporation. All rights reserved.

<R> 4.4 40-pin Package

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-HWQFN40-6x6-0.50	PWQN0040KC-A	P40K8-50-4B4-4	0.09



DETAIL OF (A) PART



Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	5.95	6.00	6.05
E	5.95	6.00	6.05
A	0.70	0.75	0.80
b	0.18	0.25	0.30
e	—	0.50	—
Lp	0.30	0.40	0.50
x	—	—	0.05
y	—	—	0.05

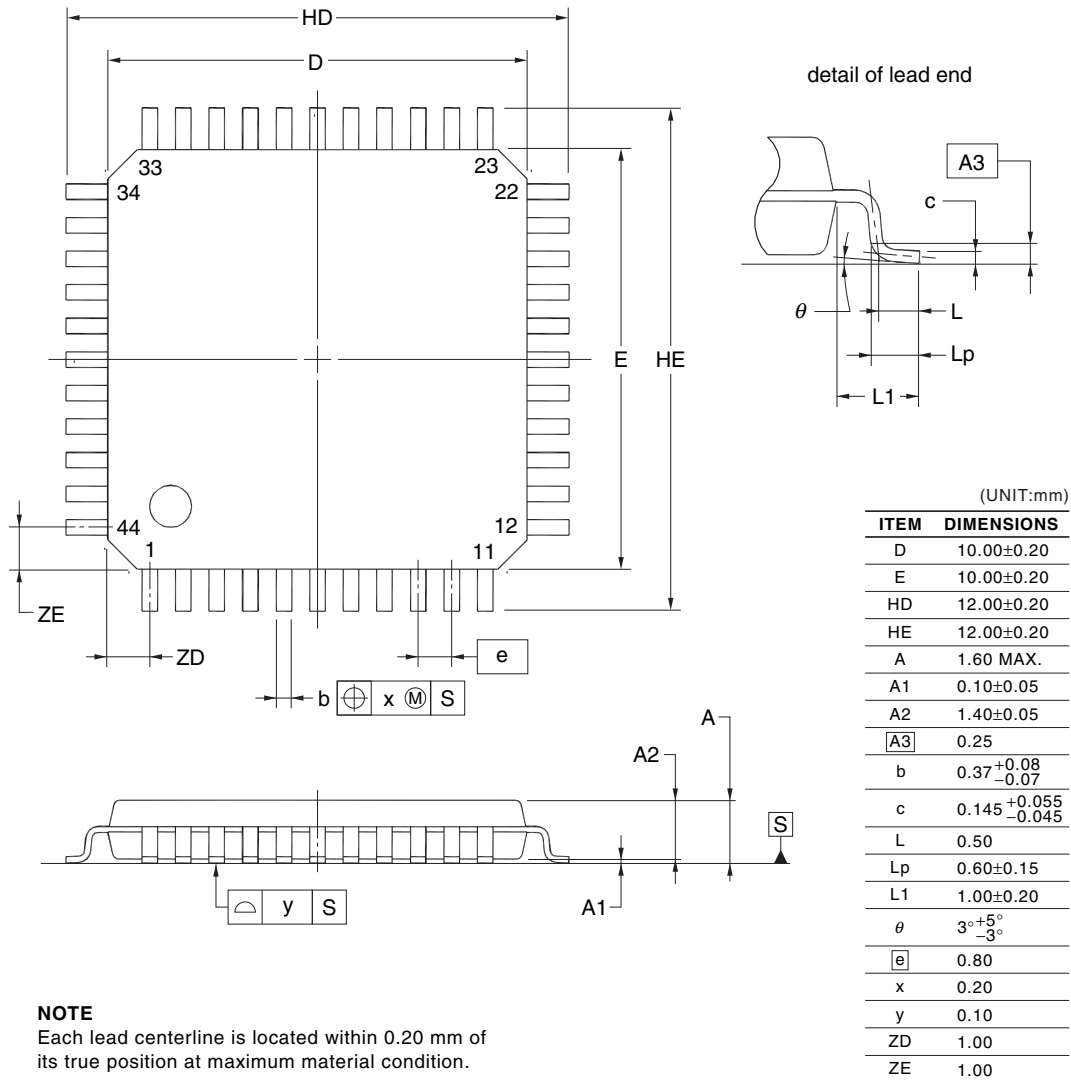
ITEM	A	D2			E2		
		MIN	NOM	MAX	MIN	NOM	MAX
EXPOSED DIE PAD VARIATIONS		4.45	4.50	4.55	4.45	4.50	4.55

©2012 Renesas Electronics Corporation. All rights reserved.



<R> 4.5 44-pin Package

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LQFP44-10x10-0.80	PLQP0044GC-A	P44GB-80-UES-2	0.36

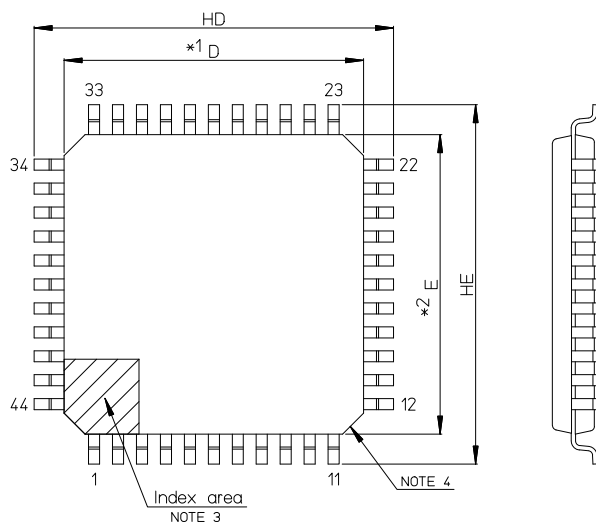


**NOTE**  
Each lead centerline is located within 0.20 mm of its true position at maximum material condition.

©2012 Renesas Electronics Corporation. All rights reserved.

<R>

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-LQFP44-10x10-0.80	PLQP0044GC-D	—	0.36g



- NOTE)
1. DIMENSIONS \*1" AND \*2" DO NOT INCLUDE MOLD FLASH.
  2. DIMENSION \*3" DOES NOT INCLUDE TRIM OFFSET.
  3. PIN 1 VISUAL INDEX FEATURE MAY VARY, BUT MUST BE LOCATED WITHIN THE HATCHED AREA.
  4. CHAMFERS AT CORNERS ARE OPTIONAL; SIZE MAY VARY.



Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	9.8	10.0	10.2
E	9.8	10.0	10.2
A2	—	1.4	—
HD	11.8	12.0	12.2
HE	11.8	12.0	12.2
A	—	—	1.6
A1	0.05	—	0.15
bp	0.22	0.37	0.45
c	0.09	—	0.20
ø	0°	3.5°	8°
[e]	—	0.80	—
x	—	—	0.20
y	—	—	0.10
Lp	0.45	0.6	0.75
L1	—	1.0	—

<R> 4.6 48-pin Package

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LFQFP48-7x7-0.50	PLQP0048KF-A	P48GA-50-8EU-1	0.16



**NOTE**  
Each lead centerline is located within 0.08 mm of its true position at maximum material condition.

©2012 Renesas Electronics Corporation. All rights reserved.

<R>

<b>JEITA Package Code</b>	<b>RENESAS Code</b>	<b>Previous Code</b>	<b>MASS (Typ) [g]</b>
P-LFQFP48-7x7-0.50	PLQP0048KB-B	—	0.2



Unit: mm



- NOTE)
1. DIMENSIONS "\*"1" AND "\*"2" DO NOT INCLUDE MOLD FLASH.
  2. DIMENSION "\*"3" DOES NOT INCLUDE TRIM OFFSET.
  3. PIN 1 VISUAL INDEX FEATURE MAY VARY, BUT MUST BE LOCATED WITHIN THE HATCHED AREA.
  4. CHAMFERS AT CORNERS ARE OPTIONAL, SIZE MAY VARY.



Detail F

Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
D	6.9	7.0	7.1
E	6.9	7.0	7.1
A <sub>2</sub>	—	1.4	—
H <sub>D</sub>	8.8	9.0	9.2
H <sub>E</sub>	8.8	9.0	9.2
A	—	—	1.7
A <sub>1</sub>	0.05	—	0.15
b <sub>p</sub>	0.17	0.20	0.27
c	0.09	—	0.20
θ	0°	3.5°	8°
e	—	0.5	—
x	—	—	0.08
y	—	—	0.08
L <sub>p</sub>	0.45	0.6	0.75
L <sub>1</sub>	—	1.0	—

© 2015 Renesas Electronics Corporation. All rights reserved.

<R>

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-HWQFN48-7x7-0.50	PWQN0048KB-A	48PJN-A P48K8-50-5B4-5	0.13



DETAIL OF (A) PART



Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	6.95	7.00	7.05
E	6.95	7.00	7.05
A	0.70	0.75	0.80
b	0.18	0.25	0.30
e	—	0.50	—
Lp	0.30	0.40	0.50
x	—	—	0.05
y	—	—	0.05

ITEM	A	D2			E2		
		MIN	NOM	MAX	MIN	NOM	MAX
EXPOSED DIE PAD VARIATIONS		5.45	5.50	5.55	5.45	5.50	5.55

©2012 Renesas Electronics Corporation. All rights reserved.

<R> 4.7 52-pin Package

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LQFP52-10x10-0.65	PLQP0052JA-A	P52GB-65-GBS-1	0.3



(UNIT:mm)

ITEM	DIMENSIONS
D	10.00±0.10
E	10.00±0.10
HD	12.00±0.20
HE	12.00±0.20
A	1.70 MAX.
A1	0.10±0.05
A2	1.40
b	0.32±0.05
c	0.145±0.055
L	0.50±0.15
θ	0° to 8°
e	0.65
x	0.13
y	0.10

**NOTE**

1. Dimensions “※1” and “※2” do not include mold flash.
2. Dimension “※3” does not include trim offset.

© 2012 Renesas Electronics Corporation. All rights reserved.

<R> 4.8 64-pin Package

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LQFP64-12x12-0.65	PLQP0064JA-A	P64GK-65-UET-2	0.51



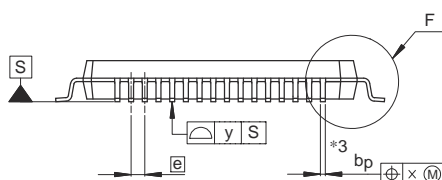
**NOTE**  
Each lead centerline is located within 0.13 mm of its true position at maximum material condition.

©2012 Renesas Electronics Corporation. All rights reserved.

<R>

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
P-LFQFP64-10x10-0.50	PLQP0064KB-C	—	0.3

Unit: mm



- NOTE)
1. DIMENSIONS "\*1" AND "\*2" DO NOT INCLUDE MOLD FLASH.
  2. DIMENSION "\*3" DOES NOT INCLUDE TRIM OFFSET.
  3. PIN 1 VISUAL INDEX FEATURE MAY VARY, BUT MUST BE LOCATED WITHIN THE HATCHED AREA.
  4. CHAMFERS AT CORNERS ARE OPTIONAL, SIZE MAY VARY.



Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
D	9.9	10.0	10.1
E	9.9	10.0	10.1
A <sub>2</sub>	—	1.4	—
H <sub>D</sub>	11.8	12.0	12.2
H <sub>E</sub>	11.8	12.0	12.2
A	—	—	1.7
A <sub>1</sub>	0.05	—	0.15
b <sub>p</sub>	0.15	0.20	0.27
c	0.09	—	0.20
θ	0°	3.5°	8°
e	—	0.5	—
x	—	—	0.08
y	—	—	0.08
L <sub>p</sub>	0.45	0.6	0.75
L <sub>1</sub>	—	1.0	—

© 2015 Renesas Electronics Corporation. All rights reserved.



<R>

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LFQFP64-10x10-0.50	PLQP0064KF-A	P64GB-50-UEU-2	0.35



**NOTE**  
Each lead centerline is located within 0.08 mm of its true position at maximum material condition.

©2012 Renesas Electronics Corporation. All rights reserved.

<R>

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-WFLGA64-5x5-0.50	PWLG0064KA-A	P64FC-50-AN5	0.037

**64-PIN PLASTIC FLGA (5x5)**



© 2011 Renesas Electronics Corporation. All rights reserved.

<R>

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP) [g]
P-LQFP64-14x14-0.80	PLQP0064GA-A	P64GC-80-GBW-1	0.7



(UNIT:mm)

ITEM	DIMENSIONS
D	14.00±0.10
E	14.00±0.10
HD	16.00±0.20
HE	16.00±0.20
A	1.70 MAX.
A1	0.10±0.10
A2	1.40
b	0.37 <sup>+0.08</sup> <sub>-0.05</sub>
c	0.125 <sup>+0.05</sup> <sub>-0.02</sub>
L	0.50±0.20
$\theta$	0° to 8°
e	0.80
x	0.20
y	0.10

**NOTE**

1. Dimensions “ $\ast 1$ ” and “ $\ast 2$ ” do not include mold flash.
2. Dimension “ $\ast 3$ ” does not include trim offset.

© 2012 Renesas Electronics Corporation. All rights reserved.

<R> 4.9 80-pin Package

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LFQFP80-12x12-0.50	PLQP0080KE-A	P80GK-50-8EU-2	0.53



**NOTE**  
Each lead centerline is located within 0.08 mm of its true position at maximum material condition.

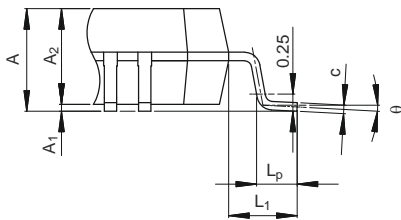
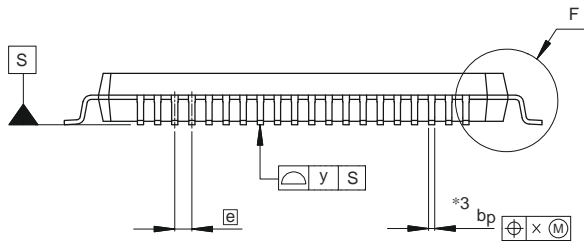
©2012 Renesas Electronics Corporation. All rights reserved.

<R>

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
P-LFQFP80-12x12-0.50	PLQP0080KB-B	—	0.5



- NOTE)
1. DIMENSIONS "\*1" AND "\*2" DO NOT INCLUDE MOLD FLASH.
  2. DIMENSION "\*3" DOES NOT INCLUDE TRIM OFFSET.
  3. PIN 1 VISUAL INDEX FEATURE MAY VARY, BUT MUST BE LOCATED WITHIN THE HATCHED AREA.
  4. CHAMFERS AT CORNERS ARE OPTIONAL, SIZE MAY VARY.



Detail F

Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
D	11.9	12.0	12.1
E	11.9	12.0	12.1
A <sub>2</sub>	—	1.4	—
H <sub>D</sub>	13.8	14.0	14.2
H <sub>E</sub>	13.8	14.0	14.2
A	—	—	1.7
A <sub>1</sub>	0.05	—	0.15
b <sub>p</sub>	0.15	0.20	0.27
c	0.09	—	0.20
θ	0°	3.5°	8°
e	—	0.5	—
x	—	—	0.08
y	—	—	0.08
L <sub>p</sub>	0.45	0.6	0.75
L <sub>1</sub>	—	1.0	—

© 2017 Renesas Electronics Corporation. All rights reserved.

<R>

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LQFP80-14x14-0.65	PLQP0080JB-E	P80GC-65-UBT-2	0.69



detail of lead end



Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	13.80	14.00	14.20
E	13.80	14.00	14.20
HD	17.00	17.20	17.40
HE	17.00	17.20	17.40
A	—	—	1.70
A1	0.05	0.125	0.20
A2	1.35	1.40	1.45
A3	—	0.25	—
bp	0.26	0.32	0.38
c	0.10	0.145	0.20
L	—	0.80	—
Lp	0.736	0.886	1.036
L1	1.40	1.60	1.80
$\theta$	0°	3°	8°
e	—	0.65	—
x	—	—	0.13
y	—	—	0.10
ZD	—	0.825	—
ZE	—	0.825	—

© 2012 Renesas Electronics Corporation. All rights reserved.

<R> 4.10 100-pin Package

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LFQFP100-14x14-0.50	PLQP0100KE-A	P100GC-50-GBR-1	0.69



(UNIT:mm)

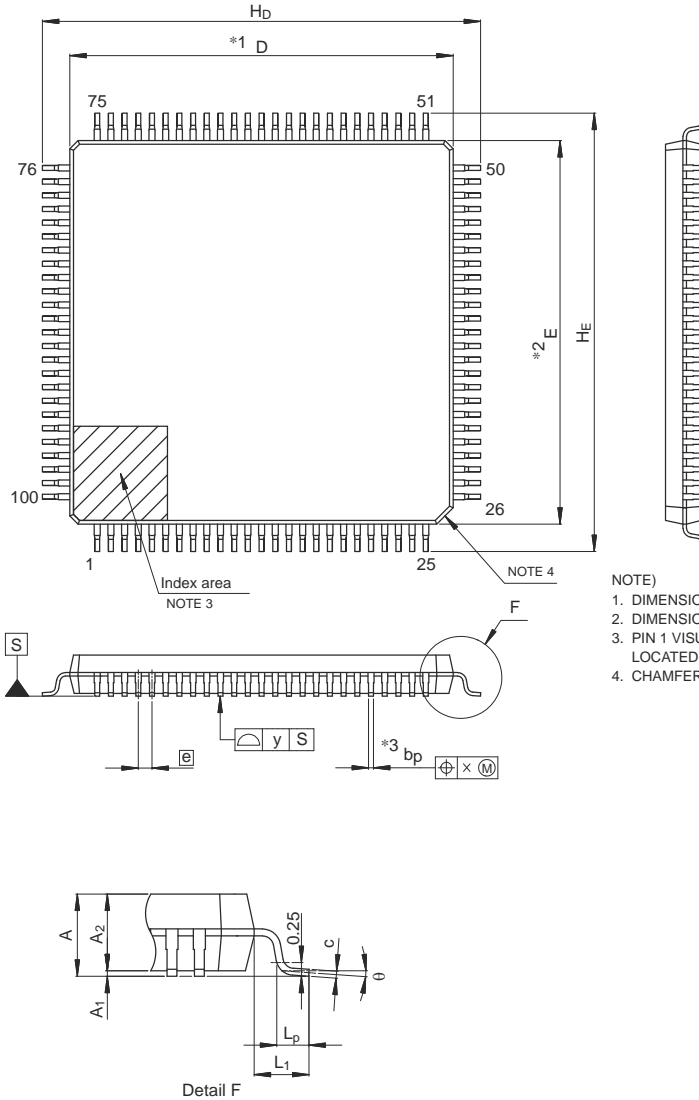
ITEM	DIMENSIONS
D	14.00±0.20
E	14.00±0.20
HD	16.00±0.20
HE	16.00±0.20
A	1.60 MAX.
A1	0.10±0.05
A2	1.40±0.05
A3	0.25
b	0.22±0.05
c	0.145 <sup>+0.055</sup> <sub>-0.045</sub>
L	0.50
Lp	0.60±0.15
L1	1.00±0.20
θ	3° <sup>+5°</sup> <sub>-3°</sub>
e	0.50
x	0.08
y	0.08
ZD	1.00
ZE	1.00

©2012 Renesas Electronics Corporation. All rights reserved.

<R>

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
P-LFQFP100-14x14-0.50	PLQP0100KB-B	—	0.6

Unit: mm



- NOTE)
1. DIMENSIONS  $*1$  AND  $*2$  DO NOT INCLUDE MOLD FLASH.
  2. DIMENSION  $*3$  DOES NOT INCLUDE TRIM OFFSET.
  3. PIN 1 VISUAL INDEX FEATURE MAY VARY, BUT MUST BE LOCATED WITHIN THE HATCHED AREA.
  4. CHAMFERS AT CORNERS ARE OPTIONAL, SIZE MAY VARY.

Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
D	13.9	14.0	14.1
E	13.9	14.0	14.1
A <sub>2</sub>	—	1.4	—
H <sub>D</sub>	15.8	16.0	16.2
H <sub>E</sub>	15.8	16.0	16.2
A	—	—	1.7
A <sub>1</sub>	0.05	—	0.15
b <sub>p</sub>	0.15	0.20	0.27
c	0.09	—	0.20
$\theta$	0°	3.5°	8°
e	—	0.5	—
x	—	—	0.08
y	—	—	0.08
L <sub>p</sub>	0.45	0.6	0.75
L <sub>1</sub>	—	1.0	—

© 2015 Renesas Electronics Corporation. All rights reserved.



<R>

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LQFP100-14x20-0.65	PLQP0100JC-A	P100GF-65-GBN-1	0.92



©2012 Renesas Electronics Corporation. All rights reserved.

## REVISION HISTORY

## RL78/G14 Datasheet

Rev.	Date	Description	
		Page	Summary
0.01	Feb 10, 2011	—	First Edition issued
0.02	May 01, 2011	1 to 2	1.1 Features revised
		3	1.2 Ordering Information revised
		4 to 13	1.3 Pin Configuration (Top View) revised
		14	1.4 Pin Identification revised
		15 to 17	1.5.1 30-pin products to 1.5.3 36-pin products revised
		23 to 26	1.6 Outline of Functions revised
0.03	Jul 28, 2011	1	1.1 Features revised
1.00	Feb 21, 2012	1 to 40	1. OUTLINE revised
		41 to 97	2. ELECTRICAL SPECIFICATIONS added
2.00	Oct 25, 2013	1	Modification of 1.1 Features
		3 to 8	Modification of 1.2 Ordering Information
		9 to 22	Modification of package type in 1.3 Pin Configuration (Top View)
		34 to 43	Modification of description of subsystem clock in 1.6 Outline of Functions
		34 to 43	Modification of description of timer output in 1.6 Outline of Functions
		34 to 43	Modification of error of data transfer controller in 1.6 Outline of Functions
		34 to 43	Modification of error of event link controller in 1.6 Outline of Functions
		45, 46	Modification of description of Tables in 2.1 Absolute Maximum Ratings
		47	Modification of Tables, notes, cautions, and remarks in 2.2 Oscillator Characteristics
		48	Modification of error of conditions of high level input voltage in 2.3.1 Pin characteristics
		49	Modification of error of conditions of low level output voltage in 2.3.1 Pin characteristics
		53 to 62	Modification of Notes and Remarks in 2.3.2 Supply current characteristics
		65, 66	Addition of Minimum Instruction Execution Time during Main System Clock Operation
		67 to 69	Addition of AC Timing Test Points
		70 to 97	Addition of LS mode and LV mode characteristics in 2.5.1 Serial array unit
		98 to 101	Addition of LS mode and LV mode characteristics in 2.5.2 Serial interface IICA
		102 to 105	Addition of characteristics about conversion of internal reference voltage and temperature sensor in 2.6.1 A/D converter characteristics
		107	Addition of characteristic in 2.6.4 Comparator
		107	Deletion of detection delay in 2.6.5 POR circuit characteristics
		109	Modification of 2.6.7 Power supply voltage rising slope characteristics
110	Modification of 2.7 Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics		
110	Addition of characteristic in 2.8 Flash Memory Programming Characteristics		
111	Addition of description in 2.10 Timing for Switching Flash Memory Programming Modes		

## REVISION HISTORY

## RL78/G14 Datasheet

Rev.	Date	Description	
		Page	Summary
2.00	Oct 25, 2013	112 to 169	Addition of CHAPTER 3 ELECTRICAL SPECIFICATIONS
		171 to 187	Modification of 4.1 30-pin products to 4.10 100-pin products
3.00	Feb 07, 2014	All	Addition of products with maximum 512 KB flash ROM and 48 KB RAM
		1	Modification of 1.1 Features
		2	Modification of ROM, RAM capacities and addition of note 3
		3	Modification of Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14
		6 to 8	Addition of part number
		15, 16	Modification of 1.3.6 48-pin products
		17	Modification of 1.3.7 52-pin products
		18, 19	Modification of 1.3.8 64-pin products
		20	Modification of 1.3.9 80-pin products
		21, 22	Modification of 1.3.10 100-pin products
		35, 37, 39, 41, 43, 45, 47	Modification of operating ambient temperature in 1.6 Outline of Functions
		42, 43	Addition of table of 48-pin, 52-pin, 64-pin products (code flash memory 384 KB to 512 KB)
		46, 47	Addition of table of 80-pin, 100-pin products (code flash memory 384 KB to 512 KB)
		65 to 68	Addition of (3) Flash ROM: 384 to 512 KB of 48- to 100-pin products
		118	Modification of 2.7 Data Memory Retention Characteristics
		137 to 140	Addition of (3) Flash ROM: 384 to 512 KB of 48- to 100-pin products
		180	Modification of 3.7 Data Memory Retention Characteristics
		189, 190	Addition and modification of 4.6 48-pin products
191	Modification of 4.7 52-pin products		
193 to 195	Addition and modification of 4.8 64-pin products		
198, 199	Addition and modification of 4.9 80-pin products		
201, 202	Addition and modification of 4.10 100-pin products		
3.20	Jan 05, 2015	2	Deletion of R5F104JK and R5F104JL from the list of ROM and RAM capacities and modification of note
		6	Deletion of ordering part numbers of R5F104JK and R5F104JL from 52-pin plastic LQFP package in 1.2 Ordering Information
		6 to 8	Deletion of note 2 in 1.2 Ordering Information
		17	Deletion of note 2 in 1.3.7 52-pin products
		36, 39, 42, 45, 48, 50, 52	Modification of description in 1.6 Outline of Functions
		46, 48	Deletion of description of 52-pin in 1.6 Outline of Functions
		47	Modification of note of 1.6 Outline of Functions
		62, 64, 66, 68, 70, 72	Modification of specifications in 2.3.2 Supply current characteristics

REVISION HISTORY	RL78/G14 Datasheet
------------------	--------------------

Rev.	Date	Description	
		Page	Summary
3.20	Jan 05, 2015	135, 137, 139, 141, 143, 145	Modification of specifications in 3.3.2 Supply current characteristics
		197	Modification of part number in 4.7 52-pin products
3.30	Aug 12, 2016	143, 145	Addition of maximum values in (3) Flash ROM: 384 to 512 KB of 48- to 100-pin products of 3.3.2 Supply current characteristics
3.31	Feb 14, 2020	3	Addition of packaging specifications in Figure 1 - 1 Part Number, Memory Size, and Package of RL78/G14
		4 to 15	Addition of ordering part numbers and RENESAS codes in Table 1 - 1 List of Ordering Part Numbers
		195, 196, 198 to 201, 203, 205 to 207, 209 to 212, 214, 215, 217	Modification of the titles of the subchapters and deletion of product names in Chapter 4
		197	Addition of figure in 4.2 32-pin Package
		202	Addition of figure in 4.5 44-pin Package
		204	Modification of figure in 4.6 48-pin Package
		208	Modification of figure in 4.8 64-pin Package
		213	Modification of figure in 4.9 80-pin Package
		216	Modification of figure in 4.10 100-pin Package

SuperFlash is a registered trademark of Silicon Storage Technology, Inc. in several countries including the United States and Japan.

Caution: This product uses SuperFlash® technology licensed from Silicon Storage Technology, Inc.

All trademarks and registered trademarks are the property of their respective owners.

# General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

## 1. Precaution against Electrostatic Discharge (ESD)

A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity.

Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.

## 2. Processing at power-on

The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.

## 3. Input of signal during power-off state

Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.

## 4. Handling of unused pins

Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.

## 5. Clock signals

After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.

## 6. Voltage application waveform at input pin

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.).

## 7. Prohibition of access to reserved addresses

Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.

## 8. Differences between products

Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

## Notice

1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation or any other use of the circuits, software, and information in the design of your product or system. Renesas Electronics disclaims any and all liability for any losses and damages incurred by you or third parties arising from the use of these circuits, software, or information.
2. Renesas Electronics hereby expressly disclaims any warranties against and liability for infringement or any other claims involving patents, copyrights, or other intellectual property rights of third parties, by or arising from the use of Renesas Electronics products or technical information described in this document, including but not limited to, the product data, drawings, charts, programs, algorithms, and application examples.
3. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
4. You shall not alter, modify, copy, or reverse engineer any Renesas Electronics product, whether in whole or in part. Renesas Electronics disclaims any and all liability for any losses or damages incurred by you or third parties arising from such alteration, modification, copying or reverse engineering.
5. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The intended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below.  
"Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; industrial robots; etc.  
"High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control (traffic lights); large-scale communication equipment; key financial terminal systems; safety control equipment; etc.  
Unless expressly designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not intended or authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems; surgical implantations; etc.), or may cause serious property damage (space system; undersea repeaters; nuclear power control systems; aircraft control systems; key plant systems; military equipment; etc.). Renesas Electronics disclaims any and all liability for any damages or losses incurred by you or any third parties arising from the use of any Renesas Electronics product that is inconsistent with any Renesas Electronics data sheet, user's manual or other Renesas Electronics document.
6. When using Renesas Electronics products, refer to the latest product information (data sheets, user's manuals, application notes, "General Notes for Handling and Using Semiconductor Devices" in the reliability handbook, etc.), and ensure that usage conditions are within the ranges specified by Renesas Electronics with respect to maximum ratings, operating power supply voltage range, heat dissipation characteristics, installation, etc. Renesas Electronics disclaims any and all liability for any malfunctions, failure or accident arising out of the use of Renesas Electronics products outside of such specified ranges.
7. Although Renesas Electronics endeavors to improve the quality and reliability of Renesas Electronics products, semiconductor products have specific characteristics, such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Unless designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not subject to radiation resistance design. You are responsible for implementing safety measures to guard against the possibility of bodily injury, injury or damage caused by fire, and/or danger to the public in the event of a failure or malfunction of Renesas Electronics products, such as safety design for hardware and software, including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult and impractical, you are responsible for evaluating the safety of the final products or systems manufactured by you.
8. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. You are responsible for carefully and sufficiently investigating applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive, and using Renesas Electronics products in compliance with all these applicable laws and regulations. Renesas Electronics disclaims any and all liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
9. Renesas Electronics products and technologies shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You shall comply with any applicable export control laws and regulations promulgated and administered by the governments of any countries asserting jurisdiction over the parties or transactions.
10. It is the responsibility of the buyer or distributor of Renesas Electronics products, or any other party who distributes, disposes of, or otherwise sells or transfers the product to a third party, to notify such third party in advance of the contents and conditions set forth in this document.
11. This document shall not be reprinted, reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics.
12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products.

(Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its directly or indirectly controlled subsidiaries.

(Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

(Rev.4.0-1 November 2017)



### SALES OFFICES

Renesas Electronics Corporation

<http://www.renesas.com>

Refer to "<http://www.renesas.com/>" for the latest and detailed information.

#### Renesas Electronics Corporation

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan

#### Renesas Electronics America Inc. Milpitas Campus

1001 Murphy Ranch Road, Milpitas, CA 95035, U.S.A.

Tel: +1-408-432-8888, Fax: +1-408-434-5351

#### Renesas Electronics America Inc. San Jose Campus

6024 Silver Creek Valley Road, San Jose, CA 95138, USA

Tel: +1-408-284-8200, Fax: +1-408-284-2775

#### Renesas Electronics Canada Limited

9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3

Tel: +1-905-237-2004

#### Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany

Tel: +49-211-6503-0, Fax: +49-211-6503-1327

#### Renesas Electronics (China) Co., Ltd.

Room 101-T01, Floor 1, Building 7, Yard No. 7, 8th Street, Shangdi, Haidian District, Beijing 100085, China

Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

#### Renesas Electronics (Shanghai) Co., Ltd.

Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai 200333, China

Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

#### Renesas Electronics Hong Kong Limited

Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong

Tel: +852-2265-6688, Fax: +852-2886-9022

#### Renesas Electronics Taiwan Co., Ltd.

13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan

Tel: +886-2-8175-9600, Fax: +886-2-8175-9670

#### Renesas Electronics Singapore Pte. Ltd.

80 Bendemeer Road, #06-02 Singapore 339949

Tel: +65-6213-0200, Fax: +65-6213-0300

#### Renesas Electronics Malaysia Sdn.Bhd.

Unit No 3A-1 Level 3A Tower 8 UOA Business Park, No 1 Jalan Pengerutcara U1/51A, Seksyen U1, 40150 Shah Alam, Selangor, Malaysia

Tel: +60-3-5022-1288, Fax: +60-3-5022-1290

#### Renesas Electronics India Pvt. Ltd.

No.77C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India

Tel: +91-80-67208700

#### Renesas Electronics Korea Co., Ltd.

17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea

Tel: +82-2-558-3737, Fax: +82-2-558-5338

# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

## Renesas Electronics:

[R5F104AFASP#X0](#) [R5F104BCANA#W0](#) [R5F104FJAFP#X0](#) [R5F104GAAFB#V0](#) [R5F104MKGFA#30](#)  
[R5F104LKAFa#50](#) [R5F104GEGFB#V0](#) [R5F104MHAFa#X0](#) [R5F104EDGNA#U0](#) [R5F104PKAFa#30](#)  
[R5F104LFALa#U0](#) [R5F104MGAFa#V0](#) [R5F104LCAFP#V0](#) [R5F104LLAFB#50](#) [R5F104MGDFB#V0](#)  
[R5F104LEAFP#V0](#) [R5F104GGAFB#X0](#) [R5F104BGANA#W0](#) [R5F104EFANA#U0](#) [R5F104GDADF#V0](#)  
[R5F104LDALa#U0](#) [R5F104LFAFP#V0](#) [R5F104LCALa#U0](#) [R5F104FAAFP#V0](#) [R5F104GCANA#W0](#)  
[R5F104JGAFa#V0](#) [R5F104LCAFB#V0](#) [R5F104PKAFB#30](#) [R5F104GDANA#U0](#) [R5F104GLAFB#50](#)  
[R5F104BEGNa#U0](#) [R5F104CDALa#U0](#) [R5F104GCAFB#V0](#) [R5F104GLANA#U0](#) [R5F104BDANA#U0](#)  
[R5F104CEALa#U0](#) [R5F104GJAFB#V0](#) [R5F104GKAFB#50](#) [R5F104JJAFa#V0](#) [R5F104BFGNa#U0](#)  
[R5F104MLAFB#50](#) [R5F104EDGNA#W0](#) [R5F104MLGFB#30](#) [R5F104ADASP#V0](#) [R5F104AFASP#V0](#)  
[R5F104AGASP#V0](#) [R5F104MJAFa#V0](#) [R5F104PFAFB#V0](#) [R5F104MJAFB#V0](#) [R5F104PHAFa#V0](#)  
[R5F104BCGFP#V0](#) [R5F104ACASP#X0](#) [R5F104LHAFa#V0](#) [R5F104MHAFa#V0](#) [R5F104MLAFa#30](#)  
[R5F104PFaF#V0](#) [R5F104PJAFa#V0](#) [R5F104MHAFB#V0](#) [R5F104MJAFa#X0](#) [R5F104MKAFa#30](#)  
[R5F104MKAFB#30](#) [R5F104PGAFa#V0](#) [R5F104PLAFa#30](#) [R5F104PLAFB#30](#) [R5F104JFaf#V0](#)  
[R5F104JEaf#V0](#) [R5F104JJAFa#X0](#) [R5F104LEALa#U0](#) [R5F104LJALa#U0](#) [R5F104LLAFa#50](#) [R5F104LEAFB#V0](#)  
[R5F104JGGF#V0](#) [R5F104LDAFB#V0](#) [R5F104LJAFa#V0](#) [R5F104MGAFB#V0](#) [R5F104LLALa#W0](#)  
[R5F104GCDFB#V0](#) [R5F104LKALa#W0](#) [R5F104LHAFB#V0](#) [R5F104PGAFB#V0](#) [R5F104PJAFB#X0](#)  
[R5F104MKGFA#50](#) [R5F104LDAFA#V0](#) [R5F104LJAFP#V0](#) [R5F104LLAFa#30](#) [R5F104LHAFP#V0](#)  
[R5F104GJANA#U0](#) [R5F104GKAFB#30](#) [R5F104BDAFP#V0](#) [R5F104GGANA#U0](#) [R5F104LKALa#U0](#)  
[R5F104LLAFB#30](#) [R5F104MFAFA#V0](#) [R5F104JDaf#V0](#) [R5F104GHANA#U0](#) [R5F104JCAF#X0](#)  
[R5F104LDALa#W0](#) [R5F104LKAFa#30](#) [R5F104JGGFA#30](#) [R5F104LEAF#V0](#)



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.